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AFML-TR-69-84 PART III. VOLUME I

STABILITY CHARACTERIZATION OF REFRACTORY MATERIALS UNDER HIGH VELOCITY ATMOSPHERIC FLIGHT CONDITIONS

PART III. VOLUME I: EXPERIMENTAL RESULTS OF LOW VELOCITY COLD GAS/HOT WALL TESTS

LARRY KAUFMAN
HARVEY NESOR
ManLabs, Inc.

TECHNICAL REPORT AFML-TR-69-84, PART III, VOLUME I

DECEMBER 1969



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FOREWORD

This report was prepared by ManLabs, Inc. with the assistance of Arthur D. Little, Inc., Acorn Park, Massachusetts (Dr. Joan B. Berkowitz-Mattuck, Project Leader). This contract was initiated under Project 7312, "Metal Surface Deterioration and Protection," Task 731201, "Metal Surface Protection," and Project 7350, "Refractory Inorganic Nonmetallic Materials," Task Nos. 735001, "Refractory Inorganic Nonmetallic Materials: Nongraphitic," and 735002, "Refractory Inorganic Nonmetallic Materials: Graphitic," under AF33(615)-3859 and was administered by the Metals and Ceramics Division of the Air Force Materials Laboratory, Air Force Systems Command, with J.D. Latva, J. Krochmal and N.M. Geyer acting as project engineers.

This report covers the period from April 1966 to July 1969.

The manuscript of this report was released by the authors in September 1969 for publication.

ManLabs personnel participating in this study included L. Kaufman, H. Nesor, H. Bernstein, E. Peters, J.R. Baron, G. Stepakoff, R. Pober, R. Hopper, R. Yeaton, S. Wallerstein, E. Sybicki, J. Davis, K. Meaney, K. Ross, J. Dudley, E. Offner, A. Macey, A. Silverman and A. Constantino.

This technical report has been reviewed and is approved.

W. G. Ramke

Chief, Ceramics and Graphite Branch Metals and Ceramics Division Air Force Materials Laboratory

The following reports will be issued under this contract,

Part/Volume	
I-I	Summary of Results
II-I	Facilities and Techniques Employed for Characterization of Candidate Materials
II-II	Facilities and Techniques Employed for Cold Gas/Hot Wall Tests
п-ш	Facilities and Techniques Employed for Hot Gas/Cold Wall Tests
ш-1	Experimental Results of Low Velocity Cold Gas/Hot Wall Tests
III-II	Experimental Results of High Velocity Cold Gas/Hot Wall Tests
111-111	Experimental Results of High Velocity Hot Gas/Cold Wall Tests
IV-I	Theoretical Correlation of Material Performance with Stream Conditions
IV-II	Calculation of the General Surface Reaction Problem

ABSTRACT

The oxidation of refractory borides, graphites and JT composites, hypereutectic carbide-graphite composites, refractory metals, coated refractory metals, metal oxide composites, and iridium coated graphites-in air was investigated over the spectrum of conditions encountered during reentry or high velocity atmospheric flight, as well as those employed in conventional furnace tests. Elucidation of the relationship between hot gas/cold wall (HG/CW) and cold gas/hot wall (CG/HW) surface effects in terms of heat and mass transfer rates at high temperatures is a principal goal.

Furnace oxidation results in flowing air at 0.9 to 7.2 ft/sec for times up to four hours at temperatures between 1150° and 4200° F are presented for 30 candidate materials including the refractory borides, carbides, boride composites, boride-graphite composites (JTA), JT composites, carbide-graphite composites, pyrolytic and bulk graphite, PT graphite, coated refractory metal/alloys, oxide-metal composites, oxidation-resistant refractory metal alloys and coated graphites. Temperature limits for coated materials, viscous flow of metal-oxide composites and effects of cyclic heating and cooling exposures are reported. Results are presented for exposures in flowing argon between 300° and 4200° F. These data are complemented by the results of oxygen pickup and gas analysis tests on JT composites, silicide coated tungsten and a series of binary and ternary iridium-base alloys which were heated by induction in oxygen-helium mixtures flowing at 0.2 ft/sec. Failure conditions were established for the silicide coating on tungsten at oxygen partial pressures of 0.031 and 0.20 atmospheres.

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I. INTRODUCTION AND SUMMARY

A. Introduction

The response of refractory materials to high temperature oxidizing conditions imposed by furnace heating has been observed to differ markedly from the behavior in arc plasma"reentry simulators." The former evaluations are normally performed for long times at fixed temperatures and slow gas flows with well-defined solid/gas-reactant/ product chemistry. The latter on the other hand are usually carried out under high velocity gas flow conditions in which the energy flux rather than the temperature is defined and significant shear forces can be encountered. Consequently, the differences in philosophy, observables, and techniques used in the "material centered" regime and the "environment centered, reentry simulation" area differ so significantly as to render correlation of material responses at high and low speeds difficult if not impossible in many cases. Under these circumstances, expeditious utilization of the vast background of information available in either area for optimum matching of existing material systems with specific missions or prediction and synthesis of advanced material systems to meet requirements of projected missions is sharply curtailed,

In order to progress toward the elimination of this gap, an integrated study of the response of refractory materials to oxidation in air over a wide range of time, gas velocity, temperature and pressure has been designed and implemented. This interdisciplinary study spans the heat flux and boundary layer-shear spectrum of conditions encountered during high-velocity atmospheric flight as well as conditions normally employed in conventional materials centered investigations. In this context, significant efforts have been directed toward elucidating the relationship between hot gas/cold wall HG/CW and cold gas/hot wall CG/HW surface effects in terms of heat and mass transfer rates at high temperatures, so that full utilization of both types of experimental data can be made.

The principal goal of this study is the coupling of the material centered and environment centered philosophies in order to gain a better insight into systems behavior under high speed atmospheric flight conditions. This coupling function has been provided by an interdisciplinary panel composed of scientists representing the component philosophies. The coupling framework consists of an intimate mixture of theoretical and experimental studies specifically designed to overlap temperature/energy and pressure/velocity conditions. This overlap has provided a means for the evaluation of test techniques and the performance of specific materials systems under a wide range of flight conditions. In addition, it provides a base for developing an integrated theory or modus operandi capable of translating reentry systems requirements such as velocity, altitude, configuration and lifetime into requisite materials properties as vaporization rates, oxidation kinetics, density, etc., over a wide range of conditions.

The correlation of heat flux, stangation enthalpy, Mach No., stagnation pressure and specimen geometry with surface temperature through the utilization of thermodynamic, thermal and radiational properties of the material and environmental systems used in this study was of prime importance in defining the conditions for overlap between materials-centered and environment-centered tests.

Significant practical as well as fundamental progress along the above mentioned lines necessitated evaluation of refractory material systems which exhibit varying gradations of stability above 2700°F. Emphasis was directed towards candidates for 3400° to 6000°F exploitation. Thus, borides, carbides, boride-graphite composites (JTA), JT composites, carbide-graphite composites, pyrolytic and bulk graphite, PT graphite, coated refractory metals/alloys, oxide-metal composites, exidation-resistant refractory metal alloys, and coated graphites were considered. Similarly, a range of test facilities and techniques including oxygen pickup measurements, cold sample hot gas, and hot sample cold gas devices at low velocities, as well as different arc plasma facilities capable of covering the 50-2500 BTU/ft2sec flux range under conditions equivalent to speeds up to Mach 12 at altitudes up to 200,000 feet were employed. Stagnation pressures employed ranged between 0.001 and 10 atmospheres. Splash and pipe tests were performed in order to evaluate the effects of aerodynamic shear. Based on the present results, this range of heat flux and stagnation enthalpy produced surface temperatures between 2000° and 6500°F.

This report describes the results obtained for the Cold Gas/Hot Wall tests performed at ManLabs and Arthur D. Little employing facilities described elsewhere (1)*. Low velocity testing was performed at ManLabs, Inc. under the direction of H. Nesor. Air flowing at 0.9 to 9.0 ft/sec was employed in resistance heated tube furnaces at temperatures between 1000° and 4200°F. Exposure times ranging from five minutes up to four hours were used to evaluate the behavior of the candidate materials. Post exposure metallographic examination of samples disclosed the extent of oxidation. Temperature measurement within the tube furnaces was carried out by means of optical brightness and two color pyrometry and checked by measurements of the melting temperature of several materials.

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Low velocity tests of inductively heated samples were performed at Arthur D. Little under the direction of J.B. Berkowitz-Mattuck. These exposures were carried out in oxygen-helium mixtures at flow rates of 0.2 ft/sec with oxygen monitored by measuring the rate at which oxygen was removed from the stream for times up to one hour. These measurements were complemented by measurements of CO and CO₂ formation. Post-exposure metallographic measurements were employed to check and supplement the gas analysis data. Optical brightness measurements were employed to measure the surface temperature by employing suitable emittance corrections.

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^{*}The underscored numbers in parenthesis refer to references listed at the end of this report.

B. Summary of Results

Air oxidation test data generated in CG/HW furnace tests are presented for most of the candidate materials. Test conditions covered temperatures between 11500 and 4200°F, times from five minutes to four hours and air flow rates between 0.9 and 9.0 ft/sec. Cyclic exposures were performed for most of the candidates. Temperature limits of 3060°, 3200° and 3450° F were found for Si/RVC(B-8), Sn-Al/Ta-10W(G-19) and WSi₂/W(G-18), respectively. Supply limited oxidation at rates of 0.2-0.3 mils/sec for temperatures between 2800° and 4100°F in air at one atmosphere was noted for RVA(B-5), PG(B-6), BPG(B-7), PT0178(B-9) and AXF-5Q Poco(B-10) graphites. The arc cast hypereutectic carbides HfC+C(C-11) and ZrC+C(C-12) exhibit surprisingly constant recession levels of 50-100 mils for one hour exposures between 1200 and 4200 F. A transition from puffy to adherent oxide occurs above 3450 F for the carbides. The SiO₂ + 35 w/oW(H-24) composite was observed to flow at temperatures above 3000°F. By contrast, the SiO₂+68.5 w/o W(H-22) and SiO₂+60 w/o W(H-23) composites exhibit low oxidation rates at temperatures between 3200° and 3900°F, above which viscous flow occurs. The hypereutectic carbides HfC+C(C-11) and ZrC+C(C-12) and the SiO₂+W(H-22) and (H-23) composites are susceptible to oxidation at low temperatures (1200°-2500°F) where protective oxides do not form. KT-SiC(E-14) exhibits low recession up to 3450°F, and rapid degradation above 3500°F.

The HfB₂+20%SiC(A-4), HfB₂₋₁+20%SiC(A-7) and HfB₂₋₁+35%SiC (A-9) composites exhibit the lowest overall recessions up to 3800°F, above which complete depletion of SiC occurs and rates are comparable to HfB₂₋₁ (A-2) and (A-6). HfB₂ base materials show lower recession values than the ZrB₂ base materials - ZrB₂(A-3), Boride Z(A-5), ZrB₂+14%SiC+30%C(A-10) and ZrB₂+20%SiC(A-8) which are listed in order of increasing oxidation resistance. JT0992(C-HfC-SiC)(F-15) exhibits better oxidation resistance than does JT0981(C-ZrC-SiC)(F-16), which in turn is superior to JTA(C-ZrB₂-SiC)(D-13). However, the former composites show substantially higher rates than JTA (D-13) below 3000°F since they do not contain boron and the graphite can oxidize freely. Above 3000°F, JT0992(F-15) exhibits conversion depths comparable to HfB₂(A-2) and JT0981(F-16) is similarly comparable to ZrB₂(A-3). Hf-20Ta-2Mo(I-23) is as oxidation resistant as (A-3) and (F-16), but melts near 3850°F.

Kinetic studies indicate protective behavior over a two hour period at the following temperatures for: HfB2.1(A-2)-3700°F, ZrB2 (A-3)-3400°F, HfB2+20%SiC(A-4) and (A-7)-3790°F, ZrB2.1+20%SiC (A-8)-3750°F, ZrB2+SiC+C(A-10)-3600°F, HfC+C(C-11)-4000°F, ZrC+C(C-12)-3600°F, JTA(D-13)-3250°F, KT-SiC(E-14)-3450°F, JT0992(F-15)-3520°F, JT0981(F-16)-3390°F, SiO2+60w/oW(H-23)-3850°F, Hf-20Ta-2Mo(I-23)-3380°F. Comparison of the recessions after two hour continuous exposures with the results obtained after four,thirty minute periods interrupted by cooling cycles yielded similar results for HfB2.1(A-2), ZrB2 (A-3), HfB2+20%SiC(A-4), Si/RVC(B-8), HfC+C(C-11), ZrC+C(C-12), JTA (D-13), JT0992(F-15), JT0981(F-16), WSi2/W(G-18) and Sn-Al/Ta-10W (G-19). In each case, the exposure temperature did not exceed the two hour protection limit or failure temperature for coatings. More rapid degradation was observed for KT-SiC(E-14), SiO2+68.5w/oW(H-22), SiO2+60w/oW (H-23) and Hf-20Ta-2Mo(I-23). Seven of the candidate materials were tested

in larger tube furnaces than usually employed (2 inch vs. 7/8 inch inside diameters). HfB_{2.1}(A-2) and ZrB₂(A-3) recession results were independent of test facility but more rapid oxidation was observed for HfB_{2.1}+20%SiC(A-4) and (A-7), JTA(D-13), KT-SiC(E-14), JT0992(F-15), JT0981(F-16) and Hf-20Ta-2Mo(I-23) in large furnace tests. These differences are most probably due to differences in air supply.

Six materials were heated in flowing argon for one hour between 3000° and 4200°F. Negligible changes in JT0992(F-15) and JT0981 (F-16) occurred. JTA(D-13) exhibited changes in internal structure suggestive of melting in the ZrB₂-SiC phases at 4200°F. Exposure of WSi₂/W(G-18) above 3500°F resulted in melting of the coating. Testing of SiO₂+60w/oW (H-23) between 3800° and 4000°F resulted in cracking and evidence of SiO₂ sublimation. PT0178(B-9) graphite was not affected.

Oxygen pickup and gas analysis studies were performed on JTA(D-13), JT0992(F-15), JT0981(F-16), WSi₂/W(G-18) and a series of iridium-base alloys between 2900° and 4275°F and at oxygen partial pressures of 10 to 150 Torr in oxygen-helium mixtures at flow rates of 0.2 ft/sec (CG/HW). The graphite composites exhibit protective oxidation at 2900 F and linear oxidation at 3500 F, although at 2900 F, 40 Torr O_2 is required to provide a protective oxide for JTA(D-13). Thus at temperatures where protective oxidation occurs, raising the oxygen pressure can lower the rate of oxidation. However, at higher temperatures where exidation is linear (i.e., at or above 3500°F) raising the pressure increases the rate. In testing of WSi2/W(G-18) at an oxygen partial pressure of 10 Torr, protective oxidation is not observed above 3500°F unless a protective film is formed first by oxidation at lower temperatures. Under such conditions, protection can be retained to 3500°F. At one atmosphere, failure was noted at 3560°F. The temperature and pressure ranges over which protective oxidation of WSi2/W (G-18) is observed are discussed in terms of initial formation of WO3(g) and SiO2(s) followed by preferential oxidation of silicon to form lower silicides and finally W at the oxide/alloy interface. Failure to form a protective SiO₂ layer at low oxygen pressures and the rupturing of existing SiO₂ films by SiO(g) evolution are considered as mechanisms operative during nonprotective oxidation of WSi2/W(G-18).

Several binary and ternary iridium-base alloys were tested at 4000°F in 53% oxygen-47% helium at one atmosphere and a 0.2 ft/sec flow rate. Comparative results indicate that rhodium additions offer the greatest resistance against oxidation while platinum and rhenium confer only moderate resistance. Osmium additions reduce oxidation resistance. It should be noted that rhenium raises the iridium-carbon eutectic temperature, while platinum and rhodium lower it.

II. RESULTS OF FURNACE OXIDATION TESTS (CG/HW)

A. Introduction

Air oxidation tests have been performed for most of the candidate materials listed in Table 1. Details of the apparatus and procedures employed are given in Part II-Volume II of this series (1), and characterization data on the candidate materials are presented in Part II-Volume I (2). In general, single samples mounted on zirconia pedestals are placed into the furnace which is at room temperature. The samples are heated to test temperature in flowing argon. When temperature is reached, the argon is turned off and air is turned on. Air flow rates between 0.9 and 9.0 ft/sec at one atmosphere have been used for times from five minutes to four hours. Testing temperatures between 1150° and 4200°F have been employed. After the required time has elapsed, the furnace power and air are turned off and argon is reintroduced during cooling of the sample. Most of the candidate materials have been subjected to cyclic heating and cooling exposures, which generally involved four thirty minute periods at elevated temperature with intermediate furnace cooling to below 500°F between each elevated temperature cycle. The conversion depth, or extent to which oxidation takes place during exposure, was determined by post-exposure metallography. Material recessions were measured both for length and diameter of the cylindrically-shaped samples. All conversion depths reported below are the maximum value, rather than the average of the two measurements, since significant differences have been noted between longitudinal and transverse values, particularly in samples having conversion depths greater than 100 mils.

B. Oxidation Results

Oxidation data have been generated for all candidate materials listed in Table 1 with the exception of Glassy Carbon(B-11), W+Zr+Cu(G-20), W+Ag(G-21) and Ir/C(I-24). A complete tabulation of exposure conditions and recession measurements is given in Tables 2-9. Figures 1-7 show variation of maximum conversion depth with temperature and air flow rate for these conditions. Figures 8-15 illustrate time dependence of oxidation at fixed temperature and air flow rate. In some instances, the large furnaces (2 inch inside diameter) were used to test several samples simultaneously, withdrawing each specimen after a given time interval without cooling the furnace. The results have led to the following conclusions:

1. $HfB_{2.1}(A-2)$ and $HfB_{2.1}(A-6)$

Tables 2 and 5 and Figures 1, 8, 12 and 14 summarize the results obtained following CG/HW air oxidation furnace tests on hafnium diboride. One hour exposures in flowing air have been performed at temperatures between 1200°F and 4100°F. The results which are shown in Figure 1 refer to exposures conducted in the small furnaces (7/8 inch inside diameter). HfB_{2.1}(A-2) appears to oxidize more rapidly at temperatures below 3200°F

^{*}Temperatures were measured with LATRONICS COLORATIO Automatic Two-Color Pyrometers or with a MILLETRON Therm-O-Scope Automatic Two-Color Pyrometer. Instruments were calibrated weekly against a tungsten filament bulb.

than HfB_{2.1}(A-6) and the hafnium borides having B/Me = 1.7-2.1 (3,4). Reference to Figure 1 shows that the one hour conversion depth becomes insensitive to temperature above 3600°F. The reason for this insensitivity is not clear. In all cases, the quantity of air flowing through the furnace exceeded that required to oxidize the samples by a substantial amount. It is possible, however, that the supply of oxygen available at the gas/oxide interface is limited by the transport rate or diffusion of oxygen molecules through the gas. In a case where the observed conversion depth is limited by the air velocity (i.e., where increasing air velocity increases the conversion depth), the rate is defined to be supply limited. By contrast, if the observed oxidation rate is independent of both air velocity and temperature, the oxidation rate may be limited by diffusion of oxygen through the gas. In the present case, the conversion depth for one hour exposures of HfB_{2.1}(A-2) at temperatures above 3600°F does not seem strongly dependent upon air velocities between 0.9 and 7.2 ft/sec. Thus, the reaction may be diffusion limited above 3600°F. Figures 16-19 show post-exposure photomicrographs of exposure HfB_{2.1}(A-2), Test 1356, and HfB_{2.1}(A-6), Test 367. An adherent oxide and uniform conversion of boride to oxide is indicated in both cases.

Kinetic studies have been performed at temperatures between 3350° and 4000°F for times between 15 and 120 minutes. Figure 8 shows results obtained in the small furnace (7/8 inch inside diameter tube), while Figure 12 shows results obtained in the large furnace (2 inch inside diameter tube). A comparison of "small" and "large" furnace results is contained in Figure 14. These figures indicate protective behavior** between 3350° and 4000°F with little dependence on furnace size although conversion depths in the "large" furnace appear to be very slightly larger. Two hour conversion depths are relatively insensitive to temperature above 3600°F.

Test 858 (Table 2) consisted of four - thirty minute cycles at 3590°F on HfB_{2.1}(A-2). A conversion depth of 116 mils was obtained. This is approximately equal to the value indicated by the noncyclic kinetic studies so that alternate heating and cooling appear to have little effect on this material. Several low temperature exposures (Tests 863, 866, 867 and 8, Table 2) were performed between 1200° and 2700°F to verify the expected low rates of oxidation under these conditions. These tests, when combined with the results illustrated in Figure 1, show that the oxidation rates of HfB_{2.1}(A-2) and HfB_{2.1}(A-6) increase with increasing temperature.

^{*} This supply limit may be caused by furnace geometry and air flow rate. As a consequence it is not a unique characteristic of the material.

^{**} The meaning of the term "protective behavior" as employed here in describing the oxidation of bulk materials implies rates which decrease with time. This term is used in contrast to "nonprotective" behavior in which the oxidation rate is constant.

$2. \qquad 2 = \frac{2}{2} (A 3)$

The data for zirconium diboride are displayed in Table 2 and Figures 1, 8, 12 and 14. One hour exposures in flowing air have been performed at temperatures between 1200° and 4200° F. Recession values for ZrB₂(A-3) are in general agreement with those for ZrB₂ prepared by ManLabs and Avco under AF33(615)-3671 (3), and are somewhat larger than values obtained for hafnium diborides. An insensitivity to temperature above 3500° F is also indicated, comparable to that discussed above for HfB₂ (A-2). Post-exposure photomicrographs are shown in Figures 20 and 21. The oxide formed on ZrB₂(A-3) tends to chip off easily and is generally not as adherent as that formed on hafnium diborides.

Kinetic studies have been performed between 3260° and 3560°F for times up to two hours. Figures 8, 12 and 14 illustrate the small furnace, large furnace, and comparative results respectively. Protective behavior is observed at temperatures up to 3400°F for one hour. At higher temperatures, and for longer times at 3400°F, behavior becomes nonprotective. Similar results are obtained in both furnaces. Four - thirty minute cycles at 3206°F (Test 935, Table 2) yield a maximum conversion depth of 40 mils which is in agreement with the two hour kinetic experiments. Low temperature exposures between 1200° and 2700°F (Tests 900, 902, 904 and 905, Table 2) indicate the expected low rates of oxidation. Combination of these results with those at higher temperatures show that zirconium diboride exhibits an increasing rate of oxidation with increasing temperature.

3. $\frac{\text{HfB}_2+20\%\text{SiC}(A-4), \text{HfB}_{2.1}+20\%\text{SiC}(A-7) \text{ and}}{\text{HfB}_{2.1}+35\%\text{SiC}(A-9)}$

The results for hafnium diboride-silicon carbide composites are presented in Tables 3 and 4 and in Figures 1, 8, 12 and 14. The tables give silicon carbide depletion depths as well as diboride conversion depths. The depletion depth is the distance from the outer surface over which silicon carbide is removed during exposure. Composites containing silicon carbide are observed to form clear bubbles of silica during an exposure. These bubbles will expand and burst during a test until the silicon carbide is completely removed. Post-exposure examination of such samples reveal that a glassy oxide remains on the surface along with the white oxide formed due to diboride oxidation.

One hour exposures have been performed at temperatures between 1200° and 4200°F. These agree with results obtained under AF33-(615)-3671 (3). No real distinction can be made between the three composites, although HfB₂ 1+35%SiC(A-9) may yield slightly lower recession values than the composites containing 20%SiC. The oxidation rates for the composites are markedly slower than for HfB₂ 1(A-2) and (A-6) with virtually no oxidation taking place below 3200°F. Figure 22 illustrates the variation of depletion

^{*}Tests run at 2400°F for 150 hours indicate that HfB_{2,1}+20%SiC(A-7) exhibits only several mils conversion and no preferential oxidation of silicon carbide(5).

depth with time for HfB₂+20%SiC(A-4). At 3575°F, the conversion depth shows almost no time dependence up to 120 minutes. However, at 3685°F and above the depletion depth increases rapidly after one hour. Thus, after one hour exposures at temperatures above 3800°F, complete depletion of silicon carbide has occurred for 1/2 inch cylindrical samples, and recession values become comparable to pure hafnium diboride.

Figures 23-28 show post-exposure sections of the hafnium diboride-silicon carbide composites. The absence of silicon carbide in the depleted zone beneath the oxide is clearly visible. At temperatures equal to or less than 3800°F, the oxide is quite adherent to the diboride core. Above 3800°F, the oxide is found to be separated from the diboride core or cracked after cooling to room temperature. In cases where a sample has been partially depleted of silicon carbide, radial cracks are often found in the depleted zone, as illustrated in Figures 29 and 30.

Kinetic studies have been performed for HfB₂+20%SiC (A-4) in the large furnace between 3565° and 4000°F, and for HfB₂ +20%SiC (A-7) in the small furnace between 3550° and 3900°F. The latter results are presented in Figure 8, the former in Figure 12, and a comparison is contained in Figure 14. The comparison shows somewhat lower recession values at 3900°F in the small furnace tests on (A-7), where protective behavior is observed over a two hour period. Non-protective oxidation is observed in large furnace tests on (A-4) after one hour at 3894°F. Cyclic exposures on HfB₂+20%SiC(A-4) at 3600°F and 3900°F (Tests 1061 and 952, Table 3) indicate fittle difference when compared with two hour kinetic results at 3600°F, but enhanced oxidation at 3900°F. Tests at temperatures between 1200° and 2700°F yielded virtually no oxidation and little depletion. These composites generally exhibit increasing oxidation rates with increasing temperature.

4. Boride Z(A-5), ZrB_{2.1}+20%SiC(A-8) and ZrB₂+14%SiC+30%C(A-10)

The results of furnace oxidation tests for the zirconium diboride-base composites are presented in Tables 4 and 5, and displayed in Figures 1, 2, 8 and 9. Comparison of $ZrB_2(A-3)$ with the (A-5), (A-8) and (A-10) composites indicates comparable behavior after one hour exposures above 3800°F similar to the behavior of hafnium diboride versus its composites. Below this temperature, the silicon carbide additions become effective over one hour periods and the composites show increased resistance to oxidation relative to pure ZrB_2 . ZrB_2 +20%SiC(A-8) appears to be most resistant to oxidation followed by $ZrB_2^2+14\%$ SiC+30%C(A-10) and Boride Z (A-5). Post-exposure photomicrographs are shown in Figures 31-36. The (A-8) and (A-10) exposures exhibit depletion zones, uniform oxidation and adherent, glassy oxides. The (A-5) exposure shows nonuniform oxidation and a nonadherent oxide. The zirconium diboride-base composites exhibit slightly higher recession and depletion rates than the hafnium diboride-base composites.

Kinetic studies for times up to two hours have been performed in the small furnaces for ZrB₂ +20%SiC(A-8) between 3515° and 3850° F and for ZrB₂+14%SiC+30%C(A-10) between 3500° and 3764° F. Protective behavior is observed after two hours at 3700° F and one hour at 3850° F for the (A-8) composite. Rapid oxidation takes place for longer times at 3850° F due to the complete loss of silicon carbide after one hour at this temperature. The (A-10) composite exhibits protective behavior for one hour at 3650° F but non-protective behavior after longer times at 3650° F or at higher temperatures. These results are illustrated in Figures 8 and 9.

Cyclic exposures were not performed on these composites. Low temperature exposures on ZrB₂+14%SiC+30%C(A-10) between 1200° and 2800°F (Tests 1259, 1260 and 1261, Table 4) indicated extremely small conversion depths and virtually no depletion. Thus, the zirconium diboride-base composites exhibit increasing oxidation rates with increasing temperature as well as higher overall oxidation rates than their hafnium diboride-base counterparts.

5. RVA(B-5), PG(B-6), BPG(B-7), PT0178(B-9) and AXF-5Q Poco(B-10) Graphites

Table 5 and Figures 2 and 3 summarize the results obtained for the graphite candidate materials. The oxidation rates for these materials are insensitive to temperature changes between 2800° and 4200°F. Little effect of flow rate is observed between 0.9 and 3.6 ft/sec. However, higher rates of oxidation are observed as the rate is increased to 7.2 and 9.0 ft/sec. These results indicate that air oxidation at 1-9 ft/sec is supply limited at a rate of 0.2-0.3 mils/sec for all of the graphite candidates with the exception of PT0178(B-9). This is due to the lower density of this material. When these results are compared with those of high velocity CG/HW tests and HG/CW are plasma tests presented in other reports of this series (6.7.8)*, it is apparent that the oxidation rates are controlled by the testing environment to a greater extent than by the oxidation kinetics.

Post-exposure photomicrographs of the graphites are presented in Figures 37-46. The longitudinal and transverse sections shown for RVA(B-5), PG(B-6) and BPG(B-7), Figures 37-42, indicate their relative densities with the pyrolitic materials (B-6) and (B-7) having higher densities than (B-5). The longitudinal section of BPG(B-7) (Test 207, Table 5) shown in Figure 41 indicates incipient delamination. The BPG(B-7) material showed a greater frequency of this behavior than PG(B-6). Figures 43 and 44 show typical post-exposure photomicrographs of PT0178(B-9). Its random fibrous structure is clearly evident and uniform oxidation is thus observed. Figures 45 and 46 show post-exposure photomicrographs of AXF-5Q Pocc(B-10). The

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^{*}An extensive discussion of this problem is given in Reference (8). CG/HW and HG/CW results are presented in References (6) and (7) respectively.

extremely fine grain size of this material is illustrated by electron micrographs, Figures 47 and 48, at 13000X. These show two levels of structure at approximately 0.05 mils and 0.002 mils.

There have been no kinetic, cyclic or low temperature studies performed on the graphite candidates.

6. Siliconized RVC Graphite, Si/RVC(B-8)

Air oxidation results for Si/RVC(B-8), consisting of a four mil coating of SiC on RVC graphite, are given in Table 6 and Figure 3. The coating provides protection for one hour at 3100°F. Above this temperature, the coating flows and failure occurs leading to graphite-type oxidation rates. Coating failures were observed for all exposures above 3100°F. Figures 49 and 50 show post-exposure photomicrographs of Test 1048 after one hour at 2806°F at an air flow rate of 1.8 ft/sec. The coating system survived these conditions.

Kinetic studies were performed at 3016° and 3102°F for times between 15 minutes and two hours. No coating failures were observed at the lower temperature, but a partial coating failure occurred during the second hour at 3102°F. Four - thirty minute cycles at 2974°F (Test 866, Table 6) did not lead to failure, but failure did occur during the fourth cycle at 3098°F (Test 1101) which agrees with the kinetic results at this temperature.

7. $\frac{\text{HfC+C(C-11) and ZrC+C(C-12)}}{\text{HfC+C(C-11)}}$

Table 6 and Figures 4 and 9 contain the results for the hypereutectic carbide candidate materials. The results of one hour exposures between 1200° and 4200° F show little change of conversion depth with temperature. Recession values averaging 60 mils for HfC+C(C-11) and 80 mils for ZrC+C(C-12) are obtained over the entire temperature range with slight decreases in rate near 3450° F. Post-exposure examination of these materials reveals that the heavy oxide which forms is "puffy" below 3450° F. However, above this temperature a dense, adherent oxide forms. This behavior is illustrated in Figures 51-56 which show the results of Tests 973 and 987 for HfC+C(C-11) at 3279° and 4054° F, and Tests 988 and 1031 for ZrC+C(C-12) at 3058° and 3645° F. This transition in behavior (from puffy to adherent oxide) undoubtedly gives rise to the flat conversion depth vs. temperature curves shown in Figure 4. Thus, oxidation may be supply limited at low temperatures. Reference to Figures 53-56 shows that preferential oxidation of the primary graphite flakes occurs and that the oxides contain voids which correspond to the original location of the graphite flakes. No clear dependence on air flow rate was observed between 0.9 and 7.2 ft/sec for the hypereutectic carbides.

Kinetic studies performed in the small furnaces at temperatures between 2800° and 4000°F for times up to two hours reveal the very interesting result that the oxidation rate of HfC+C(C-11) decreases with increasing temperature between 2800° and 3600°F. Above 3800°F, the rate increases with temperature, as shown in Figure 9. Similar results are noted for ZrC+C(C-12) which exhibits a decrease in oxidation rate between 2800° and 3400°F, and an increase in rate above 3600°F. These observations

are consistent with the transition in the adherence of the oxide noted above. Obviously, the puffy oxide existing below 3450°F does not afford protection whereas the more dense oxide formed above 3450°F does protect the hypereutectic carbides and improves their registance to oxidation. Cyclic exposures on HtG+C(C-11) and ZrC+C(C-12) (Tests 1114 and 1120, Table 6, respectively) yielded identical results to those obtained in the two hour kinetic tests.

B. JTA(C-ZrB₂-SiC)(D-13), KT-SiC(E-14), JT0992 (C-HfC-SiC)(F-15) and JT0981(C-ZrC-SiC)(F-16)

Tables 6, 7 and 8 and Figures 5, 6, 10, 13 and 15 present the data for silicon carbide and the JT-composites. At low temperatures, JT0992(F-15) and JT0981(F-16) exhibit high oxidation rates due to their high graphite content and the fact that HfC or ZrC, and SiC cannot contribute protective oxides below 2800°F. By contrast, JTA(D-13) exhibits much lower oxidation depths between 1200° and 2700°F due to the formation of B₂O₃. Based on these observations, and those preceding for the hypereutectic carbides, it appears that SiC additions contribute oxidation protection above 2800°F, HfC/ZrC additions supply protection above 3400°F, while the presence of boron is required to protect graphite below 2800°F. Variation of air flow rate between 0.9 and 7.2 ft/sec has little effect on JT0981(F-16). However, JTA(D-13) and JT0992(F-15) show a marked dependence on air flow rate suggesting a supply limited reaction for these composites. The results of arc plasma exposures (7) at Mach 0.3-0.5 and one atmosphere stagnation pressure at temperatures between 3500° and 4000°F are in agreement with this conclusion.

Typical post-exposure microstructures of the JT-composites are shown in Figures 57-62. The three matrix phases are clearly distinguishable in each case. X-ray diffraction analysis of the oxide coatings revealed the presence of monoclinic ZrO₂ plus some lines which could be indexed as ZrC in JTA(D-13), and only monoclinic HfO₂ and ZrO₂ in JT0992 (F-15) and JT0981(F-16).

Kinetic studies have been performed in both large and small furnaces for these materials. Figure 10 illustrates the small furnace results, Figure 13 the large furnace, and Figure 15 compares the two. It is clear that oxidation rates for the JT-composites are extremely sensitive to the testing facility. JTA(D-13) exhibits protective behavior at 3400°F and linear behavior at 3500°F in the small furnace while linear behavior at 3350°F is observed in the large furnace. JT0992(F-15) exhibits linear behavior in large furnace tests at 3616°F but protective behavior at 3600°F and borderline behavior at 3700°F in small furnace tests. JT0981(F-16) exhibits linear behavior in large furnace tests at 3573°F but borderline behavior at 3600°F in the small furnace. The higher rates of oxidation noted in the large furnace may be due to air supply or temperature differences, the former most probably being the case although this conclusion has not been validated. Samples tested for 120 minutes in both facilities, however, should not show temperature differences since pyrometers are monitoring their temperatures continuously.

Cyclic exposures of JTA(D-13) at 2894°F (Test 945, Table 7) using four - thirty minute cycles yielded a conversion depth of 14 mils as compared with 8 mils after two hours of uninterrupted exposure. Cyclic

exposures of JT0992(F-15) at 3518°F (Test 914, Table 7) and JT0981(F-16) at 3450°F (Test 842, Table 8) yielded virtually identical results to those obtained for uninterrupted tests. Consequently, it appears that cyclic exposures do not produce additional oxidation as compared with uninterrupted exposures at temperatures where protective oxidation takes place.

The results for KT-SiC(E-14) are presented in Table 6 and Figures 5, 10, 13 and 15. One hour exposures indicate rapid degradation above 3500°F. In addition, Tests 570 and 571 performed by insertion of samples into a hot furnace showed similar results. These results differ from those made during high velocity CG/HW induction heating experiments where (E-14) survived exposures at 4700°F and 150 ft/sec (6). Typical post-exposure photomicrographs are shown in Figures 63 and 64. The results of small furnace, large furnace and comparative kinetic studies shown in Figures 10, 13 and 15 indicate similar dependence on test facility as in the case of the JT-composites. Rapid oxidation is observed in the large furnace after 60 minutes at 3470°F, whereas considerably slower rates are observed after two hours at 3500°F. Cyclic exposures at 3394°F (Test 878, Table 6) indicate accelerated oxidation. In general, then, the oxidation of KT-SiC (E-14) is characterized by low rates below 3450°F, a sharp transition from protective to nonprotective behavior at that temperature, and rapid degradation above 3500°F.

9. $WSi_2/W(G-18)$ and Sn-Al/Ta-10W(G-19)

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Table 8 and Figure 5 summarize the results obtained for the coated refractory metal candidate materials. The tungsten disilicide coating on tungsten affords protection up to 3500°F. Four - thirty minute cycles at 3476°F (Test 1068) do not cause coating failure. This coating was developed and evaluated by Nolting and Jeffereys who report degradation near 3600°F due to melting at the W₅Si₃-WSi₂ eutectic (9). Figures 65 and 66 show the results of Test 478 which exposed a WSi₂/W(G-18) sample to flowing air at 3325°F for one hour. The central W₅Si₃ zone shown in Figure 66 is 5.0 mils wide. Figure 67 plots the log of W₅Si₃ zone width vs. reciprocal temperature results obtained for all types of tests conducted within the program along with similar data for the growth of W₅Si₃ measured by Bartlett and Gage (11) and Mo₅Si₃ on MoSi₂/Mo measured by Perkins and Packer (10). The latter values were converted parabolically (10) from 30 minute to 60 minute exposures for direct comparison. The furnace test data (filled circles) are in good agreement with the results of Bartlett and Gage (11) and Perkins and Packer (10), as are results of oxygen pickup experiments (to be discussed below). However, slight deviations are noted in the results for high velocity CG/HW tests (6) and considerable deviation is observed for HG/CW are plasma exposures (7).

The emittance values employed in correcting optical brightness temperatures at $\lambda = 0.65\mu$ to true temperatures for the latter tests was $\epsilon = 0.60$ below 3500°F in Part III-Volume II(6). The large differences observed between furnace tests and arc plasma tests (squares in Figure 67) are undoubtedly due to temperature gradients through the coating. These gradients could be as high as several hundred degrees fahrenheit (7), and would then lead to reduced diffusion rates. However, this explanation does not offer a means for understanding the relative widths observed in the high velocity CG/HW test samples (triangles in Figure 67) which were inductively heated.

Figures 68 and 69 illustrate the post-exposure microstructure obtained for Test 485 exposed at 3532°F where the WSi₂ coating failed in an irregular manner. Some coating was still left on the surface after a 60 minute exposure. Kinetic studies for up to two hours at 3450°F did not produce failures in either the small or large furnaces.

The results obtained for Sn-Al/Ta-10W (G-19) indicate that this coating system offers protection at one atmosphere for one hour up to approximately 3200°F. Above this temperature, failure of the coating occurs. These results are in general agreement with those of Perkins and Packer (11, pages 294-295). The failure mechanism appears to be loss of tin and oxidation of the TaAl, layer as illustrated in post-exposure photomicrographs, Figures 70-73. Figure 70 shows the coating after exposures at 2624°F and 3092°F. The former section shows the two mil TaAl, zone and six mil Sn overlayer which is virtually identical to the as-received material (2). The latter section is typical of results above 2800°F, i.e. losses in the TaAl, zone and Sn overlayer are encountered. Figures 72 and 73 show coating failure and oxidation of the Ta-10W substrate.

Tests 1192 and 1193 (Table 8) were performed using HfC+C(C-11) pedestals in place of ZrO₂ to verify that the Sn-Af coating failure temperature near 3200°F was not due to reaction with ZrO₂. These tests confirm the 3200°F protection limit with failure occurring at 3317°F. Cyclic exposures at 2990°F (Test 1069, Table 8) did not lead to coating failure, nor did two hour kinetic study exposures at this temperature.

10. $\frac{\text{SiO}_2 + 68.5^{\text{W}}/\text{oW}(\text{H}-22), \text{SiO}_2 + 60^{\text{W}}/\text{oW}(\text{H}-23)}{\text{SiO}_2 + 35^{\text{W}}/\text{oW}(\text{H}-24)}$

Table 9 and Figures 7 and 11 display results for the silica-tungsten composite materials. The (H-24) composite containing 35^W/oW exhibits viscous flow at temperatures above 3000°F. Low oxidation rates are noted for (H-22) and (H-23) at temperatures up to 3900°F. Above this temperature, substantial viscous flow occurs. Low temperature exposures of (H-23) between 1200° and 2700°F (Tests 1239-1243, Table 9) indicate rapid attack of the tungsten below the fusion range of SiO₂. Similar results were obtained in high velocity CG/HW tests (6) in the range from 1700° to 2700°F. Tests 1239-1242 showed cracking of the samples due to oxidation of tungsten and the growth of tungsten oxide. Post-exposure photomicrographs of these composites, Figures 74-79, illustrate depletion of tungsten from the surface. Figure 78 illustrates flow in SiO₂+35W/oW(H-24) at 3042°F.

Figure 11 contains the results of kinetic exposures on $SiO_2+60^W/oW(H-23)$ at 3672^O and 3846^OF . Although the observed recessions are low, the behavior is complicated by plastic flow of SiO_2 and surface depletion of tungsten from all samples. The width of the depleted region becomes larger with time. Cyclic exposures of four - thirty minute cycles were performed for $SiO_2+68.5^W/oW(H-22)$ and $SiO_2+60^W/oW(H-23)$ near 3840^OF (Tests 1153 and 1144 respectively, Table 97. An increase in viscous

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flow is noted relative to uninterrupted two hour exposures at the same temperature. The amount of tungsten depletion in the cyclic exposures is also greater than that observed in the uninterrupted tests.

11. Hf-20Ta-2Mo(I-23)

Results of Hf-20Ta-2Mo(I-23) alloy exposures are given in Table 9 and Figures 7, 11, 12 and 14. One hour exposures indicate a generally increasing oxidation rate up to the melting point of the alloy at approximately 3850°F. This is in general agreement with other results for this alloy (12, 13). Low temperature exposures between 1200° and 2700°F showed small recession values despite the observation by the supplier Wah Chang, that "extensive oxidation" takes place during forging in air at 1400° - 1800°F. It was estimated that a one hundred mil scale formed during working in air for one hour. Based on present results it must be concluded that the "one hundred mil scale" formed during forging results from the combined effects of working, thermal cycling and oxidation. The microstructures shown in Figures 80-83 are comparable to those observed earlier (12, 13). In all cases, the contaminated metal matrix is separated from the oxide by a "subscale" region containing stringers of tantalum. This feature is clearly illustrated in Figures 81 and 83.

The results of fifteen minute to two hour kinetic studies are presented in Figures 11, 12 and 14 for small furnace, large furnace and comparative results. Protective behavior is observed at 3479°F in small furnace exposures, but rapid attack occurs after 60 minutes at 3405°F in the large furnace. Four - thirty minute cycles at 3312°F (Test 893, Table 9) resulted in accelerated oxidation. However, at 3423°F (Test 621) the oxidation rate was not accelerated.

C. Summary of Furnace Oxidation Results

Based on the results presented above for oxidation in flowing air at one atmosphere for one hour, the candidate materials can be ranked as follows:

The coated candidate materials Si/RVC(B-8), Sn-Al/Ta-10W(G-19) and WSi₂/W(G-18) indicate temperature limitations of 3060°F, 3200°F and 3450°F respectively. KT-SiC(E-14) exhibits low oxidation rates up to 3500°F at which point a sharp increase in rate occurs. SiO₂+35W/oW (H-24) exhibits viscous flow at temperatures as low as 3000°F.

Oxidation rates for the graphite candidate materials RVA(B-5), PG(B-6), BPG(B-7), PT0178(B-9) and AXF-5Q Poco(B-10) are insensitive to temperature in the range of 2800° to 4200°F but sensitive to air flow rates between 0.9 and 9.0 ft/sec. Supply limited oxidation rates of 0.2-0.3 mils/sec are observed for the graphites in this temperature range.

In general, materials containing HfB₂ or HfC have higher temperature limits than comparable materials containing ZrB₂ or ZrC. The hypereutectic carbides HfC+C(C-11) and ZrC+C(C-12) exhibit constant recession levels of 50-100 mils in one hour tests at temperatures between 1200° and 4200°F, with a transition from puffy to adherent oxides above

3450°F. JT0992(C-HfC-SiC) (F-15) exhibits slightly better behavior than JT0981(C-ZrC-SiC) (F-16) which in turn exhibits better high temperature behavior than JTA(C-ZrD₂-SiC) (D-15) attnough the (F-15) and (F-16) composites have low temperature inversions due to the fact that they do not contain boron. Hf-20Ta-2Mo(I-23) is comparable in behavior to JT0961(F-16) between 3000° and 3800°F, but the alloy melts near 3850°F. ZrB₂(A-3) is also comparable to (F-16) and (I-23) in this range, but melts at 5585°F. HfB₂₋₁(A-2) and (A-6) are more resistant to oxidation than ZrB₂(A-3). ZrB₂₋₁+20%SiC(A-8), ZrB₂₊₁ 14%SiC+30%C(A-10) and Boride Z(A-5) are ranked in order of oxidation resistance for temperatures up to 3800°F. Even the least resistant (A-5) material is superior to pure ZrB₂(A-3). However, all these composites become comparable to (A-3) above 3800°F due to rapid depletion of SiC which provides protection below this temperature. The HfB₂+SiC composites (A-4), (A-7) and (A-9) are superior to the ZrB₂ composites, and exhibit the best overall behavior for the furnace oxidation conditions studied. Below 3900°F, the SiO₂+W composites (H-22) and (H-23) also yield low recession rates, but viscous flow occurs above 3900°F and tungsten oxidation occurs below 2700°F. Above 3900°F, the hypereutectic carbides (C-11) and (C-12) become competitive with the diborides and diboride-silicon carbide composites.

A summary of the results of the small furnace kinetic studies is presented in Figure 84 which indicates the temperature limits over which protective behavior for a two hour period is observed. Asimple summary would be as follows: HfB₂ (A-2) - 3700°F, ZrB₂(A-3) - 3400°F, HfB₂ +SiC(A-4) and (A-7) - 3790°F. ZrB₂ +SiC(A-8) - 3750°F, ZrB₂+SiC+C(A-10) - 3600°F, HfC+C(C-11) - between 3200° and 4000°F, ZrC+C(C-12) - between 3100° and 3600°F, JTA(D-13) - 3250°F (large furnace) and 3400°F (small furnace), KT-SiC(E-14) - 3450°F (large furnace) and 3500°F (small furnace), JT0992(F-15) - 3520°F (large furnace) and 3600°F (small furnace), JT0981(F-16) - 3390°F (large furnace) and 3500°F (small furnace), SiO₂+60W/OW(H-23) - 3850°F, and Hf-20Ta-2Mo(I-23) - 3380°F (large furnace) and 3480°F (small furnace). The poor low temperature behavior of (C-11), (C-12) (F-15), (F-16) and (H-23) should be kept in mind when evaluating these results.

Comparison of the recessions after two hour continuous exposures with the results obtained following four - thirty minute periods interrupted by cooling cycles yielded similar results for HfB₂ (A-2), ZrB₂(A-3), HfB₃+20% SiC(A-4), Si/RVC(B-8), HfC+C(C-11), ZrC+C(C-12), JTA(D-13), JT0992(F-15), JT0981(F-16), WSi₂/W(G-18) and Sn-Af/Ta-10W(G-19). In each case, the exposure temperature was below the two hour protection limit or the failure temperature for coated materials. KT-SiC(E-14), SiO₂+68.5W/OW(H-22), SiO₂+60W/OW(H-23) and Hf-20Ta-2Mo(I-23) exhibited more rapid degradation in the cyclic exposures.

Comparison of the exidation rates in the small furnaces (7/8 inch inside diameter) and the large furnaces (2 inch inside diameter) given in Figures 14 and 15 indicate no differences for HfB₂ (A-2) and ZrB₂(A-3). However, more rapid exidation was observed in large furnace tests on HfB₂+20%SiC(A-4) (compared with small furnace tests on (A-7)), JTA(D-13), KT-SiC(E-14), JT0992(F-15), JT0981(F-16) and Hf-20Ta-2Mo(I-23). These differences are most probably due to differences in air supply.

III. ARGON INERT TESTS

A. Introduction

Furnace exposures (CG/HW) have been performed for selected candidate materials under conditions employed to perform air oxidation tests. However, the exposures were performed in flowing argon at 0.9 ft/sec. Test conditions covered the temperature range between 3000° and 4200° F for one hour in the small furnaces (7/8 inch inside diameter). The purpose of these tests was to determine the effect of temperature exposure in the absence of air on the behavior of some of the candidate materials. The results of the argon inert tests are summarized in Table 10. Material recession and weight change were determined by post-exposure metallography and gravimetric techniques. The candidate materials investigated were Si/RVC(B-8), PT0178(B-9), JTA(D-13), JT0992(F-15), JT0981(F-16), WSi₂/W (G-18) and SiO₂+60W/oW(H-23).

B. Results of Argon Inert Test Exposures

Reference to Table 10 indicates that exposures of Si/RVC (B-8) in argon at temperatures up to 3800°F caused little change in one hour. At 4000°F, however, most of the SiC coating was removed during a one hour exposure. The temperature limit of 3060°F noted for this material in air is due to the formation of volatile exidation products. In argon, destruction of the 4 mil SiC coating proceeds via vaporization.

Negligibly small changes in dimensions and structure were noted for PT0178(B-9), JT0992(F-15) and JT0981(F-16) at temperatures up to 4200°F in argon, as shown in Table 10. At 4200°F, JTA(D-13) resulted in an internal structure which suggests melting of the ZrB₂-SiC phases. Figures 85 and 86, showing post-exposure microstructures of Test 1200, illustrate the melting of (D-13).

Exposures of WSi₂/W(G-18) at temperatures above 3500°F resulted in melting of the coating, as was observed in air. The thickness of W₅Si₃ zones observed in Tests 1203 (3101°F) and 1205 (3288°F) after one hour were 1.28 and 2.20 mils respectively. These values are lower than those observed after exposure in air at one atmosphere. Figure 67 indicates W₅Si₃ zone widths which are nearly twice as large for air exposures as those observed in these argon inert tests.

The inert tests performed on SiO₂+60W/oW(H-23) at temperatures between 3800°F and 4000°F showed evidence for SiO₂ sublimation and cracking of the specimens upon cooling.

IV. RESULTS OF OXYGEN PICKUP AND GAS ANALYSIS TESTS

A. Introduction

Samples of JTA(C-ZrB₂-SiC) (D-13), JT0992(C-HfC-SiC) (F-15), JT0981 (C-ZrC-SiC) (F-16), WSi₂/W(G-18) as well as pure iridium and iridium alloyed with other platinum group metals were inductively heated between 2900°F and 4000°F during exposure to flowing mixtures of oxygen and helium. Flow rates of 0.2 ft/sec at oxygen partial pressures of 0.013 to 0.20 atmospheres and total pressures of one atmosphere were employed. Oxidation behavior was monitored by continuously measuring the rate at which oxygen was removed from the stream. The measurements of oxygen pickup rate were complemented by continuous measurements of CO and CO₂ formation in the case of the graphite composites. A complete description of the experimental procedures is given in Part II-Volume II (1) of this series, along with a detailed discussion on calculation of recession rates from the data obtained.

B. Results

1. JTA(C-ZrB2-SiC) (D-13)

The composition of JTA(D-13) in terms of measured weight percentages is presented elsewhere (2). Conversion of the compositional data to atom percentages (neglecting the fact that the weight data does not add up to 100%) indicates that the JTA(C-ZrB,-SiC) (D-13) composite contains 74.4 atomic per cent carbon and 5.4a/o, 6.2a/o and 14.0a/o of silicon, zirconium and boron respectively. Phases identified microstructurally include graphite. SiC and ZrB, (2). Table 11 summarizes the initial weights and dimensions of the JTA samples that were exidized and gives the conditions of temperature, pressure, time and flow rate employed in the exidation experiments.

A derivation of the expression for S, the signal from the thermal conductivity cell, is given in Part II-Volume II (1) as:

$$S = \frac{RT}{\phi} k_1 \sqrt{\frac{w_{CO_2}}{MCO} + \frac{w_{O, sol.}}{MO_2} - \frac{w_{CO}}{2MCO}}$$
 (1)

where \mathbf{w} and \mathbf{M} are the weights per unit time and molecular weights of specie x respectively, k_1 is a calibration constant and ϕ is the volume flow rate. This relation applies for carbon-containing samples such as the JT-composites. In Figure 87, the quantity

$$\frac{{}^{\text{W}}\text{CO}_2}{{}^{\text{M}}\text{CO}_2} + \frac{{}^{\text{W}}\text{O, sol}}{{}^{\text{M}}\text{O}_2} - \frac{{}^{\text{W}}\text{CO}}{{}^{\text{2}}\text{M}}$$

in moles/cm² is plotted against time. The data points were obtained by integrating the experimental rate curve over time, and are based on the initial

surface area. The reaction rate at 2900°F and 11.9 Torr (Sample XXVIII-28, Table 11) is apparently linear. The measured recession for this sample observed by sectioning and metallographic measurements is 17 mils from change in length and 18 mils from change in diameter. Hence, the ratio of initial to final surface area is 1.49. On the basis of a linear rate law, all the points can be corrected for surface area as shown in Figure 87. The corrected points still fall on a straight line, but of higher slope than the original curve.

The observed (uncorrected) reaction rate of JTA at 2910°F and 40.4 Torr (XXVIII-33) appears to decrease considerably with time. The measured recession of 18 mils based on length and 25 mils based on diameter corresponds to a ratio of initial to final surface area of 1.68. The deviation from linearity is still apparent in the linearly corrected points plotted in Figure 87, although it is not as pronounced as in the original data. In Figure 88, a parabolic plot of the corrected points is shown. The parabolic rate law appears to be followed to an excellent approximation over the period of observation.

Qualitatively, (Sample XXVIII-28), (2900°F and 11.9 Torr) was covered with a very thick cage-like oxide that fractured away from the sample in large chunks on cooling. JTA XXVIII-33, exposed at about the same temperature at a higher oxygen pressure, 40.4 Torr, also oxidized extensively. A thick white oxide was observed on the curved sides of the cylindrical sample, and a thinner dark grey, slightly glassy oxide was seen on the two flat faces.

The quantitative difference in behavior between XXVIII-28 and XXVIII-33 is apparent in Figure 87. At the higher pressure (XXVIII-33) the initial rate of oxidation is higher, but the rate definitely drops off with time. The total extent of oxidation corrected for surface area is equal for the two samples after approximately one hour. Extrapolation beyond one-hour would suggest greater oxidation resistance over an extended period at the higher pressure. If the effect of increased pressure is to accelerate the formation of a protective film, then one might expect to observe deviations from linearity at longer times at 10 Torr and very early at 150 Torr at the same temperature.

At a temperature of 3740° F and oxygen partial pressure of 11.9 Torr (XXVII-31), the results might have been influenced by reaction with the thoria support rods. The recession rate, calculated from a linear extrapolation of the carbon consumption data, is given in Table 11. Table 11 also gives the number of moles of O_2 used to form CO_2 , CO, and solid oxides, respectively. The major product is seen to be CO.

A series of tests run at 3663°F (Tests XXIX-8, 12, 17, 20 and 22, Table II) gave calculated recession rates as high as 500 mil/hour. Reference to Figure 5 shows that JTA(D-13) exhibits a rate near 200 mil/hour at this temperature in furnace tests.

2. JT0992(F-15)

The composition of JT0992(F-15) in terms of measured weight percentages was presented elsewhere (2). Conversion of the compositional data to atom percentages indicates that the JT0992(F-15) (C-HfC-SiC) composite contains 79.1 atomic percent carbon, 11.8 atomic percent silicon and 9.0 atomic percent hafnium. Phases identified microstructurally include graphite, SiC and HfC (2). Table 12 summarizes the oxygen pickup data for JT0992(F-15). Figure 89 shows the integrated rate curve for JT0992 (F-15) sample XXVIII-37 exposed at 2950°F and a partial pressure of 40.1 Torr of oxygen. When the ordinate is negative, the number of moles of O2 consumed in the formation of CO exceeds the sum of the number of moles of O2 used to form both CO2 and solid oxides. The maximum in Figure 89 may indicate that solid surface oxide is building up and acting to retard the oxidation of carbon to CO.

In Figure 90, data obtained at 40.5 Torr at higher temperatures, 3470 and 3550°F, are plotted. The 3470°F data seem to be controlled initially by rapid evolution of CO, and ultimately, by a linear oxidation process. The strong negative peak is not seen in the 3550°F data, but the period of linear increase is followed by a plateau, where CO evolution may be causing rupture of a solid oxide film, and finally by another period of linear rate that may represent repair of a solid oxide film. The relative proportion of CO₂ in the product is much higher at 3470°F than at 2950°F for an oxygen pressure of 40 Torr (Table 12).

On the basis of the calculated recessions of 14.7 and 21.2 mils/hr., for XXVIII-47 and XXVIII-50, respectively, the ratios of initial to final surface areas are 1.25 for XXVIII-47 and 1.44 for XXVIII-50. Correction for surface area changes would remove the apparent curvature in the regions of increasing ordinate in Figure 90, and the rates at these high temperatures, around 3500°F may be taken as linear. Near 2950°F, the oxidation rate for sample (XXVIII-37) decreases with time and may be assumed to be parabolic, or possibly even logarithmic. Qualitatively, the extensive exidative degradation near 3500°F prevented observation of meaningful weight change data after exidation. By contrast, at 2900 and 2950°F the exidation resistance was excellent.

3. JT0981(F-16)

The composition of JT0981(C-ZrC-SiC) (F-16) composite in terms of measured weight percentages was presented elsewhere (2). Conversion of the compositional data to atom percentages indicated that the composite contains 81.5 atomic per cent carbon, 6.6 atomic per cent zirconium and 12.2 atomic per cent silicon. Phases identified microstructurally include graphite, SiC and ZrC (2).

Table 13 summarizes the experimental data on JT0981 (F-16). The data obtained near 2935°F at 10 and 40 Torr are plotted in Figure 91; the data obtained near 3550°F at the same two pressures are plotted in Figure 92. At 10 Torr, oxidation of carbon to CO seems to be the dominant process. At 40 Torr, the number of moles of O₂ going into CO₂ and solid

oxides increases relative to that going into the formation of CO. These conclusions are also confirmed by data given in Table 13. Around 2935°F, the rate of reaction definitely decreases with time. The data of Figure 91 are replotted on a parabolic basis as

$$\begin{bmatrix} \frac{W_{CO_2}}{M_{CO_3}} + \frac{W_{O, sol}}{M_{O_3}} - \frac{W_{CO}}{2M_{CO}} \end{bmatrix}^2$$
 vs. time in Figure 93. The over-all

reaction rate is seen to be dropping more rapidly with time than predicted by the parabolic rate equation, indicating a highly protective oxidation mechanism. Near 3550°F recession rates would be expected to be linear on the basis of the data in Figure 92.

4. Calculated Recession Rates for the JT-Composites

The recession rates listed in Tables 11-13 were calculated on the assumption that the rate controlling factor is the oxidation of carbon. The amount of carbon initially present in each sample can be calculated from the initial weights given in the tables and the carbon analyses listed above. The percentage of carbon converted to oxide can then be obtained from the net carbon consumption data in the tables.

If x represents the net sample recession, and if the initial volume Vo of the sample is given by:

$$V_0 = 2\pi r_0^2 h_0$$
 (2)

then the final volume V may be written as:

$$V = 2\pi (r_0 - x)^2 (h_0 - 2x)$$
 (3)

The fractional decrease in volume then becomes:

$$\frac{V_{O}-V}{V_{O}} = \frac{2r_{O}(h_{O} + r_{O}) \times - (h_{O} + 4 r_{O}) \times^{2} + 2x^{3}}{r_{O}^{2} h_{O}}$$
(4)

If we equate $\frac{V_0-V}{V_0}$ with the percentage of carbon consumed, as given in Tables 11-13, we may calculate values for x, the net sample recession. The latter results are contained in Tables 11-13 for comparison with metallographic observation.

5. $WSi_2/W(G-18)$

The data on WSi₂ coated W is summarized in Tables 14 and 15. Figure 94 is a plot of total oxygen consumption, in g/cm², vs. time for run XXVIII-55. This run was aimed at determining the failure temperature for the WSi₂/W system at 10.7 Torr. The sample was heated to 3055°F, maintained that temperature for an hour, and was then heated successively, without intermediate cooling to 3210, 3285, 3375, 3440, 3510, and 4045°F. A protective film is apparently established rapidly at 3055°F,

and subsequent growth is very slow and essentially independent of temperature up to 3285°F. At 3375°F, a definite increase in oxidation rate was noticed. At 3440°F, a pronounced increase in oxidation rate occurred immediately upon raising the temperature. However, the curvature with time indicates that the rate was beginning to slow down, and that a protective film might have been re-established, perhaps to be ruptured again by evolution of gaseous oxides formed at the oxide/coating interface. At 3510 and 4045°F, rapid linear, nonprotective oxidation, characteristic of definite failure is seen. The failure temperature at 10 Torr thus lies between 3440°F and 3510°F, probably closer to 3440°F.

Data from a 150 Torr failure run (XXVIII-58) are plotted in Figure 95. Protective oxidation, characterized by rapid build-up of a silica film, and exceedingly slow subsequent oxide growth, approximately independent of temperature is noted at 3320 and 3475°F. When the r.f. power was increased for the next step, the temperature climbed rapidly to 3805°F, and the protection was lost. The failure point at 150 Torr thus appears to be greater than 3475°F but less than 3805°F.

For run XXVIII-68, at 3280°F and 149 Torr, one would have expected, based on the results obtained with XXVIII-58, protective oxidation, and low total oxygen consumption. The actual experimental results, plotted in Figure 96 do show eventual highly protective oxidation, but only after close to 0.2 g/cm² of oxygen had been consumed, compared to 0.006 g/cm² under comparable conditions shown in Figure 95. If the coating in XXVIII-68 had pin holes or if the coating composition were W₅Si₃ or W₃Si for XXVIII-68 and closer to WSi₂ for XXVIII-58, the results might be explained. In a 3370°F run at 150°Torr shown in Figure 96 oxidation is seen to be linear and catastrophic. A decreasing temperature is probably responsible for the last points lying off the line.

In runs XXVIII-70 and XXVIII-72, also plotted in Figure 96, the oxidation is seen to be linear, indicating the continual evolution of SiO(g) and the failure to form a protective SiO₂(s) film at all. Recessions in Table 14 were calculated on the basis of the assumed reaction:

$$WSi_2 + \frac{5}{2}O_2 \rightarrow WO_3(g) + 2SiO(g)$$
 (5)

Table 15 summarizes the results of single exposure experiments at oxygen partial pressures of 10 Torr and 149 Torr. The above results indicated failure temperatures between 3400° and 3500°F at 10 Torr and between 3450° and 3550°F at 150 Torr. These values were obtained on samples which were exposed at a series of ascending temperatures. In the single exposure experiments, Test XXIX-43 shows the onset of failure at 3460°F at 10 Torr, while Tests XXIX-53 and 57 define the one atmosphere failure temperature at about 3500°F. Figures 97-100 show post-exposure macrophotographs of the WSi₂/W(G-18) samples as well as the appearance of the W₅Si₃ zones formed at 3370°F in one hour. Reference to Figure 67 shows that the oxygen pressure does not influence the width of the zone, and that the widths obtained in these tests agree quite well with those of Bartlett and Gage (11).

Discussion of the oxidation of WSi₂ must take into account the different mechanisms that are operative in the protective and nonprotective

ranges. The remarkable exidation resistance of WSi₂ up to 3100°F in air or pure exygen has been ascribed (14), (15) to the rapid formation of a slow-growing, self-healing film of pure SiO₂. The initial exidation reaction on the bare WSi₂ surface is probably:

$$WSi_2 + \frac{7}{2} O_2 \rightarrow WO_3(g) + 2SiO_2(s)$$
 (6)

Once a coherent silica film has formed, further growth may depend upon diffusion of oxygen to the SiO₂/WSi₂ interface. It is generally believed that silicon is then oxidized preferentially, so that the reaction at the interface becomes:

$$W_{Si_2} + \frac{7}{5}O_2 \rightarrow \frac{1}{5} W_5Si_3 + \frac{7}{5}SiO_2$$
 (7)

As oxidation proceeds, layers of W_3Si and eventually even pure W should develop beneath the silica film. The primary factor controlling the over-all recession of the coated system should be reaction (6), since it is much more rapid than reaction (7) and results in greater silicide consumption. If wo is the measured oxygen consumption (g/cm^2) , then $d_{\{1\}}$, the WSi 2 recession in mils, based on reaction (6) is given by:

$$d_{(1)} = \frac{M_{WSi_2}}{7 M_O} \left(\frac{w_O}{\rho_{WSi_2}}\right) \frac{1000}{2.54} = 90.8 w_O$$
 (8)

where M is the molecular weight of X, WSi, is the density of WSi, (9.3g/cc) and 1000 is the conversion factor from cm to mils. Equation (8) has been used to caltulate recession values for those experiments listed in Table 14 where rapid initial oxidation followed by a flat protective region was observed. Subsequent recession d₍₂₎, via reaction (7) will be given by:

$$d_{(2)} = 43.9 w_{O}$$
 (9)

Equation (9) was used to convert oxygen consumption data to recession data for measurements made within the protective region.

Nonprotective oxidation of WSi 2 is associated with two related phenomena: (1) failure to form an SiO2 film at all low oxygen pressures, and (2) rupture of an already existing SiO2 film by SiO(g) evolution. Analagous behavior has been observed for pure silicon (16), and the problem has been analyzed in detail by Wagner (17). Wagner's analysis should also be applicable to silicides if the lowered silicon activity is taken into account. Silicon forms one stable solid oxide, SiO2(s), and a gaseous oxide, SiO(g). If p_{SiO} , the pressure of SiO(g) at the surface of a silicide of activity a g_i , is less than the equilibrium partial pressure $p_{SiO(eq)}$ for the reaction:

$$1/2 \text{ Si } (a_{Si}) + 1/2 \text{ SiO}_2(s) = \text{SiO}(g)$$
 (10)

the condensed oxide will not form. (In general p, will represent the pressure of x at the solid surface.) The condition for a protective SiO₂(s) film to form, or in Wagner's terminology, the point of transition between active and passive oxidation is:

$$p_{SiO}^* = p_{SiO (eq)}$$
 (11)

Since oxygen should react readily at a bare silicide surface, oxidation in the active region will be characterized by $p_{O_2}^{-} << p_{O_2}$ where p_{O_2} is the oxygen partial pressure in the ambient gas stream. From boundary layer theory (18), m_{O_2} , the rate of transport of oxygen towards the surface will be given by:

$$\dot{m}_{O}^{2}(atoms/cm^{2}-sec) = -\frac{2D_{O_{2}}C^{O}_{O_{2}}}{\delta_{O_{2}}}$$
 (12)

where the negative sign denotes motion towards the surface, D_{0} is the diffusion coefficient for O_{2} molecules, $C_{0}^{0} = p_{O_{2}}/RT$ and δ_{0} is the boundary layer thickness for mass transport of O_{2} . Similarly, the rate of transport of oxygen away from the surface as SiO(g) is given by:

$$m_O^+ = \frac{D_{SiO} C_{SiO}^*}{\delta_{SiO}} \tag{13}$$

In the steady state, there will be no net oxygen transport, and therefore, we will have

$$C_{SiO}^* = 2 (\delta_{SiO}/\delta_{O_2}) (D_{O_2}/D_{SiO}) C_{O_2}^{\circ}$$
 (14)

Wagner approximates the ratio of the boundary layer thicknesses by: $(\delta_{SiO} \delta_{O2}) = (D_{SiO}/D_{O2})^{1/2}$. Then, setting $p_{SiO}^* = p_{SiO(eq)}$, he finally solves for the maximum ambient oxygen pressure compatible with a bare silicide surface:

$$p_{O_2}^{\circ} \text{ (max) } = 1/2 \left[\frac{D_{SiO}}{D_{O_2}} \right]^{1/2}$$
 $p_{SiO(eq)} = 0.4 p_{SiO(eq)}$ (15)

The ratio of diffusion coefficients is estimated by Wagner as $(D_{SiO}/D_{O_{1}}) = 0.64$. The equilibrium pressure, $p_{SiO(eq)}$, for reaction (10) is plotted in Figure 101 as a function of temperature for various activities of silicon. Calculations were based on the data given in the JANAF Tables (19). The activity of silicon in WSi₂ is not known, but may be estimated by comparison with activities in the Mo-Si system. For MoSi₂, a_{Si} lies between 0.1 and 1; for Mo₂Si₃, 0.005 < a_{Si} < 0.1, and for Mo₃Si a_{Si} = 0.004. The activities in the W-Si system are expected to be lower by about a factor of two.

If we estimate $a_{Si} = 0.1$ for WSi2, then at an ambient oxygen pressure of 10 Torr (0.013 atm), we find from Figure 101 that active or nonprotective oxidation should be observed on the bare silicide surface at temperatures above 3022 F, where

$$p_{SiO(eq)} = \frac{0.013}{0.4} = 0.03 \text{ atm}$$

Experimentally, passive oxidation was observed at 3055°F (XXVIII-55), active oxidation at 3355°F (XXVIII-70). At an ambient oxygen pressure of 0.2 atm, corresponding to air, active oxidation is predicted at temperatures above 3600°F.

There is a hysteresis in the transition point between active and passive oxidation. The above discussion was concerned with the failure to form a protective silica film as a function of ambient oxygen pressure. Once an SiO₂(s) film has been formed, the ambient oxygen pressure may be permitted to fall well below p_O (max) before oxidative protection is lost. Wagner's analysis (17) gives the lowest ambient oxygen pressure p_O (min) at which a layer of SiO₂ formed at higher pressure is stable. The final equation is:

$$p_{O_2}(min) = 1/2[(1/4)^{2/3} + (1/2)^{2/3}] K^{2/3} \frac{D_{SiO}}{D_{O_2}}$$
 (16)

where K is the equilibrium constant for the reaction:

$$SiO_2(s) = SiO(g) + 1/2 O_2(g)$$
 (17)

Values of p₀ (min) based on JANAF thermodynamic data are plotted against 10³/T in Figure 102. According to Figure 102, even at 4000°F, a silica film once formed should be stable down to oxygen pressures of 4.7 Torr.

Wagner's development is concerned with the effect of reducing the oxygen pressure at constant temperature after a silica film has formed at that same temperature. A problem of equal importance in practice is the stability of a silica film with increasing temperature. If a protective SiO₂ film is grown on the surface of a silicide at some oxygen pressure, and the temperature is raised while maintaining the pressure constant, SiO(g) can be formed via reaction (17) at the silicide/oxide interface. If the equilibrium SiO(g) pressure becomes the same order of magnitude as the ambient pressure, evolution of SiO(g) and consequent film rupture may be anticipated. If $a_{Si} = 0.1$, then the SiO(g) pressure at the silicide/SiO₂(s) interface will become of the order of one atmosphere at a temperature around 3785°F. The experimental failure point was closer to 3600°F. It should be noted that eutectic melting occurs in this sytem at 3650°F.

Iridium-Base Alloys

The oxidation behavior of a series of eight iridium and iridium-base alloys, prepared by D.P. Harmon of Aerojet General Corp., Sacramento, California (20), was evaluated by means of the gas analysis technique (1, 21). A recorder tracing for the oxidation of an Ir-Rh-Re sample is reproduced in Figure 103. The rate of oxygen pickup by the reacting sample in g/min of oxygen consumed, is given as a function of time. Similar curves were obtained in every experiment. The rate of oxidation of all the alloys under study was observed to rapidly reach a maximum level and then to remain linear for time periods that varied from 5-30 minutes. Subsequently, the rate began to drop with time, often in the step wise manner illustrated in Figure 103. Since the oxides of the platinum metals are known to be highly volatile at the temperatures of the present series of experiments, the rate of oxidation is expected to be independent of time. Consequently, the cause of the observed decrease in rate is presently unknown. However, even the initial linear rate is low compared to the true surface reaction controlled rate. Consequently, it is possible that the apparent drop in rate with time is due to changes in the pattern of flow of metal oxides away from the surface and oxygen towards the surface.

Table 16 summarizes the experimental runs completed. Initial sample weights and dimensions and the experimental conditions maintained during oxidation are given. Sample surface temperatures were measured through an optical window with a micro-optical disappearing filament pyrometer. A combination window correction and pyrometer calibration was determined by viewing a G.E. standard lamp with the pyrometer through the same optical window. A further correction is necessary for the emittance of the oxidizing sample. In one experiment an iridium sample was heated in pure helium, flowing at a rate of 0.1 ft/sec to the point of incipient melting. The observed brightness temperature at this point was 3596°F. Application of the window correction brings the brightness temperature to 3686°F. Using the melting point of pure iridium (20), 4430°F, as the true temperature of the sample, the emittance 4 at the melting point can be calculated from Equation 18 (22):

$$\ln \left\{ \left[\lambda, T \right] = \frac{C_2}{\lambda} \left[\frac{1}{T} - \frac{1}{T_{br}} \right]$$
 (18)

where λ is the wave length at which the pyrometer operates ($\lambda = 0.65\mu = 6.5 \times 10^{-5}$ cm in these experiments) C_2 is a constant equal to 2.588 cm R; T^0R , ($T^0F + 460$) is true temperature and T_{c} R is brightness temperature (corrected for window or other extraneous optical effects). The resulting value is $\epsilon = 0.23$. This emittance value is significantly lower than the value quoted in the literature ($\epsilon = 0.30$ at 0.65μ). As indicated in the discussion, the latter was used to calculate the corrected temperatures listed in Table 16 from observed brightness temperatures.

The recessions given in the last column of Table 16 are based on the initial (maximum) observed net oxygen consumption rates. In order to convert from oxygen consumption to metal recession it is necessary to have some information about the stoichiometry of the oxidation reaction. Furthermore, this measurement is not sensitive to the vapor species formed at the hot sample surface, but rather to the solid phases which condense from the vapor onto the cool walls of the apparatus. The distinction is important

if condensation occurs with release or take up of oxygen.

In experiment XXVIII-1 on pure Ir the measured rate of oxygen consumption is 5.62×10^{-4} g/min or 3.5×10^{-5} gm. atoms of O/min. The weight loss, assuming linearity with time is 6.80×10^{-3} g/min or 3.54×10^{-5} gm. atoms of Ir/min. Thus, the net oxidation condensation reaction observed seems to involve iridium and oxygen in the atom ratio of 1:1. The metal recession rates were calculated on this basis for all of the materials studied, assuming preferential oxidation of iridium in every case.

Table 17 summarizes the dimensional changes observed in post-exposure metallographic analysis. Although a number of these samples showed nonuniform recessions, there was no indication of preferential oxidation.

C. Discussion of Results

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Near 2900°F the oxidation of JTA(D-13) was found to be linear at a pressure of 11.9 Torr and parabolic at a pressure of 40.4 Torr (Figures 87 and 88). In both cases, the calculated recessions contained in Table 11 were 19.7 mils in relatively good agreement with the observed recessions. It appears that as the pressure increases, protective oxidation takes place due to formation of an oxide coating. Thus, at 2900 F, one would expect lower one hour recessions at higher pressures. This finding is in agreement with the results of air oxidation tests 216 and 217 (Table 7) which resulted in 3 mil and 6 mil recessions after one hour at 2813°F and 3110°F. At 3740°F (Test XXVIII-31, Table 11) the oxidation rate is linear and corresponds to a computed value of 55.5 mils and observed values of 160-170 mils in one hour. These results are to be compared with supply limited rates of 200 mils in 60 minutes observed in 1 ft/sec air oxidation tests (Figure 5) and Mach 0.3, 1 atmosphere recessions of 60 mils in 30 minutes (Reference 7). The higher rate at 3740°F is due to breakdown of protective oxidation and an approach to graphite behavior. Thus, at higher oxygen pressure (Test XXVIII-74, Table 11) still higher recession rates corresponding to 500 mil/hr levels are seen. In all of these exposures, the supply of oxygen exceed the removal rate. Thus, the oxidation was not supply limited.

The present results for JT0992(F-15) in Table 12 indicate that protective exidation occurs at 2900 and 2950°F for exposures at 10.3 and 40.1 Torr of exygen (Figure 89). Calculated and observed rates are in general agreement with results obtained by Air Oxidation Tests (Figure 6). In addition, the observed recession levels of 1-3 mils in one hour are in keeping with arc plasma exposures at Mach 3.2 and oxygen partial pressures in the range 1-4 Torr (see Reference 7). At temperatures near 3500°F, the oxidation of JT0992(F-15) is not protective. The conversion depth at 3580°F and 149 Torr (sample XXVIII-62) corresponds to a rate near 300 mils in one hour. In all cases, the oxygen supply exceeded the quantity which reacted with the sample. The foregoing rate is higher than observed in Air Oxidation tests (Figure 6). Arc plasma tests at Mach 0.3 at one atmosphere yield recession rates of 1000 mils in 30 minutes at 3500°F (7).

The behavior of JT0981(F-16) is quite similar to JT0992(F-15) in these tests as shown in Table 13 and Figures 91 and 92. Protective oxidation is noted at 2900°F yielding rates of 1-6 mils in one hour which are comparable with the results shown in Figure 6 for oxidation in air. The JT0981(F-16) exposures reported in Table 13 were not supply limited. For WSi₂/W(G-18), at an oxygen partial pressure of 10 Torr, a protective silica film can be formed at a temperature of 3175°F. The protection is then lost when the temperature is raised to the 3600-3670°F range. At 3495 and 3560°F and 10.6 Torr, a silica film fails to form at all and the oxidation is linear due to continual evolution of SiO. At an oxygen partial pressure of 150 Torr, results were highly variable. In one experiment protective oxidation, characterized by rapid build-up of a silica film after an oxygen pickup of 0.006 g/cm² was noted at 3450°F, and the protection was retained at 3635°F. In another experiment at the same pressure, the protective film was not established until 0.2 g/cm² of oxygen had been consumed. At 3520°F, linear catastrophic oxidation was noted.

The protective oxidation of WSi₂ is discussed in terms of an initial stoichiometric reaction to form WO₂(g) and SiO₂(s), and ultimate preferential oxidation of silicon with the formation of W₂Si₃, W₂Si, and finally W at the oxide-alloy interface. The nonprotective oxidation of WSi₂ is discussed in terms of two related phenomena: (1) the failure to form an SiO₂ film at all low oxygen pressures due to the establishment of a boundary layer of SiO(g) that limits oxygen access to the surface and (2) the rupture of an already existing SiO₂ film by evolution of SiO(g) at the oxide silicide interface.

The present results indicate that one atmosphere failure occurs near 3500°F in good agreement with the air oxidation tests (Figure 5. Table 8) which suggest failure at 3500°F. Arc plasma exposures at one atmosphere and Mach 0.3 (7) showed no failures up to 3210°F. By contrast, high velocity CG/HW tests at Lockheed (6) performed at one atmosphere indicates failure at 3680°F. However, failures were noted after 5 minutes of arc plasma exposure at Mach 3.2 and 24 Torr oxygen pressure at 3635°F (7). The latter result is in fair agreement with the present 10 Torr findings.

The rates of oxidation of iridium metal reported here are compared with literature values in Table 18. The rates obtained in the present work seem to be limited by mass transport in the vapor phase. Rexer's results at 4040°F (26), oxygen pressures of 142 and 710 Torr, predict a reaction controlled rate at 400 Torr of 120 mils/hr, a factor of more than ten higher than presently observed. The influence of mass transport on the observed rates can only be checked by studying the oxidation reactions as a function of temperature, flow rate and sample size. It is quite possible that even the comparative ranking of materials might be different under true reaction controlled conditions. However, if these results are taken to be representative of the oxidation behavior independent of temperature, flow rate, etc., then Table 16 suggests that rhodium additions enhance the oxidation resistance of iridium, while platinum and rhenium confer only moderate enhancement and osmium reduces the oxidation resistance. Table 16 lists the melting temperatures of these alloys as well as their melting temperatures in the presence of carbon (20). Reference to these values indicates that while rhodium increases the oxidation resistance, it lowers the temperature of the iridium-carbon eutectic. Platinum behaves in a similar fashion. On the other

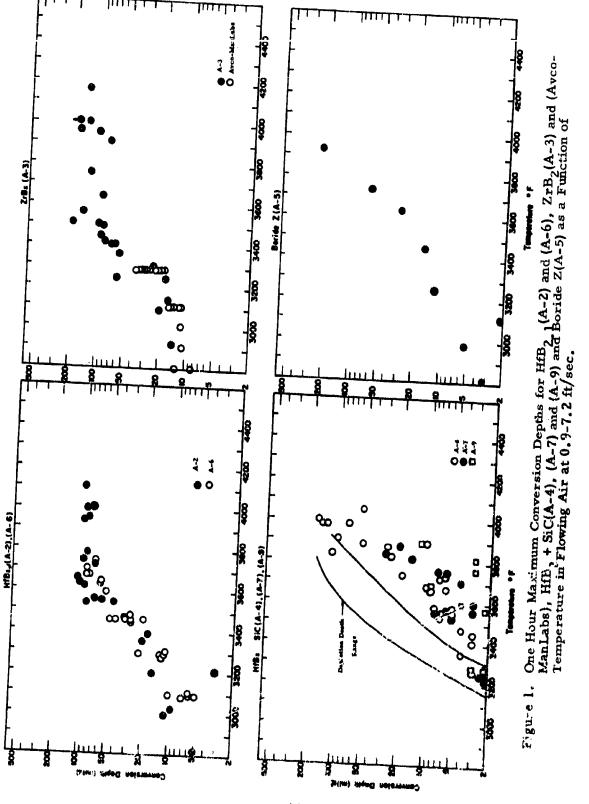
hand, rhenium additions raise the iridium-carbon eutectic temperature.

The emittance value of 0.23 determined in this work is somewhat low compared to other values in the literature. Table 19, taken from a National Bureau of Standards Compilation (22) gives 0.65µ emittance values for several of the platinum group metals and one alloy. The emittance is given as 0.30 for solid iridium, although unfortunately the temperature of measurement is not reported. More recently Wright et al. (22) have performed an extensive series of measurements of the emittance of solid iridium between 1600°F and 3600°F. Their results indicate an emittance of 0.30 at 0.65µ in static air. Accordingly, this value was employed to correct the current optical temperatures to true temperatures. The present uncertainty in the emittance of the alloys under study (all of the alloys were assumed to have emittance = 0.23 at 0.65µ) leads to the obvious inconsistency for experiment XXVIII-13 in Table 16 where in the 75Ir25Pt alloy was oxidized 50°F above its melting point.

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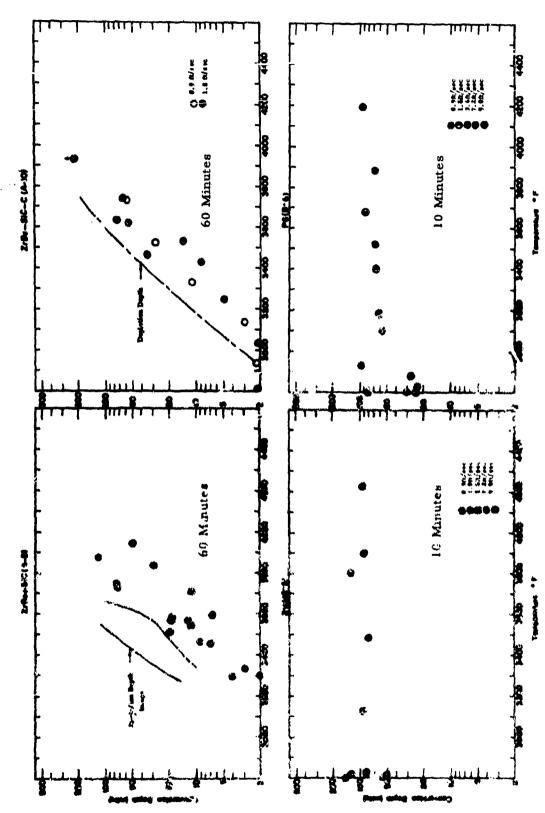
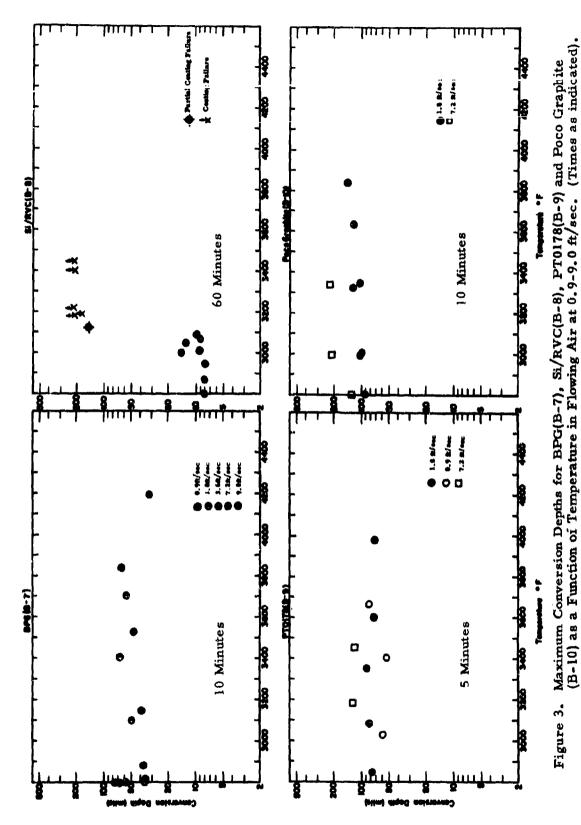
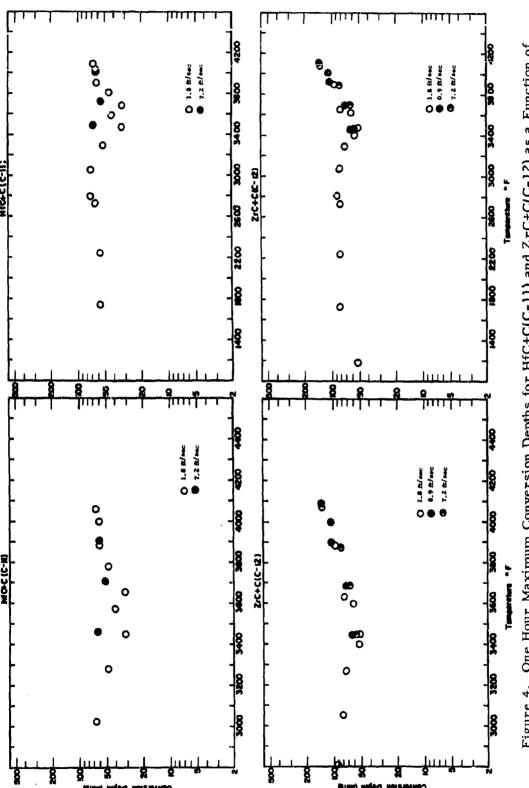
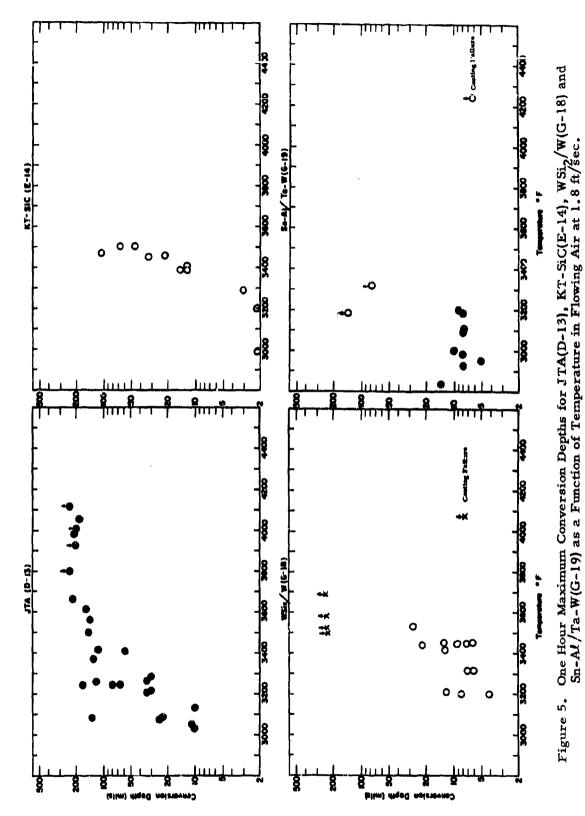


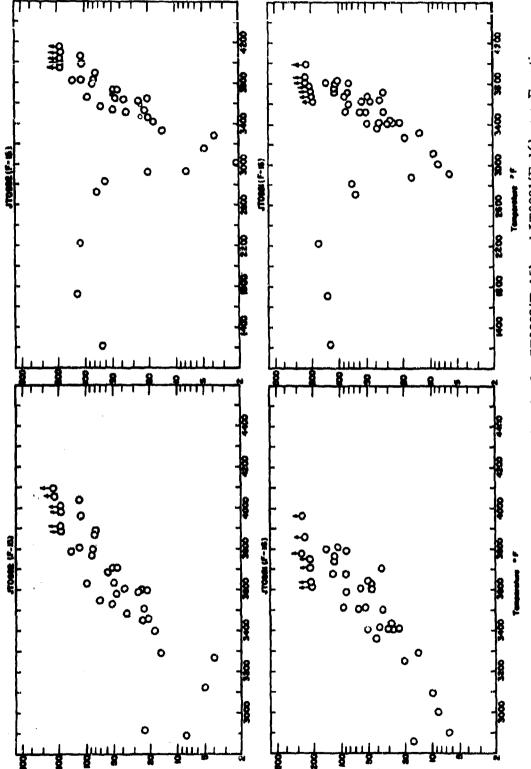
Figure 2. Maximum Conversion Depths in Arb. + SiC(A-8), ZrB, + SiC + C(A-10), RVA(B-5) and FG(5-6) and FG(5-6) and FG(5-6) and Invarianted Transfer in Flowing Air at 0.9-9.0 ft/sec. (Times as indicated).



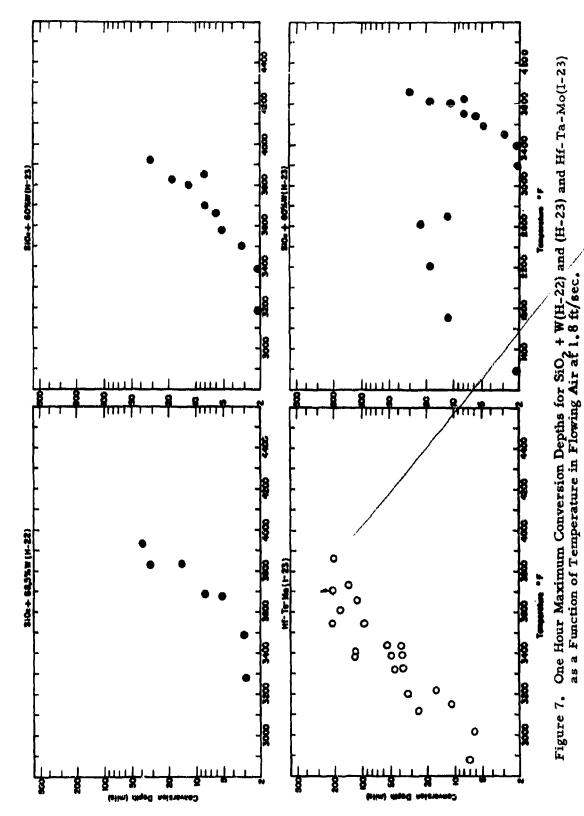
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One Hour Maximum Conversion Depths for JT0992(F-15) and JT0981(F-16) as a Function of Temperature in Flowing Air at 1,8 ft/sec. Figure 6.



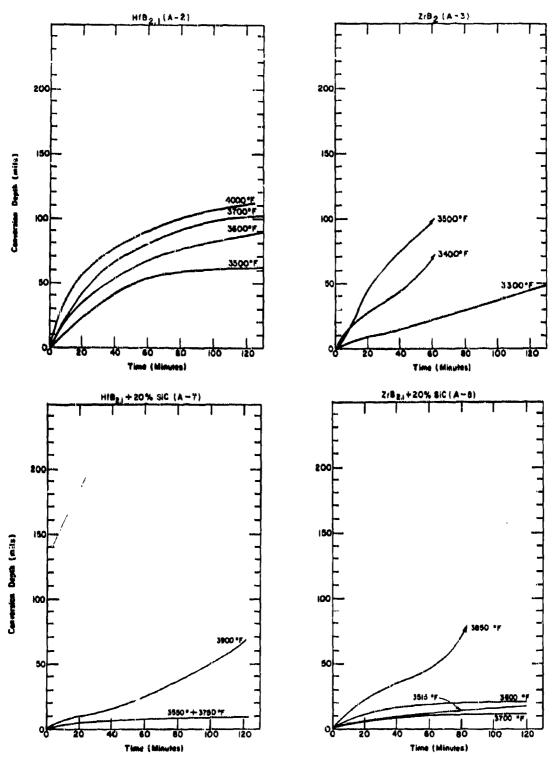


Figure 8. Conversion Depths for HfB2.1(A-2), ZrB2(A-3), HfB2.1+20% SiC(A-7) and ZrB2.1+20%SiC(A-8) as a Function of Time in Flowing Air at 1.8 ft/sec (Small Furnace).

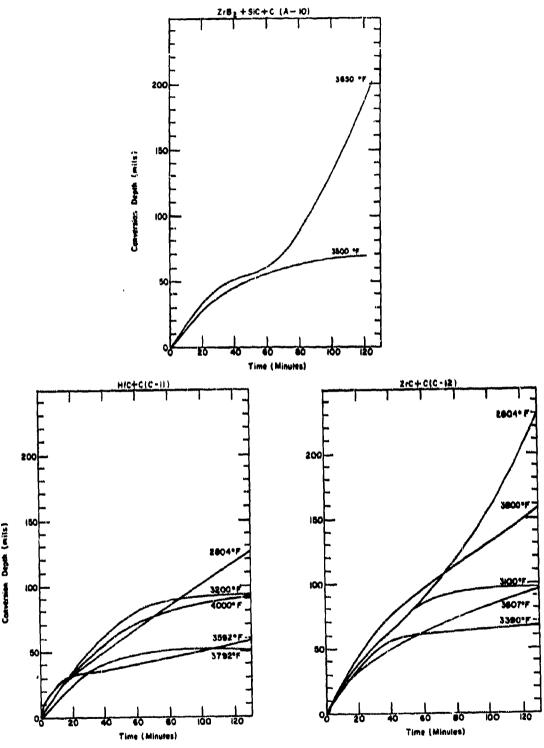


Figure 9. Conversion Depths for ZrB₂+SiC+C(A-10), HfC+C(C-11) and ZrC+C(C-12) as a Function of Time in Flowing Air at 1.8 ft/sec (Small Furnace).

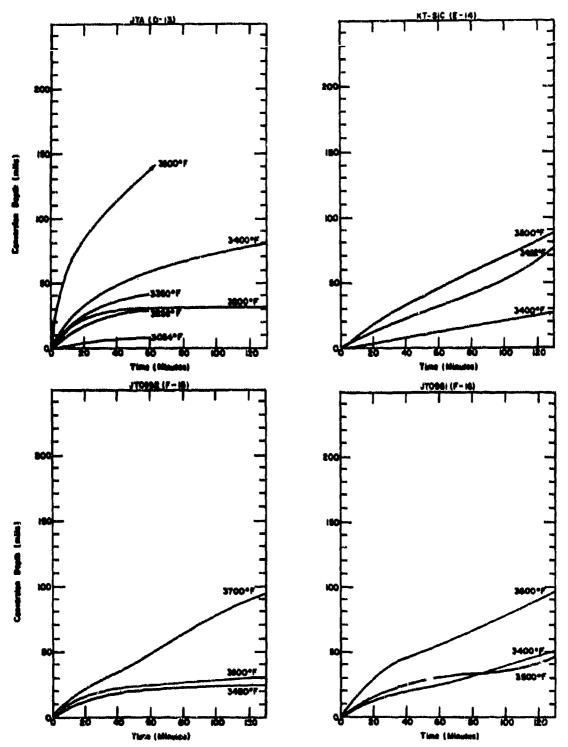
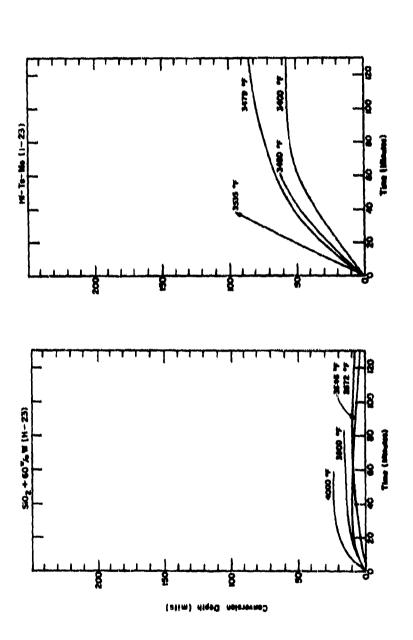


Figure 10. Conversion Depths for JTA(D-13), KT-SiC(E-14), JT0992 (F-15) and JT0981(F-16) as a Function of Time in Flowing Air at 1.8 ft/sec. (Small Furnace).



Conversion Depths for SiO₂+60w/oW(H-23) and Hf-Ta-Mo(I-23) as a Function of Time in Flowing Air at 1.8 ft/sec (Small Furnace). Figure 11.

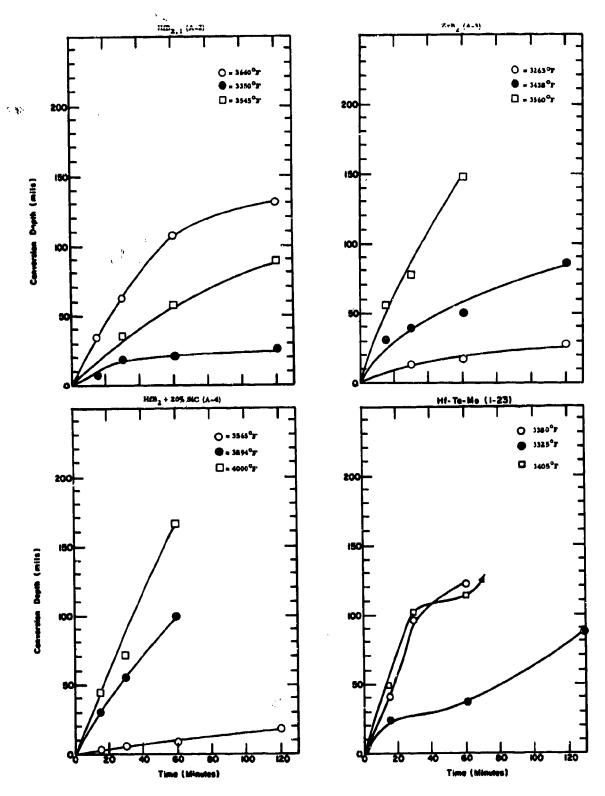


Figure 12. Conversion Depths for HfB_{2 1}(A-2), ZrB₂(A-3), HfB₂+ 20%SiC(A-4) and Hf-Ta-Mo(1-23) as a Function of Time in Flowing Air at 1.8 ft/sec. (Large Furnace).

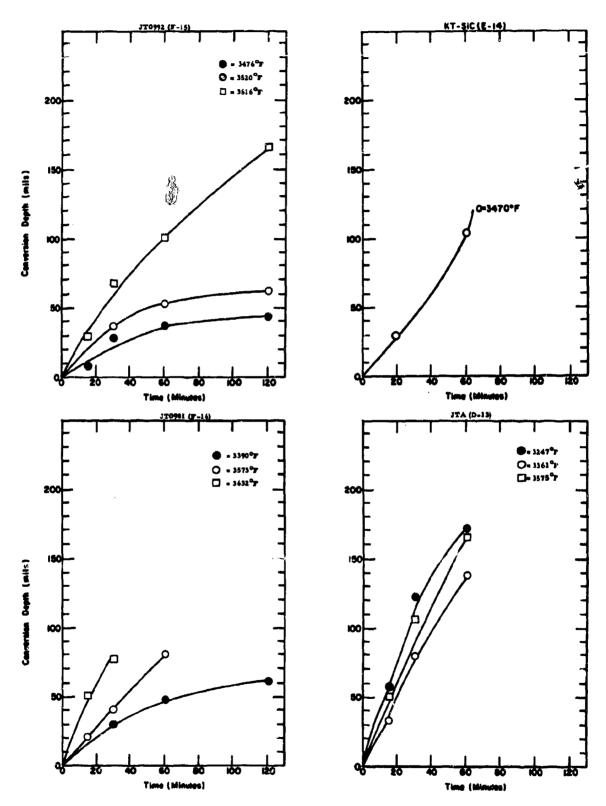


Figure 13. Conversion Depths for KT-SiC(E-14), JT0992(F-15), JT0981(F-16) and JTA(D-13) as a Function of Time in Flowing Air at 1.8 ft/sec. (Large Furnace).

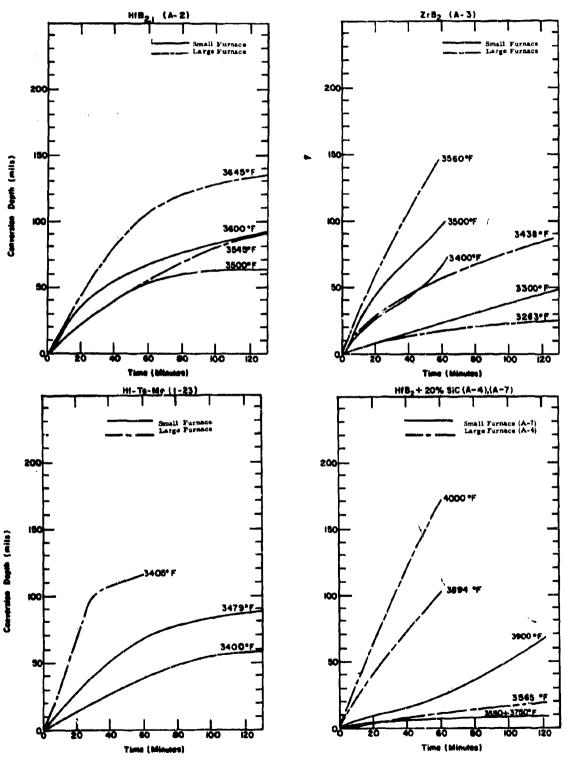


Figure 14. Comparison of Small and Large Furnace Conversion Depths for HfB_{2.1}(A-2), ZrB₂(A-3), HfB₂+20%SiC(A-4)(A-7) and Hf-Ta-Mo(I-23) as a Function of Time in Flowing Air at 1.8 ft/sec.

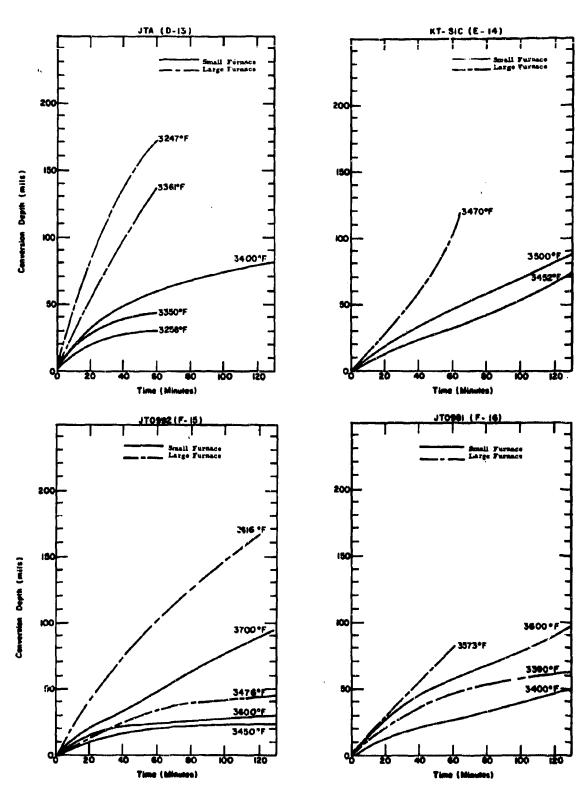
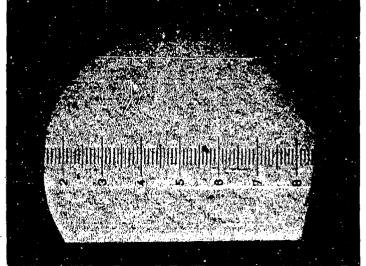


Figure 15. Comparison of Small and Large Furnace Conversion Depths for JTA(D-13), KT-SiC(E-14), JT0992(F-15) and JT0981(F-16) as a Function of Time in Flowing Air at 1.8 ft/sec.



Unetched

4.86 Mils per Small Division

Figure 16. Test 1356, HfB_{2 1}(A-2) after 60 Minutes in Flowing Air at 3700°F, Transverse Section.

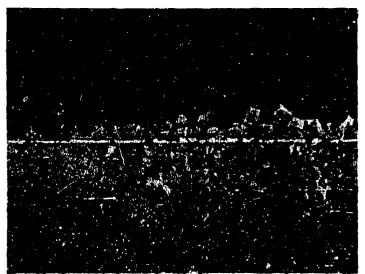
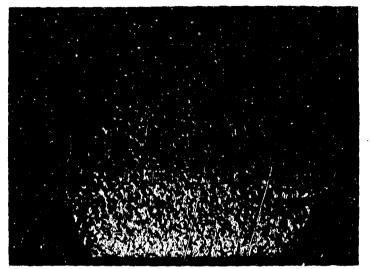


Plate No. 1-9053

Etched with 10 Glycerine 5HNO₃ 3HF

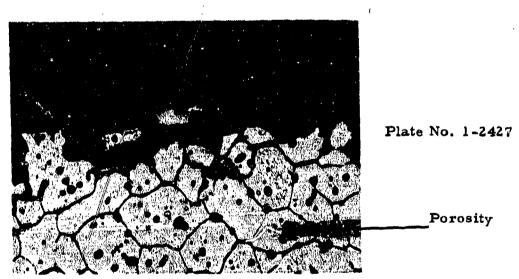
Figure 17. Test 1356, HfB, (A-2) after 60 Minutes in Flowing Air at 3700°F, Transverse Section.



Unetched

4,86 Mils per Small Division

Figure 18. Test 367, HfB_{2.1}(A-6) after 60 Minutes in Flowing Air at 3450°F, Transverse Section.



Etched with 10 Glycerine 5HNO₃ 3HF

Figure 19. Test 367, HfB_{2.1}(A-6) after 60 Minutes in Flowing Air at 3450°F, Interface of Longitudinal Section.

Unetched

4.86 Mils per Small Division

Figure 20. Test 1323, ZrB₂(A-3) after 60 Minutes in Flowing Air at 3300°F, Longitudinal Section.



Plate No. 1-8651

Etched with Glycerine 5HNO₃ 3HF

Figure 21. Test 1323, ZrB₂(A-3) after 60 Minutes in Flowing Air at 3300 F, Interface of Longitudinal Section.

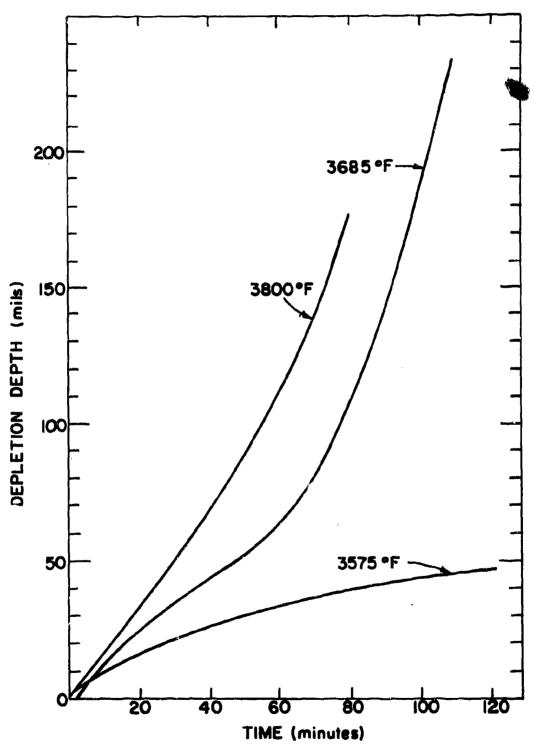
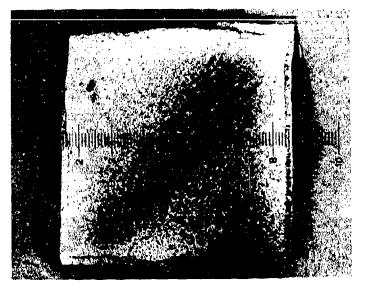


Figure 22. Depletion Depths for HfB₂+20%SiC(A-4) as a Function of Time in Flowing Air between 3575°F and 3795°F.



Unetched

4.86 Mils per Small Division

Figure 23. Test 966, HfB₂+20%SiC(A-4-2) after 60 Minutes in Flowing Air at 3353 F, Longitudinal Section.

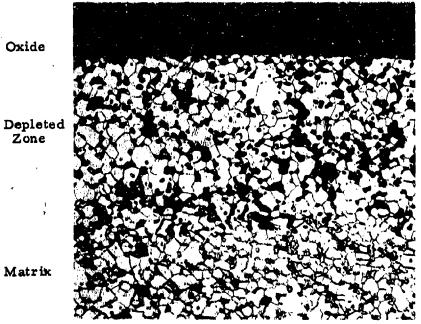
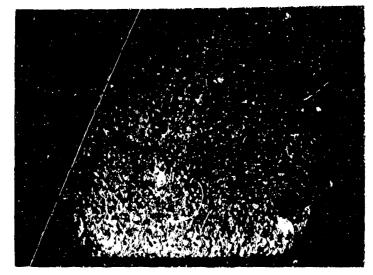


Plate No. 1-6063

Etched with 10 Glycerine 5HNO 3 3HF

Figure 24. Test 966, HfB₂+20%SiC(A-4-2) after 60 Minutes in Flowing Air at 3353 F, Interfaces of Longitudinal Section.



Unetched

4.86 Mils per Small Division

Filate No. 1-2489

Figure 25. Test 367, HfB_{2, 1}(A-6) after 60 Minutes in Flowing Air at 3450°F, Transverse Section.

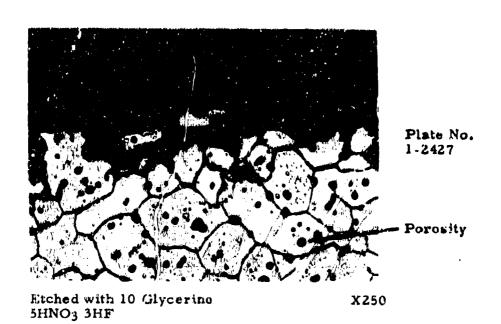
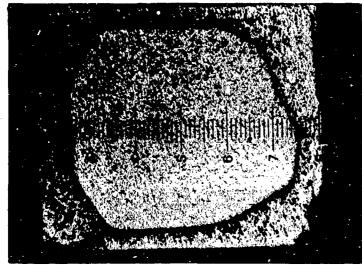


Figure 2c. Test 367, HE 2. (A-6) after 60 Minutes in Flowing Air at 3450 F, laterface of Longitudinal Section.



Unetched

4.86 Mils per Small Division

Figure 27. Test 383, HfB₂ + 35%SiC(A-9) after 60 Minutes in Flowing Air at 3560°F, Longitudinal Section.

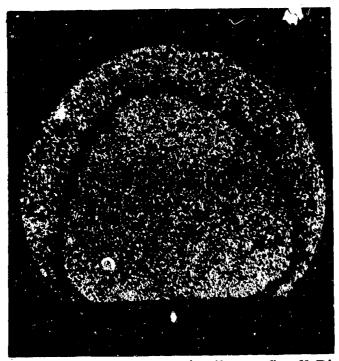
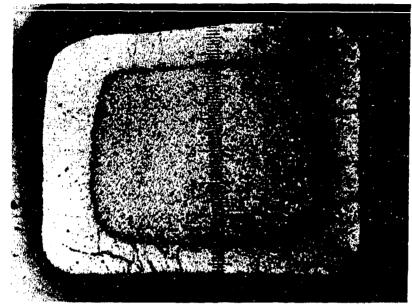


Plate No. 1-2510

Unetched

4.86 Mils per Small Division

Figure 28. Test 383, HfB₂ + 35%SiC(A-9) after 60 Minutes in Flowing Air at 3560°F, Transverse Section.



Unetched

4.86 Mils Per Unit

~X8

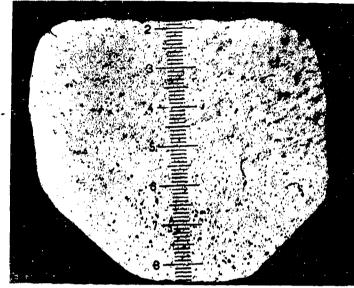
HfB₂ + SiC (A-4), OX-334 (60 Min. at 3794°F) Longitudinal Section. Conversion Depth 7 Mils. Depth of SiC Depleted Zone 60 Mils. Figure 29.



4.86 Mils Per Unit

~X8

Figure 30. $_{-}^{HfB_2} + SiC (A-4)$, OX-334 (60 Min. at 3794 F) Transverse Section. Genversion Depth 5 Mils. Depth of SiC Depleted Zone 67 Mils.



Unetched

4.86 Mils per Small Division

Figure 31. Test 1174, Boride Z (A-5) after 60 Minutes in Flowing Air at 3628°F, Longitudinal Section.

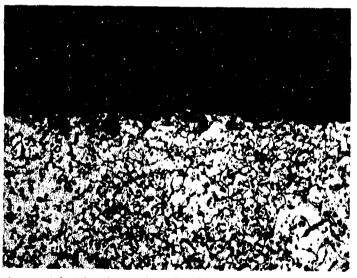
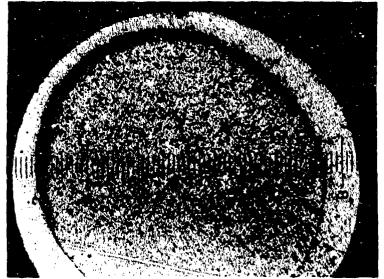


Plate No. 1-7318

Etched with 10 Glycering 5HNO₃

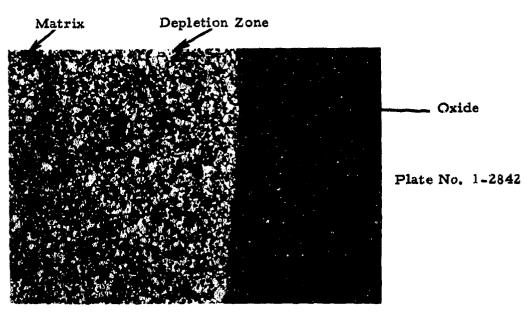
Figure 32. Test 1174, Boride Z(A-5) after 60 Minutes in Flowing Air at 3628 oF, Interface of Transverse Section.



Unetched

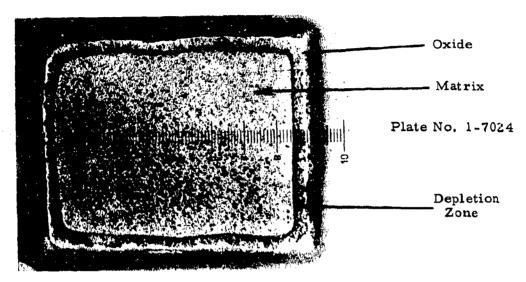
4.86 Mils per Small Division

Figure 33. Test 437, ZrB₂ + 20%SiC(A-8) after 60 Minutes in Flowing Air at 3540°F, Transverse Section.



Etched with 10 Glycerine 5HNO₃ 3HF

Figure 34. Test 437, ZrB₂ + 20%SiC(A-8) after 60 Minutes in Flowing Air at 3540°F, Interfaces of Transverse Section.



Unetched

4.86 Mils per Small Division

Figure 35. Test 1134, ZrB₂ + 14%SiC + 30%C(A-10) after 60 Minutes in Flowing Air at 3427°F, Longitudinal Section.

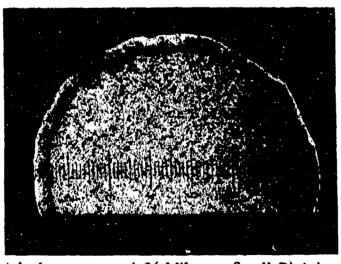


Plate No. 1-7027

Unetched

4.86 Mils per Small Division

Figure 36. Test 1134, ZrB₂ + 14%SiC + 30%C(A-10) after 60 Minutes in Flowing Air at 3427°F, Transverse Section.

Plate No. 1-1584

Unetched

Figure 37. RVA Graphite (B-5), OX-198 (10 Min. at 2813°F) Longitudinal Section. Recession 105 Mils.

4.86 Mils Per Unit

~X15

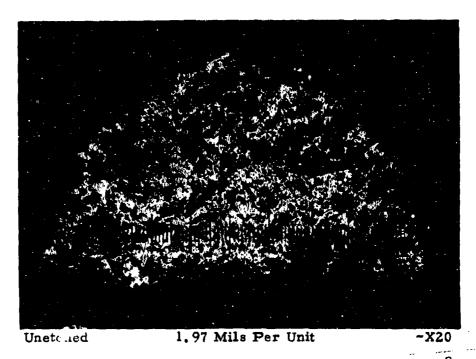


Fig. re 38. RVA Graphite (B-5) OX-198 (10 Min at 2813 F) Transverse Section. Recession 137 Mils.

Unetched 4.86 Mils Per Unit ~X8

Plate No. 1-1592

Plate No. 1-1594

Figure 39. Pyrolytic Graphite (B-6), OX-200 (10 Min. at 2876°F) Longitudinal Section. Recession 19 Mils.

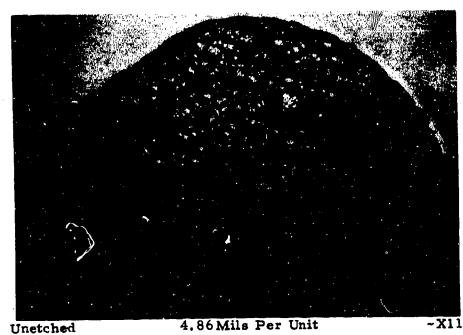


Figure 40. Pyrolytic Graphite (B-6), OX-200 (10 Min. at 2876°F) Transverse Section. Recession 27 Mils.

Incipient Delamination

Plate No. 1-1622

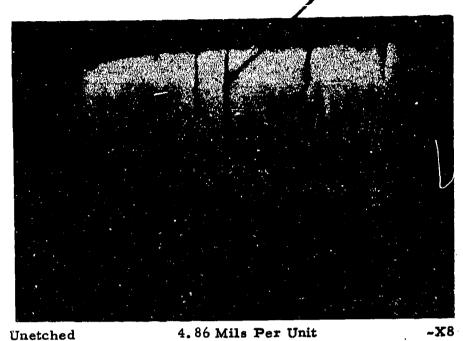
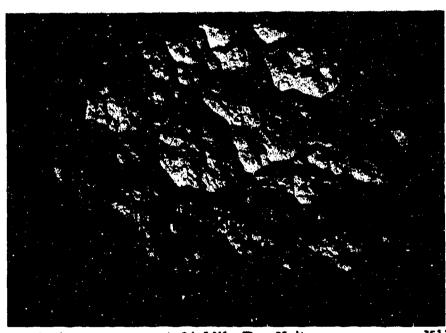


Figure 41. Boron Pyrolytic Graphite (B-7) OX-207 (10 Min. at 2804°F) Longitudinal Section. Recession 19 Mils.

Plate No. 1-1624

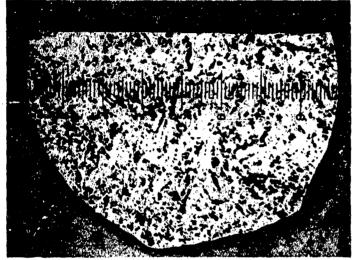


Unetched

4.86 Mils Per Unit

~X11

Figure 42. Boron Pyrolytic Graphite (B-7) OX-207 (10 Min. at 2804°F) Transverse Section. Recession 36 Mils.



Unetched

4.86 Mils per Small Division

Figure 43. Test 1099, PT0178(B-9) after 5 Minutes in Flowing Air at 3402°F, Transverse Section.

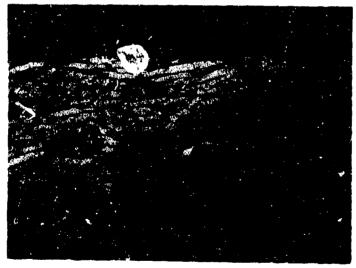


Plate No. 1-6828

Unetched

Figure 44. Test 1099, PT0178(B-9) after 5 Minutes in Flowing Air at 3402°F, Interface of Longitudinal Section.



Unetched

4.86 Mils per Small Division

Figure 45. Test 1074, AXF-5Q Poco Graphite (B-10) after 10 Minutes in Flowing Air at 3835°F, Longitudinal Section.

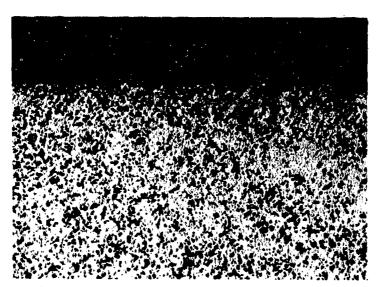


Plate No. 1-6746

Unetched

Figure 46. Test 1074, AXF-5Q Poco Graphite (B-10) after 10 Minutes in Flowing Air at 3835°F. Interface of Longitudinal Section.



Plate No. 3813/C

Unetched

X13,000

Figure 47. Microstructural Characteristics of A&F-5Q Foco Graphite (B-10), 1.5% Pariodion Replica Shadowed with Chromium at 60° Angle.

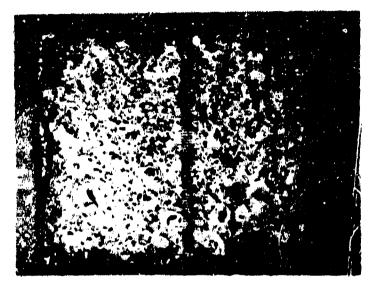


Plate No. 3813D

Unetched

XA4, 030

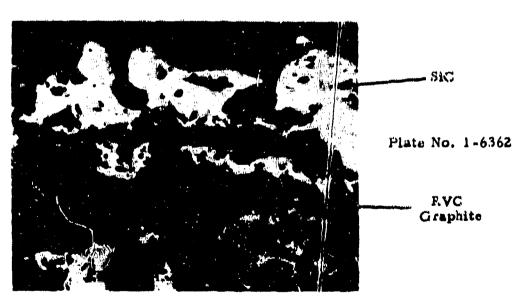
Figure 48. Microstructural Characteristics of AXF-50, Poco-Graphite (B-10). 1.5% Participation Replies Shadower with Chromium at 60° Amele.



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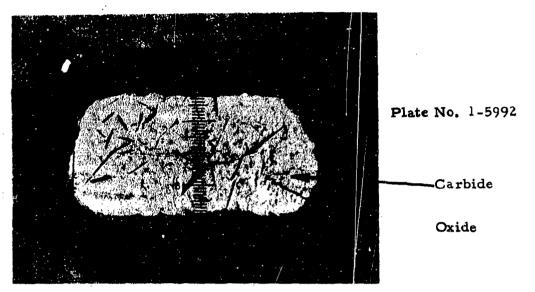
4.86 Mils per Small Division

Figure 49. Test 1048, Si/RVC(B-8) after 60 Minutes in Flowing Air at 2806°F, Longitudinal Section.



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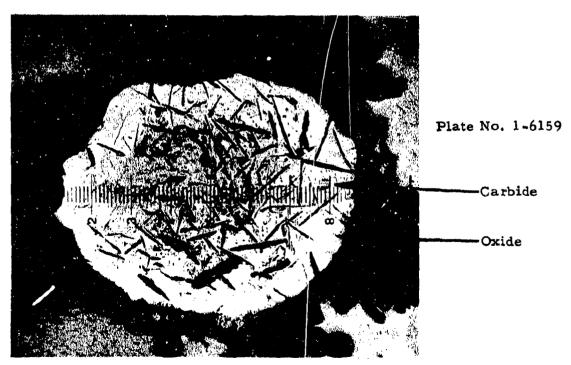
Figure 50. Test 1048, Si/RVC(B-8) after 60 Minutes in Flowing Air at 2806°F, Interface of Longitudinal Section. Coating Did Not Fail.



Unetched

4.86 Mils per Small Division

Figure 51. Test 973, HfC + C(C-11) after 60 Minutes in Flowing Air at 3279°F, Longitudinal Section.



Unetched

4.86 Mils per Small Division

Figure 52. Test 988, ZrC + C(C-12) after 60 Minutes in Flowing Air at 3058°F, Transverse Section.

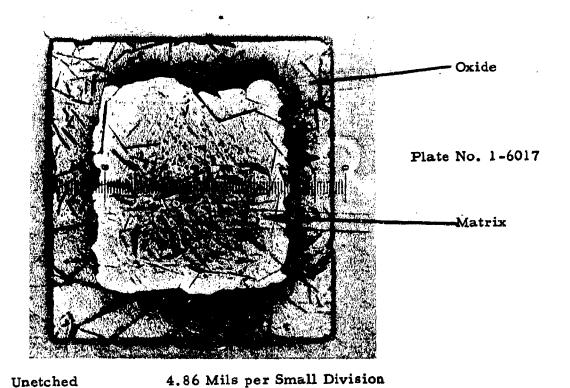
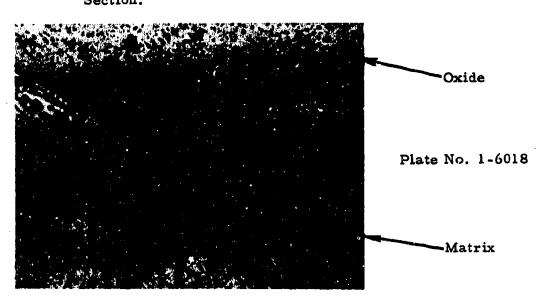
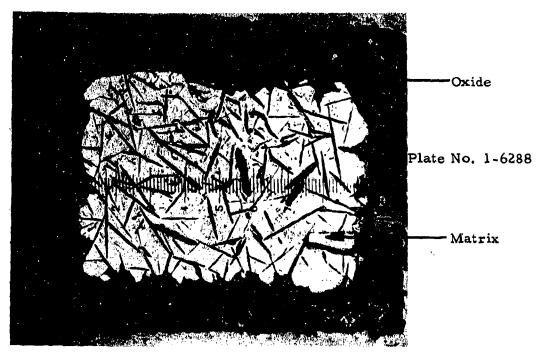


Figure 53. Test 987, HfC + C(C-11) after 60 Minutes in Flowing Air at 4054°F, Longitudinal Section.



Unetched

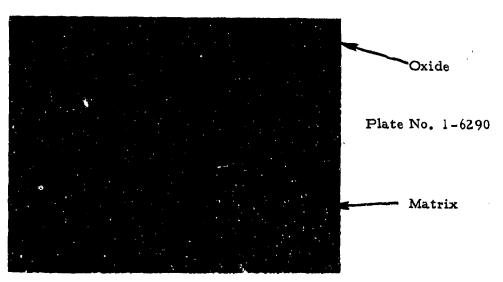
Figure 54. Test 987, HfC + C(C-11) after 60 Minutes in Flowing Air at 4054°F, Interface of Longitudinal Section.



Unetched

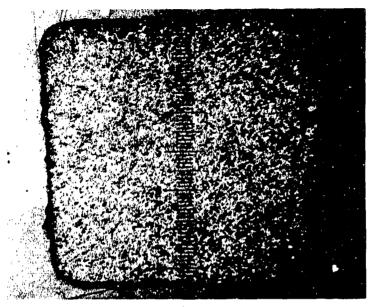
4.86 Mils per Small Division

Figure 55. Test 1031, ZrC + C(C-12) after 60 Minutes in Flowing Air at 3645°F, Longitudinal Section.



Unetched

Figure 56. Test 1031, ZrC + C(C-12) after 60 Minutes in Flowing Air at 3645°F, Interface of Longitudinal Section.



Unetched

4.86 Mils per Small Division

Figure 57. Test 1090, JTA(D-13) after 60 Minutes in Flowing Air at 3350°F, Longitudinal Section.

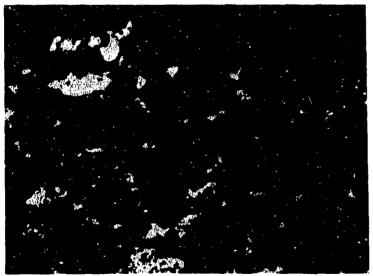


Plate No. 1-6808

Unetched

Figure 58. Test 1090, JTA(D-13) after 60 Minutes in Flowing Air at 3350°F, Interface of Longitudinal Section.

Unetched

4.86 Mils per Small Division

Figure 59. Test 1378, JT0992(F-15) after 60 Minutes in Flowing Air at 3450 F, Transverse Section

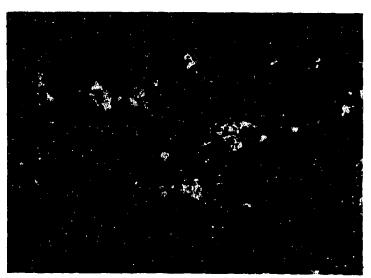
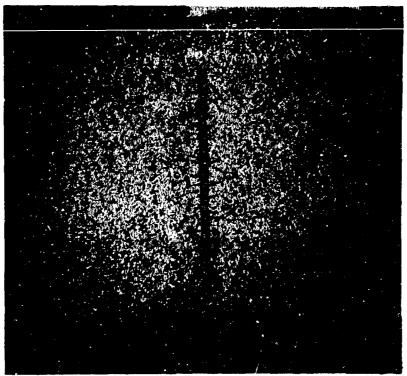


Plate No. 1-8948

Unetched

Figure 60. Test 1378, JT0992(F-15) after 60
Minutes in Flowing Air at 3450°F,
Interface of Transverse Section.



Unetched

4.86 Mils Per Small Division

Figure 61. Test 734, JT0981 (F-16) after 60 Minutes in Flowing Air at 3668 F, Longitudinal Section.

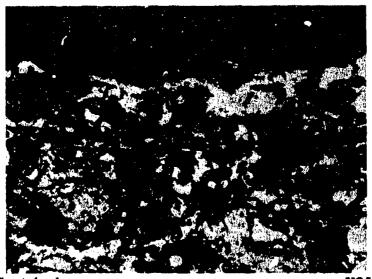


Plate No. 1-4390

Unetched

Figure 62. Test 734, JT0981(F-16) after 60 Minutes in Flowing Air at 3668 F, Interface of Longitudinal Section.

Unetched

4.86 Mils per Small Division

Figure 63. Test 1177, KT-SiC(E-14) after 60
Minutes in Flowing Air at 3371°F,
Transverse Section.



Plate No. 1-7333

Etched Electrolytically with 5%KOH Solution X250

Figure 64. Test 1177, KT-SiC(E-14) after 60
Minutes in Flowing Air at 3371°F,
Interface of Transverse Section.

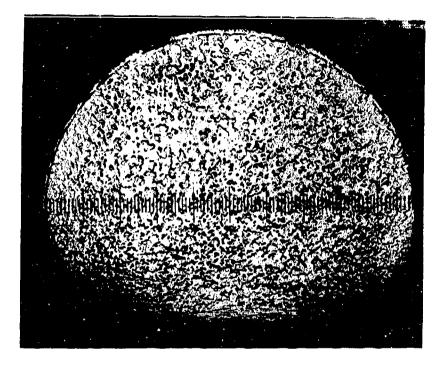


Plate 1-3157

Etched with Murakamis! Reagent

Approximately X10

Figure 65. Test 478, WSi₂/W (G-18) after 60 Minutes in Flowing Air at 3325°F. Transverse Section, 4,86 Mils/Unit.

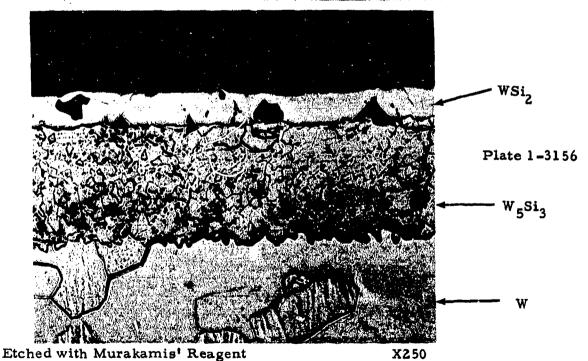


Figure 66. Test 478, WSi₂/W (G-18) after 60 Minutes in Flowing Air at 3225°F. Transverse Section, W₅Si₃ Zone Width Equals 5.0 Mils.

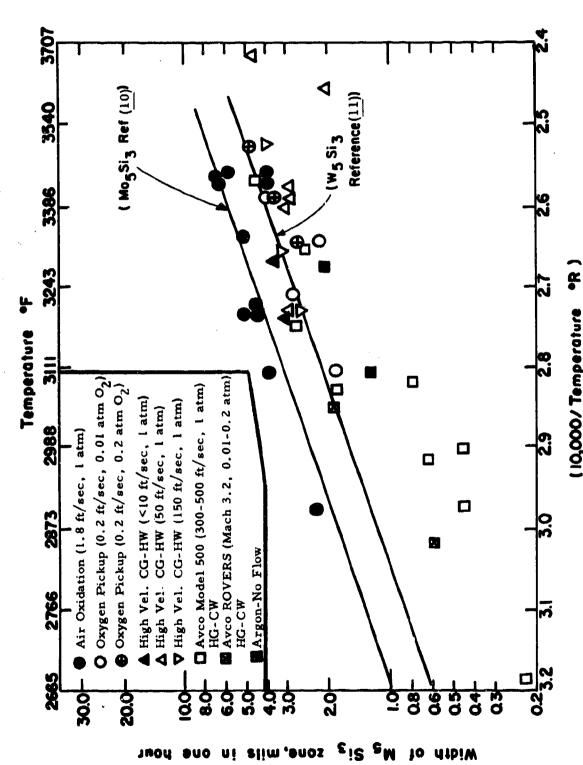


Figure 67, Growth of W_{53,3} Zone on WSi₂/W(G-18) as a function of Flow Rate and Pressure Compared with the results of Bartlett and Gage (11) for W₅Si₃ and Perkins and Packer for Mo₅Si₃ (10).

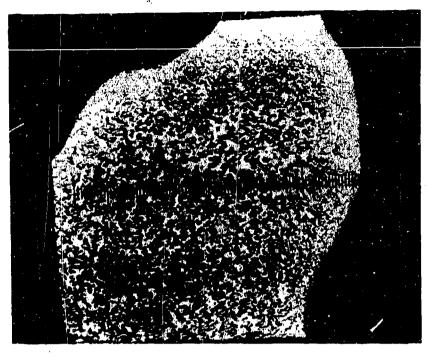
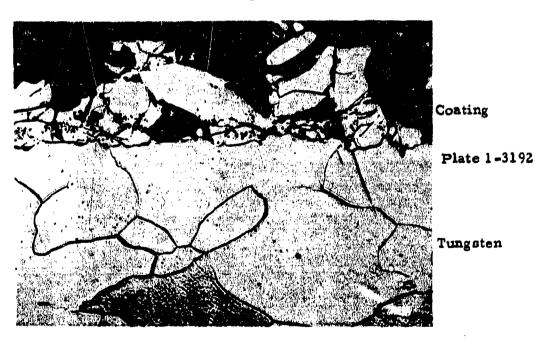


Plate 1-3191

Etched with Murakamis' Reagent

Approximately X8

Figure 68. Test 485, WSi₂/W(G-18) after 60 Minutes in Flowing Air at 3532 F. Longitudinal Section, 4.86 Mils/Unit.

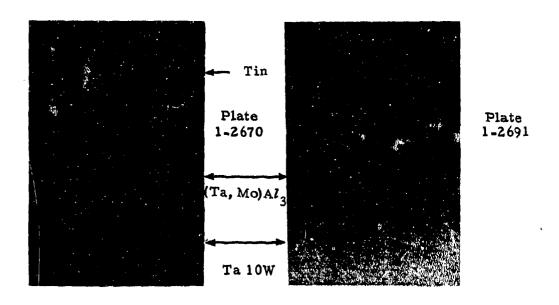


Etched with Murakamis' Reagent

250X

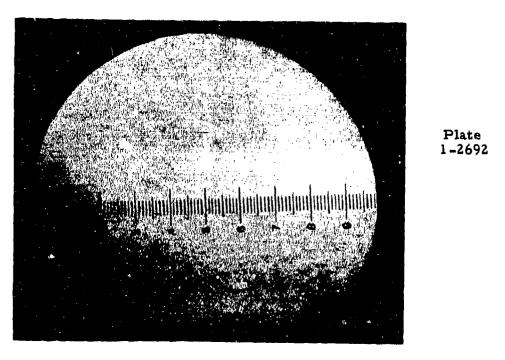
The stand and administration is for a sure in the standard and

Figure 69. Test 485, WSi₂/W (G-18) after 60 Minutes in Flowing Air at 3532°F, Longitudinal Section.



Etched with 30 cc Lactic Acid, 10 cc HNO3, 5 cc HF X250

Figure 70. Test 390 (left) and Test 400, Sn-Al/Ta-10W after One Hour Exposures in Flowing Air at 2624°F and 3092°F.
Interface of Longitudinal Section.



Unetched

Approximately X9

Figure 71. Test 400, Sn-Al/Ta-10W after One Hour Exposure in Flowing Air at 3092°F. Transverse Section, Original Diameter 516 Mils, Final Diameter 506 Mils, 4.86 Mils/Unit.

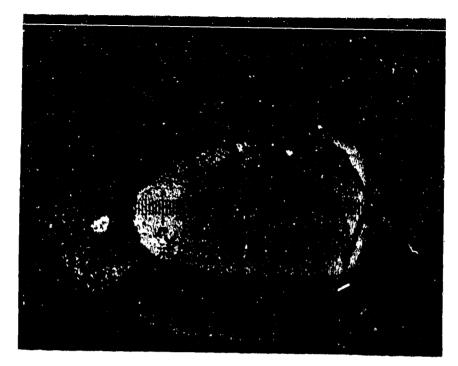
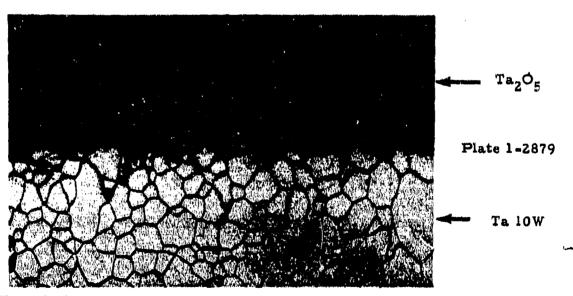


Plate -12878

Unetched

Approximately X10

Figure 72. Test 439, Sn-Al/Ta-10W(G-19) after One Hour in Flowing Air at 3173°F. Longitudinal Section Initial Length 522 Mils, Final Length 342 Mils, 4,86 Mils/Unit.



Etched with Murakamis' Reagent

Figure 73. Test 439, Sn-Al/Ta-10W(G-19), after One Hour in Flowing Air at 3173°F. Longitudinal Section, Interface Showing Oxide and Ta-10W after Coating Failure.



Unetched

4.86 Mils Per Small Division

Figure 74. Test 1038, SiO₂ + 68.5%W(H-22) after 60 Minutes in Flowing Air at 3691°F, Longitudinal Section.

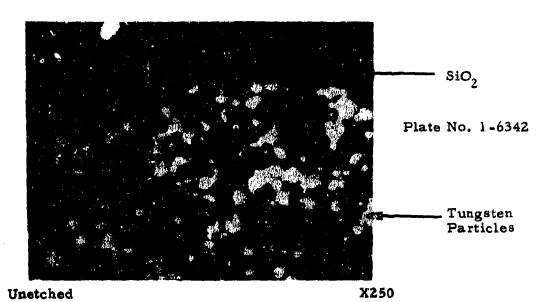
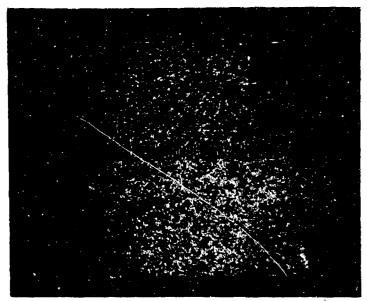


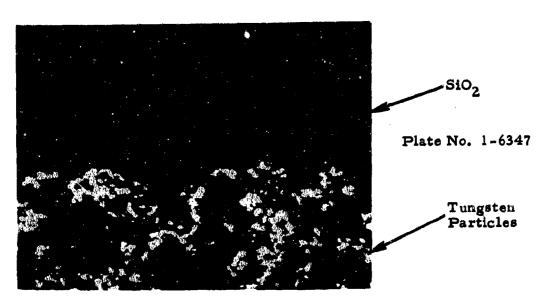
Figure 75. Test 1038, SiO₂ + 68.5%W(H-22) after 60 Minutes in Flowing Air at 3691°F, Interface of Longitudinal Section.



Unetched

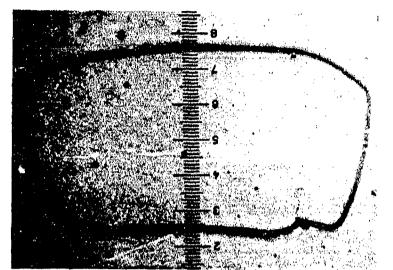
4.86 Mils per Small Division

Figure 76. Test 1042, SiO₂ + 60%W(H-23) after 60 Minutes in Flowing Air at 3819°F, Longitudinal Section.



Unetched

Figure 77. Test 1042, SiO₂ + 60%W(H-23) after 60 Minutes in Flowing Air at 3819°F, Interface of Longitudinal Section.



Unetched

4.86 Mils per Small Division

Figure 78. Test 1047, SiO₂ + 35%W(H-24) after 60 Minutes in Flowing Air at 3042°F, Longitudinal Section.

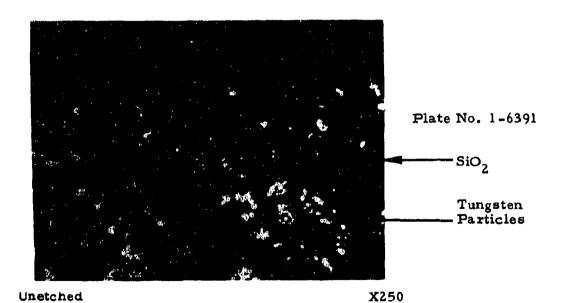


Figure 79. Test 1047, SiO₂ + 35%W(H-24) after 60 Minutes in Flowing Air at 3042°F, Interface of Longitudinal Section.

Plate No. 1-6217

Unetched

4.86 Mils per Small Division

Figure 80. Test 1007, Hf-20Ta-2Mo(I-23) after 30 Minutes in Flowing Air at 3400°F, Longitudinal Section.

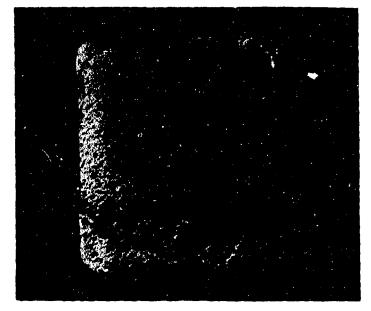
Suboxide

Oxidized Matrix



Etched with 15 Glycerine 5HNO₃ HCl 3HF X250

Figure 81. Test 1007, Hf-20Ta-2Mo(I-23) after 30 Minutes in Flowing Air at 3400°F, Interface of Longitudinal Section, Subocide at Top, Tantalum Stringers are Light Phase.



Unetched

4.86 Mils per Small Division

Figure 82. Test 1056, Hf-20Ta-2Mo(I-23) after 30 Minutes at 3479°F, Longitudinal Section.

Suboxide

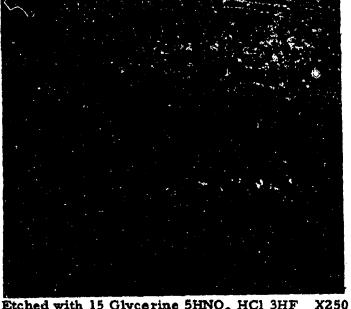


Plate No. 1-6496

Oxide

Etched with 15 Glycerine 5HNO₃ HCl 3HF X256 Figure 83. Test 1056, Hf-20Ta-2Mo(I-23) after

Figure 83. Test 1056, Hf-20Ta-2Mo(I-23) after 30 Minutes at 3479 F, Interface of Longitudinal Section, Suboxide with Tantalum Stringers at Top.

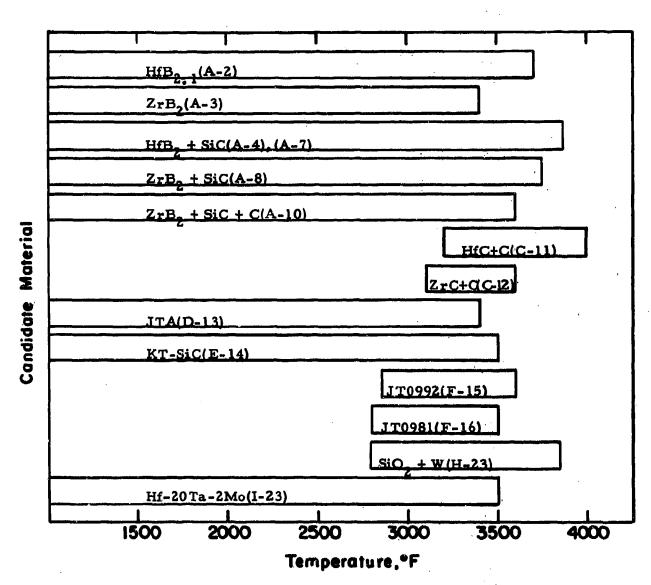


Figure 84. Two Hour Protection Limits For The Candidate Materials,



Plate No. 5089

Unetched

1.

X500

Figure 85. Inert Test No. 1200, JTA(D-13) After 60 Minutes in Flowing Argon at 4200° F, Longitudinal Section.

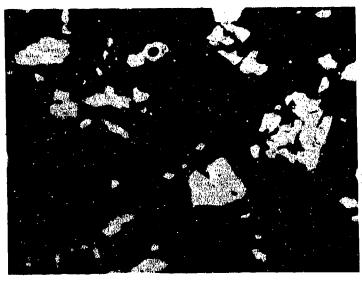


Plate No. 5093

Unetched

Figure 86. Inert Test No. 1202, JTA(D-13) After 60 Minutes in Flowing Argon at 4176°F, Longitudinal Section.

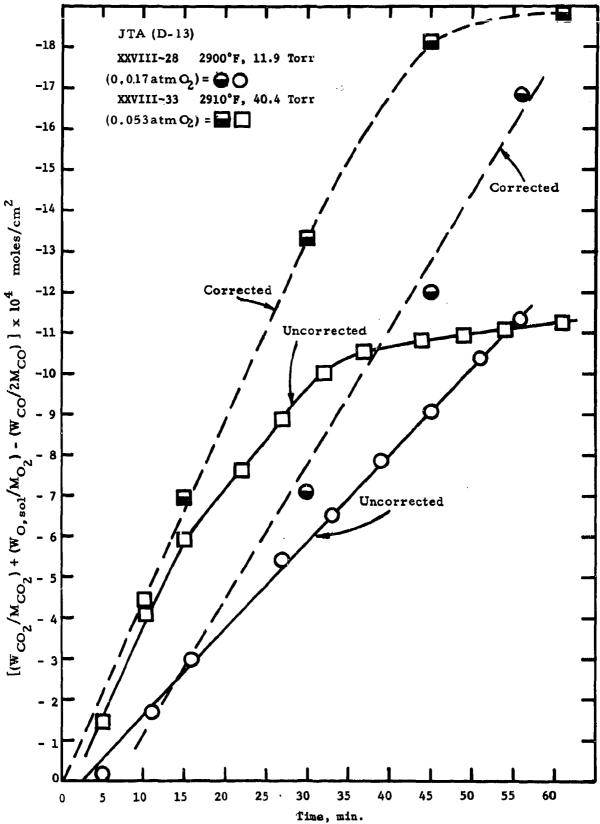


Figure 87. Oxidation of JTA (C-ZrB₂-SiC) (D-13) Composite as a Function of Time at 2900°F, Showing Correction Due to Surface Area Changes.

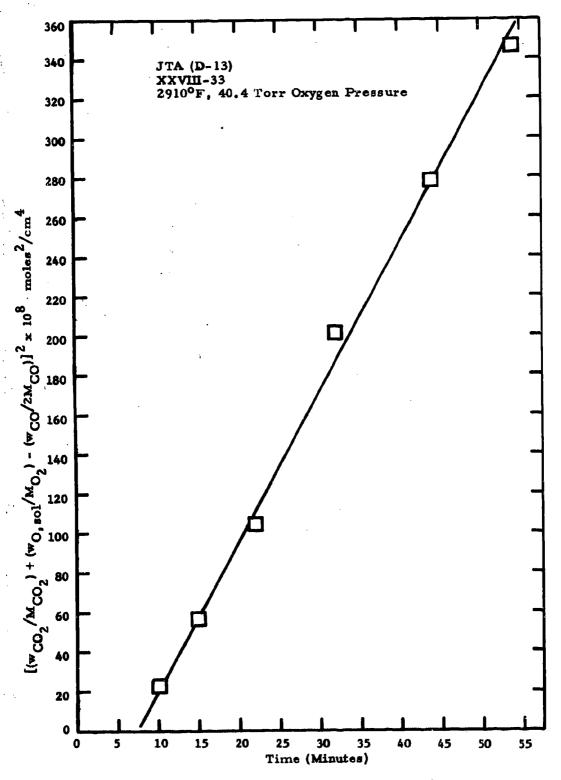


Figure 88. Parabolic Representation of the Oxidation of JTA (C-ZrB₂-SiC) (D-13) Composite at 2900°F.

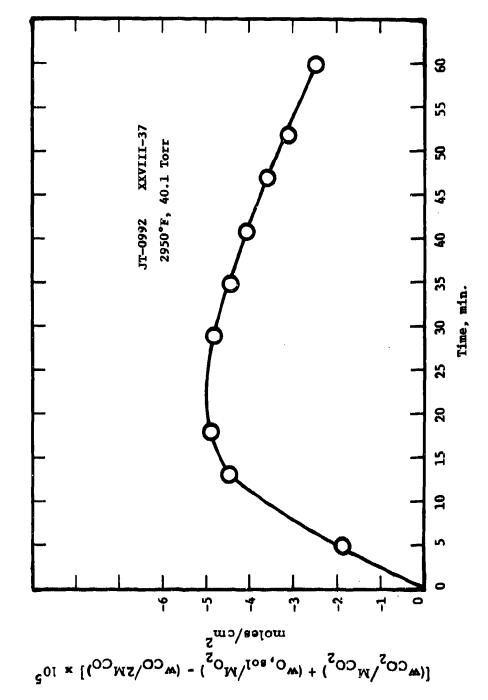


Figure 89. Oxidation of JT0992 (C-H+C-SiC) (F-15) Composite as a Function of Time at 2950°F.

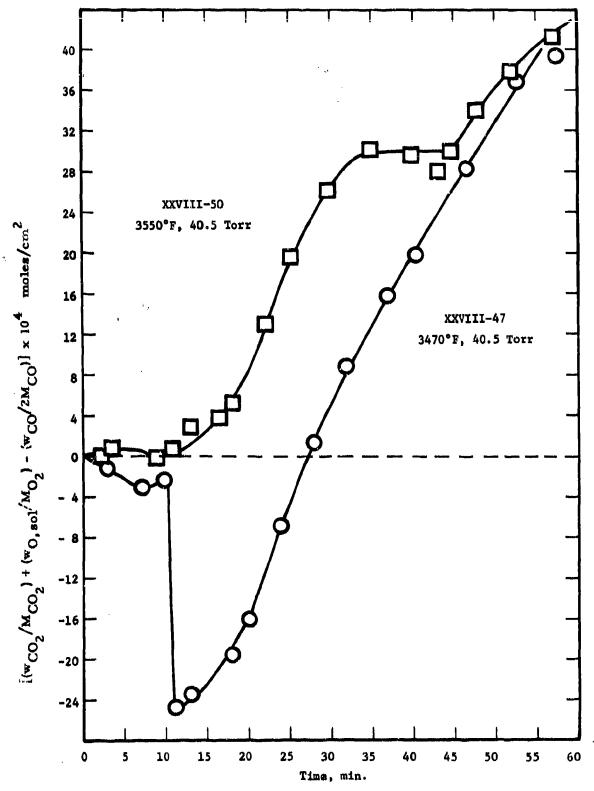
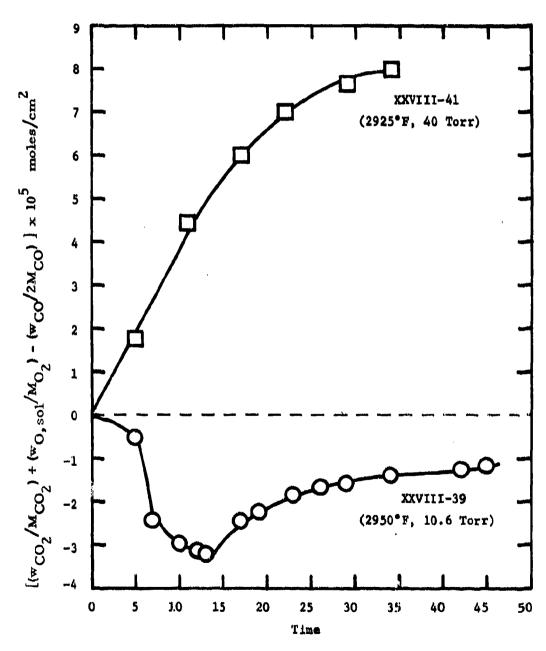


Figure 90. Oxidation of JT0992 (C-HfC-SiC) (F-15) Composite as a Function of Time at 3470°F and 3550°F.



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Figure 91. Oxidation of JT0981 (C-ZrC-SiC) (F-16) Composite as a Function of Time at 2925°F and 2950°F.

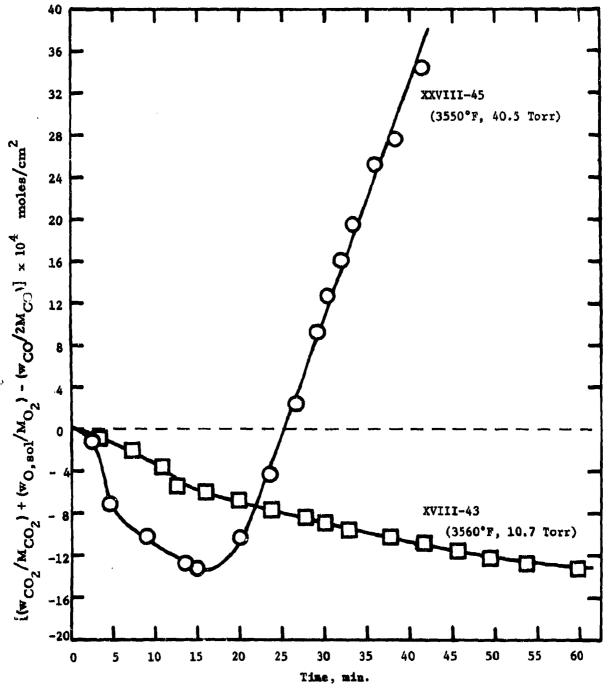


Figure 92. Oxidation of JT0981 (C-ZrC-SiC) (F-16) Composite as a Function of Time at 3550°F and 3560°F.

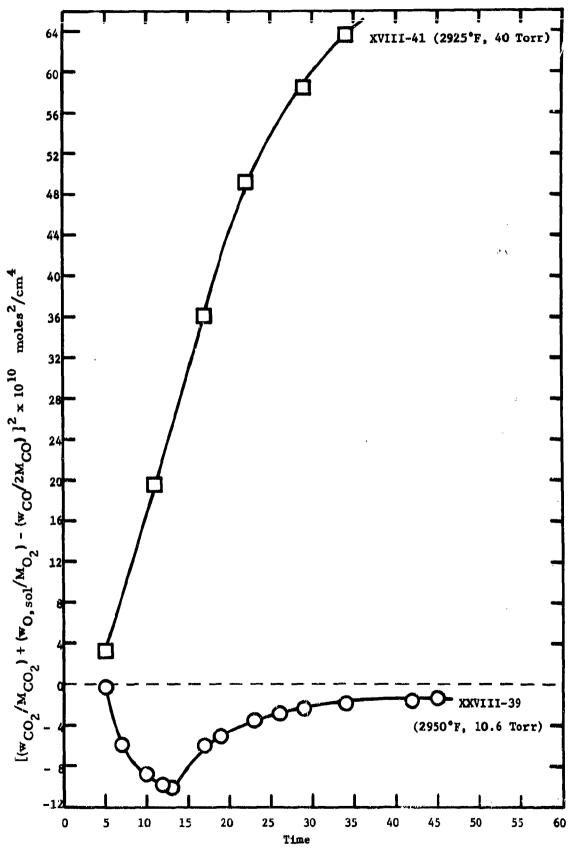
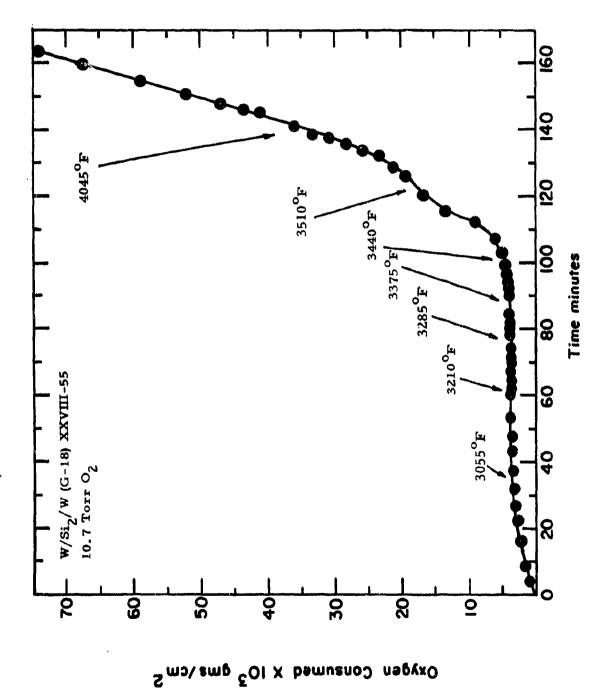


Figure 93. Parabolic Representation of Oxidation of JT0981 (F-16).



Oxygen Consumed as a Function of Time for WSi_2/W (G-18) at a. Oxygen Partial Pressure at 10.7 Torr. Figure 94.

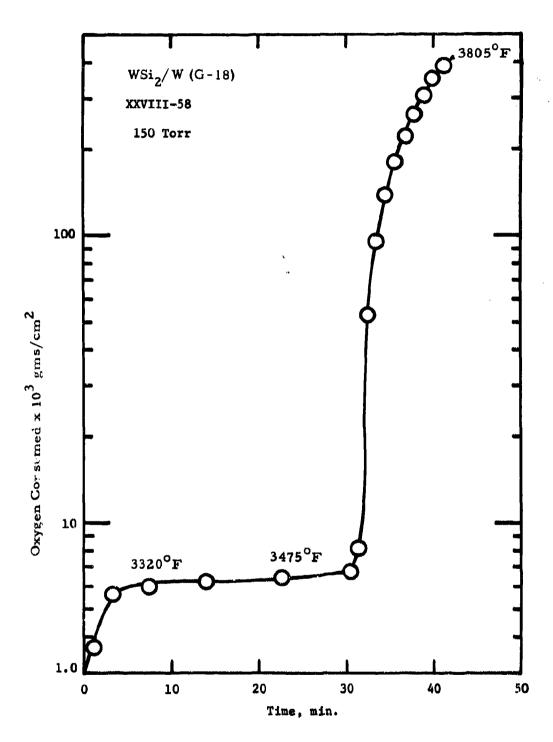


Figure 95. Oxygen Consumed as a Function of Time for WSi_2/W (G-18) at an Oxygen Partial Pressure of 150 Torr.

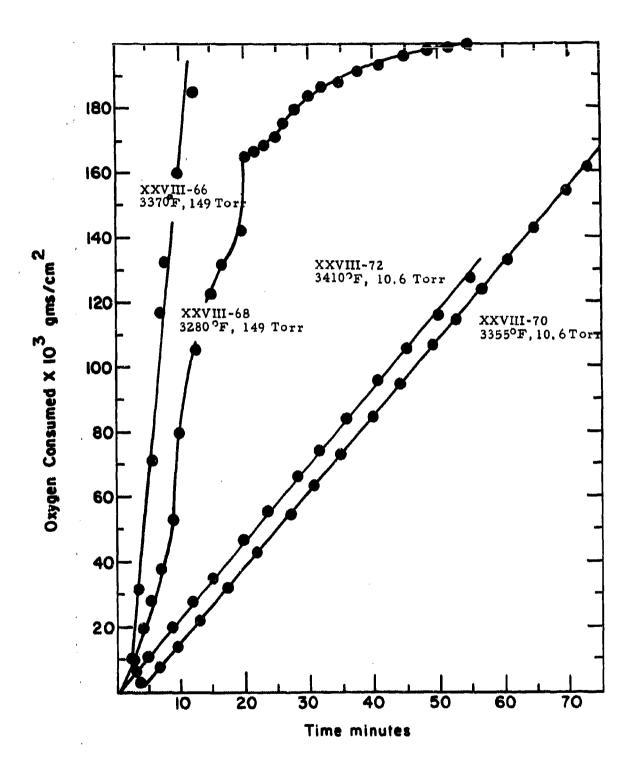


Figure 96. Oxygen Concumption as a Function of Time at Oxygen Partial Pressures of 10.6 and 149 Torr for WSi₂/W (G-18) near 3500°F.

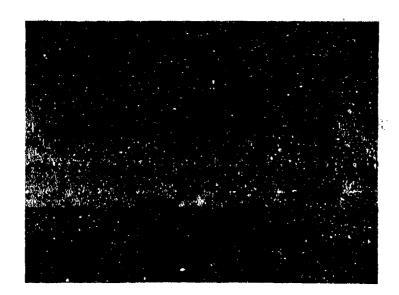


Plate No. 1-5390

Figure 97. Macrophotograph of WSi₂/W(G-18) Coated Samples Exposed at a Partial Pressure of 10 Torr O₂ at 3070(#37), 3180(#38), 3250(#41), 3380(#42) and 3460°F (#43), Respectively for One Hour.



Plate No. 1-5404

Etched with Murakami's Reagent

X200

Figure 98. Coating on WSi₂/W(G-18) Test XXIX-42 after One Hour at 3380 F in 10 Torr O₂. Width of W₅Si₃ Zone is 3.55 Mils.

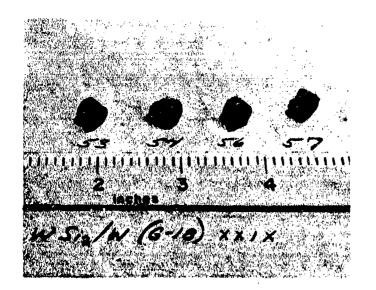


Plate No. 1-6886

Figure 99. Macrophotograph of WSi₂/W(G-18) Coated Samples Exposed at a Partial Pressure of 149 Torr at 3460 (#53), 3560(#54), 3560(#56) and 3500°F(#57), Respectively for One Hour.



Plate No. 1-6883

Etched with Murakami's Reagent

X250

Figure 100. Coating on $WSi_2/W(G-18)$ Test XXIX-48 after One Hour at 3370°F at 149 Torr O_2 . Width of W_5Si_3 Zone is 3.55 Mils.

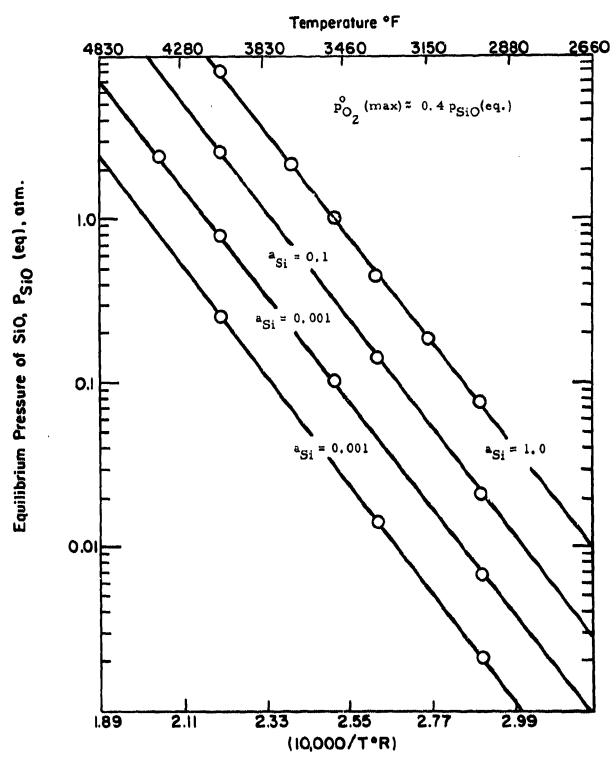


Figure 101. Pressure of SiO in Equilibrium with SiO_2 and Si as a Function of Temperature and Silicon Activity (a_{Si}).

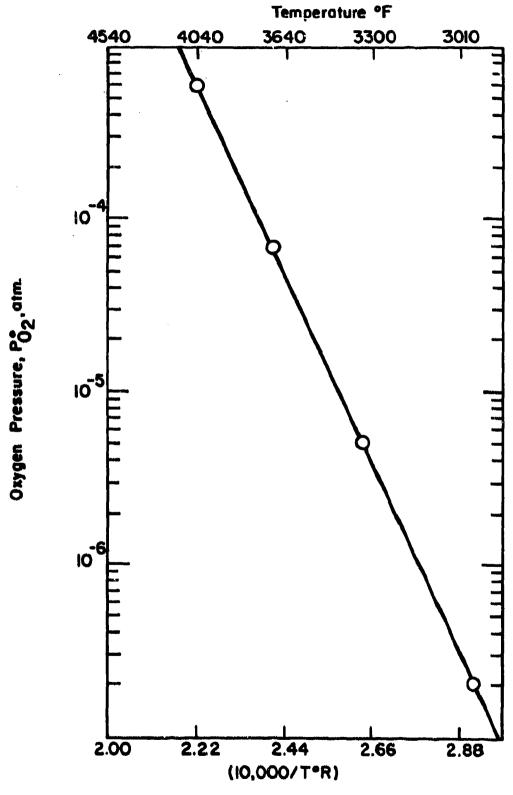


Figure 102. Minimum Oxygen Pressure at which Solid SiO is Stable as a Function of Temperature,

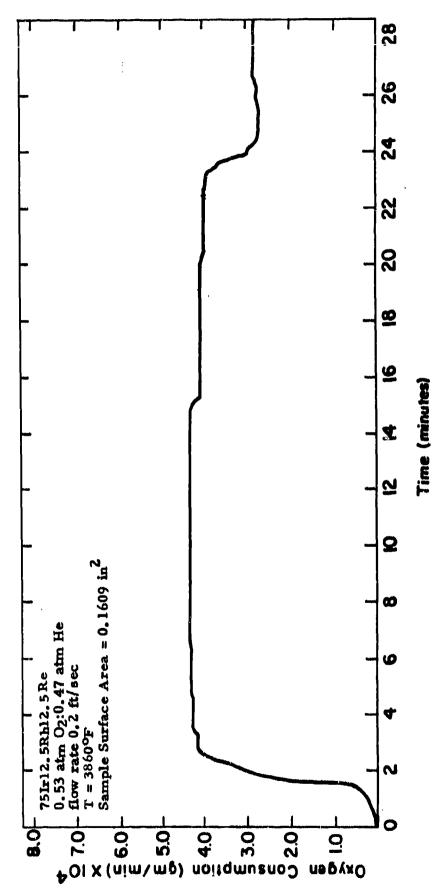


Figure 103. Oxygen Consumption Vs. Time for 75Ir12, 5Rh12, 5Re at 3860 F.

TABLE 1

CANDIDATE MATERIALS INVESTIGATED

Material	Code No.	Supplier
HfB, 1	A-2	Njagara Falls,
ZrB,	A-3	
HfB ₂ + 20 v/o SiC	A-4	
Boride Z	A-5	Carborundum Co., Niagara Falls, New York
HfB ₂ 1	A-6	ManLabs-Avco AF33(615)-3671
HfB, 1 + 20v/o SiC	A-7	ManLabs-Avco AF33(615)-3671
+ 20v	A-8	ManLabs-Avco AF33(615)-3671
+ 35v/	A-9	ManLabs-Avco AF33(615)-3671
ZrB2 + 14v/o SiC + 30v/o C	A-10	ManLabs-Avco AF33(615)-3671
	B-5	Union Carbide Corp., New York, New York
PG	B-6	General Electric Co., Detroit, Michigan
BPG	B-7	High Temperature Materials, Lowell, Mass.
Si/RVC	B-8	Union Carbide Corp., New York, New York
PT0178	B-5	Union Carbide Corp., New York, New York
Poco Graphite (AXF-5Q)	B-10	Poco Graphite Inc., Garland, Texas
Glassy Carbon	B-11	Lockheed M/S Co., Palo Alto, California
HfC+C	C-11	Battelle Memorial Institute, Columbus, Ohio
	C-12	Battelle Memorial Institute, Columbus, Ohio
JTA (C + ZrB, + SiC)	D-13	Union Carbide Corp., New York, New York
KT-SiC 2	E-14	Carborundum Co., Niagara Falls, New York
JT0992 (C + HfC + SiC)	F-15	Union Carbide Corp., New York, New York
JT0981 (C + ZrC + SiC)	F-16	Union Carbide Corp., New York, New York
WSi2/W	G-18	General Electric Co., Cleveland, Ohio (Type MK-W)
ı		TRW, Cleveland, Ohio (WSi2 coating)
Sr-Al/Ta-W	G-19	National Research Corp., Newton, Mass. (Ta-10W)
		GT&E, Hicksville, New York (Sn-Al coating)
W-Zr-Cu	C-20	Rockeydyne, Canoga Park, California
W-Ag	G-21	Wah Chang Corp., Albany, Oregon
SiO ₂ + 68.5 w/o W	H-22	Bjorksten Research Labs, Madison, Wisconsin
$SiO_2^2 + 60 \text{ w/o W}$	H-23	General Electric Co., Willoughby, Ohio
SiO ₂ + 35 w/o W	H-24	General Electric Co., Willoughby, Ohio
Hf-20Ta-2Mo	I-23	Wah Chang Corp., Albany, Oregon
Ir/Graphite	1-24	Battelle Memorial Institute, Columbus, Ohio
		General Technologies Corp., Restor, Virginia

TABLE 2
SUMMARY OF AIR OXIDATION RESULTS FOR HfB_{2.1}(A-2) AND ZrB₂(A-3)

н	IfB _{2, 1} (A-2)		2rB ₂ (A··3)
	L_(mile) D_(mile) L_(mile)D_(mile) demile)	Test No. Time 1ºF	Lo(mile) Do(mile) Lo(mile) Do(mile) d(mile) Initial dimensions linal dimensions length/dism
266 (0, 9) 60 327 260 (0, 9) 60 327 270 (0, 9) 60 327 271 (0, 9) 60 327 271 (0, 9) 60 377 320 (1, 10, 9) 60 377 320 (1, 10, 9) 60 377 320 (1, 10, 9) 60 377 320 (1, 10, 9) 60 377 320 (1, 10, 9) 60 320 331 (1, 10, 9) 60 320 335 (7, 2) 60 320 3377 (0, 9) 60 320 3	00	175 (0.9)	354 481 313 442 21/20 3142 482 272 365 35/49 3144 481 213 377 56/51 101 491 100 491 1/1 101 495 98 487 2/4 93 494 82 476 6/9 102 492 72 448 15/21 330 491 264 381 31/54 140 491 222 342 59/78 340 491 242 322 342 59/78 340 491 242 342 59/78 340 491 242 342 59/78 340 492 ALL GONE: >170 318 492 ALL GONE: >170 318 492 315 422 40/35 12/ 493 107 466 10/14 426 401 328 356 422 40/35 12/ 493 107 466 10/14 426 400 392 371 17/15 426 400 392 371 17/15 436 401 321 304 51/49 437 400 42 5 386 14/7 438 400 42 5 386 14/7 438 400 42 5 386 14/7 438 400 42 5 386 14/7 438 400 42 5 386 14/7 438 400 42 5 386 14/7 438 400 42 5 386 14/7 438 400 42 5 386 14/7 438 400 42 5 386 14/7 438 400 42 5 386 14/7 438 400 42 5 386 14/7 438 400 42 5 386 14/7 438 400 42 5 386 14/7 438 400 42 5 386 14/7 438 400 42 5 386 14/7 438 400 42 5 386 14/7 438 400 42 5 386 14/7 438 400 41 371 388 60/67 312 426 401 374 336 82/33 316 491 279 440 24/26 427 401 41 388 8/8 427 401 40 374 336 86/32 427 401 41 388 8/8 427 401 40 377 378 8/8

The symbols ", ", " , " all denote simultaneous run

TABLE 3

SUMMAF.Y OF AIR OXIDATION RESULTS FOR HtB₂ + 20%SiC(A-4) AND (A-4-2)

		HEB ₂	+ 30%84C (A-4)						w	+ 26 y/a	MC IA-4.	.23		
										•					
<u>Tout Mo.</u> (Volstity-IL/sec)	X Spec (male)	<u> </u>		D _e (mile) none issu	(ملاده) <u>دا</u> سنة لمدة	<u>D</u> imile) Secional	<u>dimile)</u> longth/dine		SERIE	r i r	COUL ST	TARILLE .	Up and	PARTIES.	dimilo) Longilo / dila
322 (0.9)	4	3200	442	105	442, 442,	505	9/0 .	441°	15	1540	349	477	325	474,	01/120*
222 (0, 1)	4	3414	398	504	4424	582°	(0/2)°	(1.9)	30	1540	362	474	344	#	(37/84)*
324 (0. 9)	4	3670	373	104	394 367 361 368	444	(0/2)* 2/3 (4/4)*	(1 u)	44	3570	365	487	344. 276 344. 273	W.	5/6 (41/53)
145 (0, 9)	-	3030	406	504	360*	\$35\$5\$	(12/E)*	(1.8)	124	3576	354	477	300	436	(P183)
		3721		105	446 446* 377		0/0 (0/0)	143	16	3730		474		444	/2
334 (0, 9)	44		393		2737	371	(60/67)°	(1.9),	38	3730	362	474	240	444. 444. 474.	(-1/19)*
410 (0, 9)	44	3095	406	505	346. 840.	444 301	463/10E)*	(1.0) 665**	4	3723	342	441	3120	12)* 441.	(36/11)*
411 (0.9)	•	3474	403	505	561.	474	101/97)*	(1.4) (1.0)	128	3734	349	477	345 100*	461, 172,	(9), / 100s
412 (0.7)	*	3732	489	505	344 801* 394 315*	491	(47/39)	(5.0) 679	4	3000	304	477	146	370	76/113
413 (0, 9)	*	4055	>99	503	340	463	24/61	(1.4)	-				- 64	•	D148
460 (1, 6)	#	3034	396	104	371	463	12/26	(1.8)	40	3961	349	477	117	324	43/74 (>179)
461 (1.8)	120	3431	502	503	#i,	W.	38/34	726	4	1990	344	477	139	416	194/13p (>173)
514 (1.0)	15	3796	434	504	414	456	(31/334°	(1.0) 726 (1.8)	44	1996	376	477	174	444	100/135
915 (1. 4)	30	3795	522	504	373° 487°	414	21/8	(1.8) 847	15	3962	273	404	144 186 236	437	(2100) 25/31 (67/75)
534 /1 . 81*	15	3875	484	492	437	القلد	1/4	(1,0)	30	3894	314	476	162.	14.	40/44
837 (1.8)*	30	3674	441	442	444	447	(10/12)	(1.4) 949	4	1074	349	474	ivi	301.	(104/139) 99/87 (2195)
636 (1.4)*	4	3676	444	564	4174	400	(1) (1) (1) (1) (1)	(1.4)	126	1074	341	478	212	321,	84/76
A30 (1.00*	120	3675	484	104	673 677 677 576	447	• (15/33)*	(1.0) 917	44	1259	103	494	101	491.	(>191)
544A (1.4)*	15	3465	444	477	376	447	104/391	(1,0) 919	64	1784	101	494	101*	491	10/4)
846 (1.00*	30	3484	441	477	414	447	, tration,	(1.4)	44	2199	99	444	1014	***	(0/H)
					104	457 390	(30/44)	(1,4) 92) (1,4) 939**	44	2401	100	441	*7"	\$61 \$41	(1/1)
546 (1 . M ⁴	40	3600	456	544	***	#	(14/4m)**	(1.4)	15	4010	344	943	***	111-	/7/1m*
647 (1.M*	130	3446	407	105	-	•	P-2-00	(1, 9)	30				393 867	414. 397	83/66 (46/736 63/76
972 (J. 48 ⁴	130	3434	444	905	439	- 44i.	44/4	(1,0		3996	114	491	130	364 337°	(01/131)
673 (1.4)	340	3430	175	104	274	314	(42.0m°	441 go	**	1001	344	404	187	144	(>174)
àir (à. u)	•	3471	346	461) 113.	41	(16/32)*	(1.B)	130	4860	-37	561		SUME	>144
691 (1.0)	69	3464	304	467	134		>170	992 (1.4)	4 # 30	2994	740	477	143	234	(>199/174 (>199/
943 (1.0)	40	MY	6 676	474	198	346	, , , , ,	944 (), #k	64	744	198	60)	190 174 341	476	111/14
994 (1.4)**	120	364	344	410	22	44	20/27	946 (1. 44	44	1343	100	476	341. 334	371	(23/14)
505 (L. 19 ⁶⁶	140	5446	361	406	AL.		>191	947	40	3449	346	470	14,	<u></u>	3/1
396 (1.0)**	444	Nig (477	او داه	COM	*194 *180	11.4	40	3544	147	414			(AL/32)
***************************************			- -				>100 >100	(1. 0) 1961	4 m 30	3401	350	476	301	414 414 744	(48/29)* 89/29
								(1, 6) A Dankastan					761	362	(75/56)*

*Deplotits true dimensions.
The symbols o, +. 0, ** all drusts simultaneous runs in hippy forware.

*Depistion name directs incu,
The Humbals C. . . . and 00 all deputs simultaneous was

TARTE 4

SUMMARY OF AIR OXIDATION RESULTS FOR HfB_{2.1}+20v/oSiC(A-7),

ZrB_{2.1}+20v/oSiC(A-8), HfB_{2.1}+35v/oSiC(A-9) AND

ZrB₂₊₁4v/oSiC+30v/oC(A-10)

						•					Z:B2 + 20	V/6 84C	(A-8)		
	н	11.581	20 v/o S	(C(A-7)						T°F.	L. (mile)	D (mile)	L_(mile)	D'(wife)	d(rolp)
	Time				L(milie)	D _f (mile)	d(mile)	Test No.	Time (min)		MINER DE	ensions	Inal dies	Reloas k	agth/dlam
Test No.	e) (fida)	<u> </u>	nitial dis	mensions	Inal dim	ensions i	engih/diam	(Velocity-M/sec)	60	3560	197	351	270.	314.	(36/32)*
304	60	3720	300	351	215	344	3/4 (>\60)*	343 (0,9)		-		381	225	340	2/2
(0.9)		•	301	351	2:16		3/5	389 (0, 9)	60	3290	100		297.	128	(15/12)* (15/12)*
387 (0.9)	60	1560			231*	343•	(35/54)*	398	40	3720	300	351	188,	202.	(2110)
396	60	3560	254	351	755 1.95*	346 257*	(32/47)*	(0, 9) 399	60	3735	300	351	150,	2174	(2(60) 75/64 (2(60)
(0.9) 427	60	3875	300	351	265*	339 304*	(18/24)*	(0.9)	40	3465	300	361	281.	341.	9/8 .
(0.9)	60	3595	300	350	294	344	1/1	450	•-			381	145	261" 337,	(68/35)
442 (0.9)				350	246°	2714	(26/40)*	432 (0, 9)	60	3450	100		292, 236	227	(32/62) 10/12
492 (0.9)	60	3270	299		298 e	349 341*	(4/5)*	437	40	3540	301	150	261. 240°)26. 246	(31/42)
493	60	3270	301	351	299 294*	350 344*	(4/4)*	(0.9) 43 8	60	3560	299	351	274_	144 326 281	10/13
(0.9) 494	60	3270	350	350	347 342*	348	2/1 (4/5)*	(0.9) 631	60	3333	351	351	255" 344,	346.	(22/35) 2/3
(0.9) 496	60	3250	259	101	257	340°	1/1	(0.9)	-			351	302	332	(1/10) 11/40 (2(1/4)
(0,9)				350	261*	343*	(4/4)* (69/45)*	635 (0,9)	60	3940	351		0	232,	(2(7))
49 8 (0.9)	60	3640	350	390	212*	261*	(69/45)*	903	60	3575	122	340	245	332, 304 100,	(34/23)*
100	60	3740	350	350	345 324	338	(13/24)*	(0.9) 913	60	3865	333	350	167,	100,	(M67)*
(0,9) 524	40	3830	300	350	268	297	(>15/27 (>150)*	(0, 9)	40	3290	333	110	325.	34j.	. 43
(0.9) 525	60	3615	30 L	351	280.	324	10/14	91 B (U. 9)				494	300°	331	(17/14)*
(0, 9)	•			436	266	432	(×151)*	1499	15	3518	345	424	347	414.	(9/,12)
1482	15	3534	270		259*	419*	(6/9)	(1.8) 1500	30	3515	364	424	3494	408, 367 407, 384	(9/12) (11/10)
1483	30	3550	277	434	267 255*	417	(11/12)	(i. #) \501	40	3515	424	426	366. 344	407.	(10/10)
(i.8) 1489	60	3580	333	436	330	421	(12/14)	(1.0)	-			426	367	494	18/.1
(1.8) 1490	120	3450	463	435	450	417	(19/22)	(1.02 (1.6)	120	3515			313.	404, 363 413,	(40/32) (12/12)
(1,4)		•			425*			1504	15	3511	344	426	333.	401	(Li/Li)
1491	1.5	3750	777	428	333	419 3710	(21/29)	(1.8)		3600	377	484	150.	407.	14/16
(1,8) 1492	30	3780	394	428	388	416	3/6	1507 (1.4)	30				350.	407. 389	(24/19)
(1.8)	60	3750	357	427	318*	372*	(36/53)	1810	60	3600	583	424	376a 345	415. 391	(19/19)
(493 (1.8)				•	249"	262*	(84/63) 9/7	(1.4) 1911	120	3600	404	424	361. 332	401	(19/19) (37/49)
1494	120	3750	340	426	343	413	(>j 90)	(1.4)	18	3700	341	424	3434	415.	(19/17)
(1.8) 1495	15	3900	343	429	378	319	(51/55)	(1.6) 1818				424	351	393° 406	(17/17)
(1.3) (0.96	30	3400	396	429	396 365*	412		(1.6)	30				381	401. 372	(36/27)
(1,4)	40	3900		429	385* 386	249* 362	(92/90)	(1.6) 1819 (1.6)	40	370	404	426	343. 340	260	(38/89)
1497 (1.8)						126*	(92/90) (8/24 (/128 (44/28	1 1520	120	370	9 41	426	411.	404. 249. 347.	(40/40)
(498 (1.6)	120	3900	442	436	700	383	(32 (9)	(10) 1837	15	385	0 493	430	301	445.	(42/50)
10101								(l.4)	30		0 501	438	408´ 443.	339	19731
*Deplets	un auna di	mension						1536 (1.6)					463. 377	11. 11.	(62/74)
								(839 (1.6)	40	141	6 456	434	491	171°	43/34 (90/61)
								1 540	120	344	S 506	434	AL	COME	(>\$10) >E19
								(1.0)							V7

*Pontation some distantions.

TABLE 4 (CONT)

SUMMARY OF AIR OXIDATION RESULTS FOR $HfB_{2..1}+20v/osiC(A-7)$, $ZrB_{2..1}+20v/osiC(A-8)$, $HfB_{2..1}+35v/osiC(A-9)$ AND $ZrB_2+14v/osiC+30v/oC(A-10)$

				81C (A-9							2112 + 14				
Test No.	Time (mill)			D ₍ (mile) i			d(mile) ength/dlain	Test No.	Time (min)	Tor			L ₍ (mile)		d(mits) ength/dia
368	60	3270	299	351	297	346 336*	1/2	1128	60	3526	40 L	351	356 356	294 247*	23/28 (50/52)
201 201	60	3560	299	352	286	350	1/2 (-/8)* 7/1	(0.9) 1129	60	2941	401	351	399	347	(30/32) 1/2 (1/2)*
(0.9) 388	60	1810	299	361	230*	255*	(38/48) 3/2	(0, 9) 1130	60	3144	401	351	396	347°	3/2
(0, 9) 431	60	1900	249	351	5 H 3	325	(>150)* 8/13	(0, 9) 1131	60	3724	401	351	3884	338* 238	(7/7) 45/57
(0, 9) 44J	60	3540	300	350	497.	0* 349.	(>150)*	(0, 9) 1132	60	3335	403	351	0* 378	0° 340,	(2176) 1476
(0,9)	60	3270	300	150	297. 146* 294	349 204* 345	(17/73)*	(0, 4)	40	3132	401	353	394*	317	(24/17
(0,9) 499	60	3595	299	351	294 286* 291	337*	(7/7)*	(1. 6) 1134	60	3427	401		376* 365.	1214	(11/1)
(0.9) 503	60	3470	100	350	191*	230°	(54/60)*	(1,8)					350*	298*	(26/2·
(0.9)					161*	271*	(60/40)*	(1, 0)	60	3042	490	351	3914	349 344*	(4/4)
\$11 (0.4)	40	1760	300	350	295	344	{10B/}*) 136 (1.6) 1137	60	267.2	401	351	149*	150*	(126/1
								(1.6) 1136	60	3524	657	4 38	498*	409 377	(30/3
								1116 (1.0)	60	3739	544	438	471 335*	774 ₄	(15/1)
								(1.8) 1139 (1.8)	60	3913	544	438	ALL C	IONE	(2219)
								1259 (1.8)	60	1204	431	418	424	418	3/0
* Depietion	n none din	and lone						1260	60	2204	427	416	410	415	-1/1
			•					(1,#) 126) 1546 (1,8)	60 15	2900 3500	479 300	434	476	431	17/2
								1547 (1.8)	30	3500	304	440	231	364	37/3
								1548 (1.8) 1549 (1.8)	120	3500 3500	400 363	351 439	346 232	279 302	27/3 66/6
								1551 (1.8)	30 15	3650	139 139	432 438	255 165	141	42/4
								1553 (1.0)	50	1650	401	351	319	244	43/5
								1554 (1.8) 1555 (1.8)	120	3650 3764	496 348	440	94 306	155	201/1
								1556 (1.8)	iñ	1764	401	440 350	362	420 321	1371
								1557 (1.8)	60 110	3764	389 865	439	ALL (**	>31

^{*}Depletion some dimensions

TABLE 5

SUMMARY OF AIR OXIDATION RESULTS FOR BORIDE Z(A-5),

HfB_{2.1}(A-6), RVA(B-5), PG(B-6), BPG(B-7), PT0178(B-9) AND

AXF-5Q Poco (B-10)

Test No. (Velesity-R/sec)	Time Top	BORIDE E(A-S) L_(mile) D_(mile) L_(mile) D [ATULL SHAMESISES STATE SHAMESISES	(mile) : d(mile) asions (mgth/dam	Tast No.	Time T	LCB _{2, 1} (A-6) y L ₀ (mile)F ₀ (mile)	ile) L _e imile)D _e imile) e	(141 <u>0)</u>
1166 (1.8) 1167 (1.0) 1169 (1.8) 1169 (1.8) 1174 (1.0) 1179 (1.0) 1284 (1.0)	40 1920 40 2964 60 3245 40 3454 40 3428 40 3734 60 3124 60 2806	\$23 491 101 297 465 287 312 490 291 385 485 324 373 490 327 513 491 387	95 211/198 977 9/4 MAT 11/12 MB3 14/16 634 22/16 637 62/52 691 -1/-1 491 3/-1	321 (0.9) 329 (0.9) 338 (0.9) 349 (0.9) 351 (0.7) 360 (0.9)	60 3R 60 3R 60 36 60 36 60 30 60 37 60 38	05 302 301 90 301 351 90 250 351 90 257 353 30 281 351 70 281 352	280 329 11 167 179 67 248 342 6, 239 341 6 269 340 6	
Tast No. (Vetesty-n/166) 1.44 (0.9) 1.47 (0.2)	10 201 10 311	" <u>United Circlestons (New Circles)</u> 13 493 468 331 19 403 467 314	O _r (mile) \$10451-04(mile) \$10451-04(mile) \$10 01/05 \$11 90/05 \$14 70/66	364 (0. 9) 367 (0. 9) 369 (0. 9) 486 (0. 9) 486 (0. 9) 486 (0. 9) 507 (0. 9) 1100 (0. 9) 1100 (0. 9) 1100 (0. 9)	60 34 60 14 60 14 60 14 60 17 60 17 60 17	94 281 391 70 281 391 50 200 384 50 201 39 70 300 394 70 300 394 30 300 394 72 393 391 73 393 391	266 310 17. 266 290 16 283 297 16 151 172 207 54 162 207 54 132 343 330 5 132 344 12	
144 (0.9) 147 (0.9) 148 (0.9) 150 (0.9) 152 (0.9) 173 (3.4) 195 (0.9) 196 (1.8) 197 (3.4) 197 (3.4) 199 (9.0)	10 341 10 341 10 426 18 379 10 201 10 171 10 271	6 511 466 338 6 513 467 350 6 506 466 241 14 513 457 450 13 528 466 437 13 538 467 325	352 40/77 353 40/77 353 41/62 274 132/107 342 47/73 350 51/48 54/ 213 104/137 179 119/154	1103 (0. 9) 1104 (0. 9) 1105 (0. 9) 1106 (0. 9) 1107 (0. 9) 1211 (0. 9) 1212 (0. 9) 1223 (0. 9) 1224 (0. 9)	60 30 60 34	173	300 290 III 310 304 II0 141 130 I3	
Topt No. (Valestry-14/see	, ,	TRUSC CHARLES HEAT WAS	THE PARTY NAMED IN	Tom No. Ti	<u> 1°7</u>	PT6178 (B-9) L _a (mile) D _a (mile)	Lefaile) Defaile) effect	<u> 141</u>
140 (0. 9) 141 (0. 9) 142 (0. 9) 151 (0. 9) 153 (0. 9) 161 (3. 4)	10 279 10 316 10 391 10 301 10 419	12	417 19/30 416 99/30 400 45/40 411 96/40 191 96/44	,,,,,,,,,,,,,,,,,,,,,,,,,,,,,,,,,,,,,,,	10 3030 10 2760 5 2486 6 3083 5 3340		ALL CONE >816 No hierograments 2007 231 346 61/7 266 314 70/6) 15
200 (0, 9) 201 (1, 0) 202 (2, 4) 203 (7, 2) 204 (7, 0) 1272 (1, 3) 1273 (1, 0)	10 20 10 20 10 20 10 20 10 20 10 31 10 34	10 558 405 510 10 540 404 490 14 513 407 437	434 19/27 387 24/14 363 23/12 314 43/86 327 97/86 371 51/51 446 L4/23	1007 (1.0) 1006 (2.0) 1001 (1.0) 1001 (1.0) 1002 (1.0) 1008 (1.0) 1008 (1.0) 1008 (0.0) 1008 (0.0) 1008 (0.0) 1008 (0.0) 1008 (0.0)	\$ 3641 \$ 3964 \$ 3687 \$ 3486 \$ 3486 \$ 3466		200 334 43/8 201 894 48/7 244 363 48/6 200 308 81/6 244 808 43/7 271 31, 110/1	11 17 18 105
(CHENT-WO	Time T	Limited District Manual Limited I	-	Total Manager Till (Vallety-Rivers)		•	Spinited Spinited Marie Chillian Spinite Villand	
165 (0), 99 146 (0), 99 146 (0), 99 146 (0), 99 147 (1), 99	10 161 10 261 10 401 10 401 10 371 10 371 10 200 10 201 10 314 10 314	16 100 400 417 100 100 100 100 100 100 100 100 100 1	413 36/32 419 47/36 47/46 47/46 844 66/42 453 33/32 411 21/46 411 21/46 371 23/46 349 41/46 349 41/46 345 37/71 467 56/34 355 35/64 346 31/39	1071 (1.00 1072 (1.00 1073 (1.00 1074 (1.06 1076 (7.2) 1076 (7.2) 1274 (1.0)	19 2742 19 7013 10 1121 10 1644 10 3444 10 275 10 385 16 300 16 3180	463 (00) 464 (46) 460 (42) 410 (42) 410 (42) 410 (42) 410 (42)	Mai Mai	124 149 149 174 181

TABLE 6

SUMMARY OF AIR OXIDATION RESULTS FOR Si/RVC(B-8),

HfC+C(C-11), ZrC+C(C-12) AND KT-SiC(E-14)

(Voltages)-1/1011 Time 2 1 Time 1 Time 2 1 Time 2 1 Time 2 1 Time 2 1 Time 3 1 Time 3 1 Time 4 Time 4 Time 5 1 Time 6 1	### SA/RYG (19-6) **Logination Documents** **Logination Documents**	Took No. Time To Lomby Domile Limits) Extended to Complete Total Complete C
Tabl No. (Time 2 Time (TABLE No.	362 483 341 394 21/39 417 483 383 385 385/38 447 483 370 373 385 38/39 448 483 349 333 85/69 418 483 296 339 86/67 369 482 344 396 26/27 464 483 399 364 24/27 464 483 399 364 34/34 477 483 381 374 46/40 806 483 404 382 81/31 433 483 384 397 23/28 359 453 290 377 38/38 454 453 332 21/2 31/6 454 453 332 22/2 31/6 454 453 332 22/2 31/6 454 453 332 22/2 31/6 454 453 332 26/2 31/2 454 453 332 26/2 454 453 332 26/2 454 453 336 36/2 456 457 236 26/6 556 427 289 330 38/49 356 427 289 350 36/49 356 427 289 366 56/6 356 357 426 295 349 40/39 357 426 295 349 40/39	Total No. Time T

**Inserted into hot furnace.

TABLE 7
SUMMARY OF AIR OXIDATION RESULTS FOR JTA(D-13)
AND JT0992(F-15)

Toot No. Time T°F (Valestry-1875ec) [Mill]	ITA (D-13) Lafratio) Dafratio) Lafratio) Dafratio) Tentel Chilipericae Trier Chilipericae Tengan Colum	Took No. Time Top Laming Daming Daming Daming Commission (William Commission
219 (9.9) 60 2190 210 (10.9) 60 3642 210 (10.9) 60 3642 241 (0.7) 60 3142 241 (0.7) 60 3142 241 (0.7) 60 3142 242 (0.7) 60 3142 243 (0.7) 60 3142 244 (0.7) 60 3142 245 (0.7) 60 3142 246 (0.7) 60 3142 247 (0.7)	1	123 (6.7)

Depletion some dimensions.
The symbols *,**, U all denote simultaneous runs
to large firmers.

TABLE 8

SUMMARY OF AIR OXIDATION RESULTS FOR JT0981(F-16),

WSi₂/W(G-18) AND Sn-AI/Ta-W(G-19)

J70901 (F-14)	W81 ₂ /W (C-18)
Tack No. Time Lo(mile) De(mile) Le(mile) De(mile) (mile) (mile) (mile)	TestNo. Time Lo(mile) Do(mile) Lo(mile) Do(mile) (mile) (m
137 (0. 0) 1804 182	476 (1.8)
## 11.8) 46 3785 437 479 314 438 36746 ### 11.8) 46 3486 487 479 314 438 36746 ### 11.8) 46 3687 487 479 314 438 36746 ### 11.8) 46 3687 487 487 487 487 487 1874 ### 12.8) 46 3783 486 487 377 487 787 787 787 787 787 787 787 787 7	Sa-Al/Ta-W (Q-19) Tast No. Time Tag (mile) D _g (mile) L _f (mile) D _g (mile) (mile) (mile) (mile) (mile) (mile)
734 (1.8) 60 3460 718 1817 891 814 647/108 735 (1.8) 60 3460 718 1827 891 814 778 817/108 735 (1.8) 60 3731 648 994 812 778 78/108 737 (1.8) 60 3731 182 994 812 778 78/108 737 (1.8) 60 18 3371 336 448 385 685 21/17 736 (1.8) 60 318 318 414 429 310 438 27/27 736 (1.8) 60 319 414 429 310 438 37/27 736 (1.8) 60 319 414 429 313 394 386 18/60 736 (1.8) 60 318 348 395 427 341 388 18/60 736 (1.8) 60 363 348 427 341 388 18/60 736 (1.8) 60 363 448 427 347 340 386 18/60 736 (1.8) 60 363 448 427 347 340 64/78 736 (1.8) 60 363 482 423 446 427 37/34 825 (1.8) 60 310 576 428 361 147 107/121 825 (1.8) 60 210 510 510 487 186 164 167/163 826 (1.8) 60 210 510 520 429 186 164 167/163 827 (1.8) 60 210 510 520 429 186 164 167/163 827 (1.8) 60 210 510 520 429 186 164 167/163 827 (1.8) 60 310 674 429 186 186 187/163 827 (1.8) 60 310 674 429 186 186 187/163 827 (1.8) 60 310 310 474 429 186 486 17/163 827 (1.8) 60 310 310 474 429 186 486 17/163 827 (1.8) 60 310 310 310 487 449 186 186 187/163 827 (1.8) 60 310 486 329 429 186 186 187/163 827 (1.8) 60 310 480 320 489 184 486 17/163 827 (1.8) 60 310 480 310 480 310 487 317 310 517/0 824 (1.8) 60 310 310 480 329 489 341 480 87/163 827 (1.8) 60 310 480 310 480 310 480 310 317/0 824 (1.8) 60 310 310 310 310 310 310 310 310 310 31	390 (1.8)

The symbols *, **, " all jenets simultaneous run in large furners.

TARLE 9

SUMMARY OF AIR OXIDATION RESULTS FOR $SiO_2-68.5\%W(H-22)$, $SiO_2-60\%W(H-23)$, $SiO_2-35\%W(H-24)$ AND Hf-20Ta-2Mo(I-23)

	SIO.	-68.5% W	(H-22)						1	H-20Ta-2	Mo (1-23)		
Test No Time (Velocity-II/880) (min)	Top I	्र(mils) D _o ताक्षा कला	(mile) L	(mila) I mil dim	o ₍ (mile) nelune le	d(mils) ngth/dlam	Test No. (Velocity-11/146)	Time (min)	<u>T°r</u>			L ₍ (mila)		d(mile) longth/dlam
1034 (1.8) 60 1036 (1.8) 60 1038 (1.8) 60 1041 (1.6) 60 1056 (1.8) 60 1151 (1.8) 60 1158 (1.8) 15 1199 (1.8) 30 1160 (1.8) 60 1161 (1.8) 120 1162 (1.8) 15 1163 (1.8) 15	3276 3490 3491 3424 3837 3834 3682 3682 3682 3682 3639 3839 3839 3829	303 325 325 325 282 327 325 469 264 284 339 373 209 225 262	\$0777507750075008500950095009500950095009500950095009	297 325 328 204 300 187 287 287 287 328 344 175 169 171	50K 501 492 476 465 444 499 499 499 499 499 499 4463	3/1 2/3 4/8 38/16 14/16 6/16 2/5 6/5 18/18 17/5 26/7 42/16 34/25	190 (0.9) 291 (0.9) 292 (0.9) 293 (0.9) 294 (0.9) 294 (0.9) 295 (7.2) 415 (0.9) 415 (1.8) 516 (1.8) 516 (1.8) 516 (1.8) 516 (1.8) 516 (1.8) 516 (1.8)	40 40 40 40 40 40 40 40 40 120 120 4 H 13	3220 3020 3020 3024 3035 3406 3011 3119 33147 3147 3145 3305 3410 3417	401 370 402 407 447 401 393 410 409 819 801 803 825 407	500 472 503 501 503 497 506 506 509 490 608 491 107	347 379 389 321 40 123 80 343 449 449 444 444 449 321 197	487 485 485 485 136 148 488 488 488 488 488 488 488 488 488	17/14 6/3 7/4 43/39 204/ 137/181 57/ 44/25 31/45 11/9 20/26 20/26 50/26 50/27 92/71
⁸ Spacimen badty de	formed d						621 (1.8) 651 (1.8) 654 (1.8) 653 (1.8) 654 (1.8) 698 (1.8)	15 10 60 120 60	3371 3376 3380 3384	428 519 921 924 401 408	504 502 490 494 498 508	349 349 349 371 163	424 311 260 330 304 484	34/40 85/96 102/120 17/84 13/9
Test No. Time (Valuetty-M/sac) (init)	Tor	L _o (mila) L Marairan	o(mila)	L _f (mile) inst e lim	D _f (mile)	angin/diam.	498 (1.8) 499 (1.8) 792 (1.8)	42 40 15	3542 3560 3706 3125 3325	411	501 502 501 504 498	379 196 ALL 859 400 868 319	476 GONK 479 488 481	108/113 >403 34/11 4/25 24/37
H19 (1.8) 60 H20 (1.8) 60 H21 (1.8) 60 H40 (1.8) 60 1023 (1.8) 60 1025 (1.8) 60	3412 3618 3618 3672 3186 3382	392 400 391 401 410 394	505 505 505 506 506	375 No M 349 391 404 398	\$04 leasurem 499 483 506 503	ents 5/10 5/10 4/4	794 (1.6) 44 795 (1.4) 44 797 (1.4) 798 (1.8) 799 (1.4) 800 (1.5)	140 15 30 60 120 4 H 3	3146 3440 3408 3408 3400	461 705 714 763 736	101 104 106 108 199 101	669 601 Top	409 409 304 281 Distorte	86/46 37/48 27/100 78/112
1049 (1.8) 60 1034 (1.8) 60 1043 (1.8) 60 1043 (1.8) 60	3871 1692 3819 3907 4036	409 397 401 412 328	506 507 506 505 506	404 398 346 362 403 337	497 491 471 441 460	2/6 1/8 9/18 30/19	917 (1.6) 928 (1.8) 929 (1.8) 931 (1.8) 1006 (1.8)	60 60 60 15	1725 1725 1271 1707 1400	100 94 97 95 243	50A 503 50B 509 51A	269 100 90 93 84 813	344 800 498 803 468 490 449	0/1 4/3 3/0 6/21 16/11
1144 (1, 8) 4 u 3/ 1149 (1, 8) 15 1150 (1, 8) 30 1151 (1, 8) 60 1152 (1, 8) 120 1154 (1, 8) 15	3643 3672 3672 3672 3672 3846	412 178 193 492 496 173	506 506 506 506 506	170 161 484 175	507 504 495 497 488	4/-1 6/1 8/6 6/6 9/4	1007 (1,8) 1008 (1,8) 1009 (1,8) 1056 (1,8) 1056 (1,8)	30 40 140 15	3400 3400 3400 3479 3479	444	504 511 507 503 503	170 178 446 181 192 176	407 406 448 446 371	21/14 47/54 91/59 19/28 31/28 38/67
1156 (1.8) 50 1156 (1.8) 60 1157 (1.8) 120 1239 (1.8) 60 1240 (1.8) 60	3846 3846 3846 2708 2112	386 438	506 506 506 506 506	361 430 518 502 304	495 491 498 803 473	4/6 4/8 -6/4 13/2 18/16	1098 (1,8) 1474 (1,8) 1475 (1,8) 1476 (1,8) 1477 (1,8)	140 15 10 60	3450 3450 3450 3460	479 479 481 493 498	503 391 393 387 390	40# 43% 48.7 406	396 342 343 470 470	67/64 82/25 27/32 46/59 >145 36/37
1241 (1.8) 60 1242 (1.8) 60 1243 (1.8) 60 1281 (1.8) 60	1715 1613 1416 3500	339 560 178 323 38#	506 506 506 505	315 520 173 320 334	499 499 481	12/11 20/24 1/d 1/d 12/11	1478 (1.8) 1479 (1.8) 1480 (1.8) 1481 (1.8)	19 30 60 140	35 35 35 35 35 46	109 1495	340 340 388 396	432 402 77 ALL	317 241 96 90NE	36/37 54/75 209/146 1195
1288 (1,4) 60 •Specimen badly de	1803 Jornadi			314	484	14/11	** Simultar Simultar	MOTTH SIN	N.					
ashacunan nama as	,	810 ₂ -18%												
(Velocity-H7100) (International	g. zer	L _o (mile) Thittel di	nana tom	TAXT 41	MUNUTONE) d(mile) Langth/diam	ì							
1040 (1.8) 60 1045 (1.8) 40 1046 (1.8) 60 1047 (1.8) 60	3154 3256 3486 1042	300	505 505 506 506	397 273 Mal 244	509 514 ting 441	:								

(Velocity-H7 640)	(Min)	r°r	L _o (mile tkittal d	i) D _a (mile) Imanutum	L ₍ (mH • NAKT di n	D ₍ (mite hänetöks	renaturgini q(ilifia)
1040 (1.8) 1045 (1.8) 1046 (1.8) 1047 (1.8)	60 60 60	3254 3256 3486 3042	247 252 300 226	505 505 506 506	197 173 Malt 144	509 514 ing 441	:

^{*}Material deforms due to viscous flow at all temperatures studied.

TABLE 10 SUMMARY OF ARGON INERT TEST RESULTS

Material Ten He-		Ľ) D _e (mile) Militari (inch	L. (mile)	D _e (mails) mailtean	INTERNATION	Weight is remel
1335 1326 1337 1338 PT0176(B-0)	**	3440 3574 3646 4001	245 252 263 267	330 323 323	246 282 362 367	320 310 311 321	*/* */*	0,4141/0,4141 0,4471/0,4110 0,4447/0,4410 0,4734/0,447
#194 1194 1196 1196 1201	49 49 44	2996 3466 3796 4813	449 433 414 461	***	449 433 414 440	***	9/0 9/0 9/1	44.0 44.0 48.0
1195 1197 1199 1200 1202 1202	40 40 40	3547 3794 4433 4466 4176	414 417 410 307 304	470 470 470 470 470	48 6 41 8 41 0 17 6 39 6	449 490 446 491	1/0	686 680 680 611 6 600
32#34 (k=19) 510 1906 1904 1904	40 40 40	3843 3513 4190 4197	184 405 184 463	481 484 485 491	389 404 389 483	***	1/1	6.2544/5.2422 9.3220/5.4675 4.7638/4.7164 6.4996/6.1937
1311 1314 1316 1316 WM ₂ /W(G-16)	40 40 40	3545 4612 4174	404 389 401 401	407 470 490 488	403 403 403	490 496 441	-1/0 0/0 -1/2 -1/3	3,8339/3,4889 3,3790/3,3120 3,7149/3,6962 3,8682/3,2793
1265 1266 1267 1267 1211 1212 1212 1214 1214 1214 1214	40 40 40	3101 3280 3504 3670 3700 4615	271 271 264 272 264	291 313 313 307 266 312	171 171 191 165 174 267	3 3 107 305 305 319	0/0 3/3 -1/1 -1/1	5.1754/5.1755 6.0094/6.0046 5.6557/5.4140 5.6541/5.2658 5.1257/4.4710 5.7964/5.4078
12169 12169 12169 1267 1267	60 60 60 60	3434 3992 3812 3000 3300	309 313 339 867 346 384	506 506 506 506	200 237 321 246 347 360	445 43266 45466 566 102 490	18/31 38/37 9/36 1/0 -1/2 -2/6	4,4481/3,4312 4,7943/3,3718 8,2330/4,4435 4,1882/4,1360 8,4440/5,3453 6,8492/5,2315

ose turgeten particles on surface due to sublimation of \$10₂, scimen hadly cracked.

TABLE 11 SUMMARY OF CXYGEN FICKUP, GAS ANALYSIS AND METALLOGRAPHIC DATA ON JTA(C-ZrB₂-SiC) (D-13) COMPOSITE

Weight Loss Carbon Consumed (gms/gms)	0.0828/0.0935 /0.0597 0.0716/0.0846 /0.0525 ****/0.0479+ ***/0.0262+ /0.331 /0.252	Recession Rate (mils/hr) 18/17 160/176 25/18 23/31 227/193 More than 500 mils/hr / 300/218 396/204 223/240 226/216 d. ar rate.
Exposure ate Time /sec) (min)	0.20 60 60 60 60 60 60 60 60 60 60 60 60 60	Observed Metallographically Final Dimensions Diam, /Height Recession R (mils) 265/80 18/17 225/70 244/68 255/189 255/189 255/189 255/189 255/189 255/189 255/189 255/189 255/189 255/189 255/189 255/189 255/189 256/216 2
T PQ at λ=0.75 at λ=0.65μ (oF) (torr/ft/sec)	2900 11.9/0.20 2910 40.4/0.20 2910 40.4/0.20 4++ 41 61.20 4++ 62.20 3663 149 /0.20 3663 149 /0.20 3653 149 /0.20 3653 149 /0.20 3653 149 /0.20	lated sign sign sign sign sign sign sign sign
Initial Surface Area Initial Weight at \(\) (cm^2/gm)	0.3887 0.4380 0.4380 0.3227 0.8458 0.8419 0.9231 0.8594 0.8594	Calcurosidation Received No. Re
Initial Initial Dimensions Diam./Height Initial (c)	301/113 1.609 293/135 1.668 294/103 1.481 300/251 2.42 300/248 2.41 300/244 2.59 300/243 2.59 300/253 2.45 300/253 2.45	Carbon (Co) (Co) (Co) (Co) (Co) (Co) (Co) (Co)
Oxidation No. D	XXVIII-28 XXVIII-31 XXVIII-52 XXVIII-60 XXVIII-60 XXIX-8(D-13) XXIX-12 XXIX-17 XXIX-20 XXIX-20	% Carbon Consumed 50 1. 28.5 54.8 13.0 10.44 6.54 6.54 83.0 74.0 65.6 47.8 90.0 ** Signs of me ** Temperatur *** Sample to b

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TABLE 12

SUMMARY OF OXYGEN PICKUP, GAS ANALYSIS AND METALLOGRAPHIC DATA ON JT0992 (C-HfC-SiC) (F-15) COMPOSITE

Weight Loss Carbon Consumed (gms/gms)	0.0106/0.0092 0.0107/0.0189 ***/0.1790 ***/0.1462 ***/0.0533	aphically Recession Rate (mils/hr)	1.0/ 3.0 1.0/ 2.0 42/34 98/- >2.7
Exposure Time (min)	15* 60 60 60 31	Observed Metallographically Final Dimensions Diam/Height Reces (mils) (mils)	295/116 296/105 204/185 Irr. Shape 103/- Irr. Shape 0/0
PO ₂ Flow Rate (torr/ft/sec)	10.3/0.2 40.1/0.2 40.5/0.2 40.5/0.2 149/0.2	ii ii	
$T \\ \epsilon = 0.75$ at $\lambda = 0.65\mu$ (°F)	2900 2950 3470 3550 3580	Calculated n Recession Rate (mils/hr)	35 3.0 ## 57 3.4 67 14.7 50 -
Initial Surface Area Initial Weight (cm 2/gm)	.609/0.6177 .560/0.5725 .30 /1.2401 .14 /1.0972 .60 /1.4781	Oxidation No.	XXVIII-35 XXVIII-37 XXVIII-47 XXVIII-62 XXVIII-62
Initia Initia (cn	1.600 2.30 2.14 2.60	20 A 32 A	2.08 3.53 63.4
Initial Dimensions Diam/Height	298/117 298/109 287/252 298/206 307/277	^w CO ₂ ^w CO 44 56 gms x 10	1.36/ 3.16/ 2.72/ 6.50/ 99.5 /24.9 /
Dir.		» 4	999
Oxidation No.	XXVIII-35 XXVIII-37 XXVIII-47 XXVIII-50 XXVIII-62	% Carbon Consumed	4.7 10.4 30.0 41.8 11.3 ⁺

*Whisker formation.

**Extraploation based on parabolic rate law (actual rate may be lower).
***Sample too badly oxidized to determine weight loss.
+Ascarite may have been exhausted.

TABLE 13

SUMMARY OF OXYGEN PICKUP, GAS ANALYSIS AND METALLOGRAPHIC DATA ON JT0981 (C-ZrC-SiC) (F-16) COMPOSITE

Weight Loss Carbon Consumed (gms/gms)	0.0274/0.0336 0.015:/0.0260 *** ***	Recession Rate
Exposure Time (min)	60 60 60 45 45	Observed Metallographically Finz I Dimensions Recession (mils) Limits 4. ½ / (mils) 291/103 4. ½ / (mils) 298/91 1. € / (mils) 298/91 2. ½ / (mils) 260/205 2. ½ / (mils) Sample Melted 85. / (mils) - /
PO ₂ Flow Rate (torr/ft/sec)	10.6/0.2 40.1/0.2 10.7/0.2 40.5/0.2 149 /0.2 149 /0.2	Sam Dian
$ \begin{array}{c} T \\ \epsilon = 0.75 \\ \text{at } \lambda = 0.65 \mu \\ (^{G}\mathbf{F}) \end{array} $	2950 2925 3558 3547 3550 3652	Calculated Recession Rate (mils/hr) 39 6.0 41 4.9 45 47 64
Initial Surface Area Initia! Weight (cm ² /gm)	1, 598/0, 3961 1, 490/0, 3380 2, 31 /0, 8319 2, 30 /0, 8191 2, 24 /0, 7816 2, 44 /0, 8993	Oxidation No. XXVIII-39 XXVIII-41 XXVIII-43 XXVIII-45 XXVIII-64 XXXVIII-64
Initia] A Initia (cr	1. 5. 2. 2. 2. 2. 2. 4. 4. 4. 4. 4. 4. 4. 4. 4. 4. 4. 4. 4.	*02 32 4 4.85 3.52 /10.3 /85.1
Initial Dimensions Diam/Height	300/112 300/ 95 301/229 300/227 296/225 295/261	WCO ₂ WCO WO ₂ 44 56 32 44 56 32 6.00/10.99/ 4.85 5.60/ 8.00/ 3.52 3.02/43.4 /10.3 113.8 /62.3 /85.1
Oxidation No.	XXVIII-39 XXVIII-41 XXVIII-43 XXVIII-45 XXVIII-64 XXIX - 1	% Carbon Consumed 17.6 16.0 26.9 72.4 11.9† 5.5

*Temperature dropped to 2900°F during the last 20 minutes of the run. +Ascarite may have been exhausted.

TABLE 14

SUMMARY OF OXYGEN PICKUP AND METALLOGRAPHIC DATA FOR WSi₂/W (G-18) (WSi2 Coating Initially 5 mils Thick)

Weight Loss Oxygen Consumed (gms/gms)	Sample reacted with ThO ₂ support rod on degassing. 10.7/0.2 60/0.006790 13/0.000106 13/0.003150 24/0.032900 13/0.0350 2/0.0350 18/0.0793 13/0.0793	ically	Comments	Extensive Reaction	Coating Failed
PO ₂ Exposure Flow Rate Time (torr/ft/sec) (min)	Sample reacted with ThO ₂ 10.7/0.2 60 13 13 13 24 24 13 24 13 13	Observed Metallographically	Recession (mils)	! !	17/13.5
$ \begin{array}{c} \mathbf{T} \\ \mathbf{e} = 0.60 \\ \mathbf{at} \lambda = 0.65 \mu \\ (^{O}F) \end{array} $	3465 3055 3210 3285 3375 3440 3510 2995		Final Dimensions Diam/Height (mils)		272/141
Initial Surface Area Initial Weight (cm ² /gm)	2.05/3.7371 1.99/3.5356		ion Oxidation	XXVIII-54 XXVIII-55	
Initial Dimensions Diam/Height	309/174 306/168 1		Calculated Recession Based on Equation	(11) (12) (12) (12) (12) (13) (13) (14)	(8)
Oxidation No.	**************************************		Calculated Recession (mils)	0.310 0.013 0.002 0.060 2.1	5.1

TABLE 14 (CONT)

SUMMARY OF OXYGEN PICKUP AND METALLOGRAPHIC DATA FOR WSi2/W (G-18) (WSi2 Coating Initially 5 mils Thick)

Weight Loss Oxygen Consumed (gms/gms)	/0.01235	0.469/0.424 0.188/0.421 0.781/0.386 0.458/0.281	Comments	Coating Failed Irregular Height (Failure) Irregular Diam (Failure) Coating Failed Coating Failed
Exposure Time (min)	4116	10 13 55 60	Observed Metallographically ins Recession (mils)	47/46 75/ 29/20 46/9 32/16
PO ₂ Flow Rate (torr/ft/sec)	150/0.2	149/0.2 149/0.2 10.6/0.2	Observed Maions Sph Rec	2 5 7 5 8 8 8 8 8 8 8 8 8 8 8 8 8 8 8 8 8
T $\epsilon = 0.60$ at $\lambda = 0.65\mu$ (^{0}F)	3320 3475 3805	3370 3280 3355 3410	Final Dimensions Diam/Height (mils)	214/73 158/128 251/143 206/140 252/127
Initial Surface Area Initial Weight (cm ² /gm)	1.98/3.5030	1, 69/2, 9885 2, 11/3, 8975 1, 84/3, 0910 2, 00/3, 4278	ion Oxidation	XXVШ-58 XXVШ-66 XXVШ-68 XXVШ-70 XXVШ-70
Initial Dimensions Diam/Height	308/164	307/118 309/183 298/157 313/159	Calculated Recession Based on Equation	(11) (11) (11) (11) (11)
Oxidation No.	ххуш-58	XXVIII-68 XXVIII-68 XXVIII-70 XXVIII-72	Calculated Recession (mils)	0.570 0.018 42.0 31.8 18.1 26.6 17.8

TABLE 15

本間関係の関係をおきているとあるよう。 では、1000円の対象がある。

SUMMARY OF OXYGEN PICKUP AND METALLOGRAPHIC DATA ON WSi₂/W (G-18) MATERIAL

Width of W ₅ Si ₃ Zone	(mils)	1 1	1.95	2,15	2.15	3,55	1 2 1	:	1 1 3	2,75	3,55	:	4.70	!	:	:
Oxidation Mode		coating damaged during degassing	protective	protective	protective	protective	onset of failure	linear	linear	protective	protective	sample fell off mount	protective	sample overheated	failure	failure
Temperature Time	(e) =0.65 =0.60)		3070/60	3180/40	3280/60	3380/60	3460/60	3560/10	3560/60	3280/60	3370/60	3465/	3465/60	3550/	3550/5	3500/23
Initial (Area/Weight)	cm_/gms	/5.4503	2,62/5,6732	2.58/5.5104	2.50/5.2991	2.57/5.5118	2.57/5.5208	2,58/5,5630	2.67/5.6551	2.55/5.4632	2.54/5,4227	/5.5034	2.49/5.2678	/5.2436	2.63/5.7858	2.56/5.1660
Initial (Diam/Height)	(mils)	300/268	308/264	307/259	307/249	310/253	308/257				307/256	247/542	300/262	306/248	307/269	296/262
Oxidation No.		XXIX - 28*	- 37	38	- 4i*	- 42	- 43*	- 44	- 45*	- 46°	- 480	- 520	- 53°	- 540	- 56°	- 54°

*Oxygen pressure equal to 10 torr.

TABLE 16

SUMMARY OF OXIDATION EXPERIMENTS OF IRIDIUM BASE ALLOYS (0.53 atm O_2 -0.47 atm He, flow rate = 0.2 ft/sec)

Initial Rate of Oxidation	5.9	7.0	7.2	5.5	3.2	ru A.	6.8	13.7	13.2	6.2
Surface Area in ²	0.1875	0.1544	0.0946	0.1440	0.1690	0.1527	0.1609	0.1652	0.1378	0.1297
Exposure Time (min) Weight Loss (gms)	40 0.2721	38 0.2508	57	60 0.3120	57 0.3415	19 0.2111	24 0.0875	32	32	30
Oxidation Temperature	4030	4030	3840	3860	3860	3860	3860	3860	3860	3860
Melting Temperature Carbon Present	4175	4175	4175	3800	3865	4255	4150	4370	3980	4055
Melting Temperature	4430	4430	4430	3940	4060	4425	4450	4595	4230	4240
Initial Weight	2,0215	1.4401	0.5489	1,3522	1.6064	1.5006	1.6204	1.7192	1,2857	1.1000
Initial Height Diam.	111.2	91.5	52.5 198.8	95.8	92.8 248	105.6	230	113.8	95.1	81.8
Alloy Test No.	Ir XXVIII-1	1r* XXVIII-5	Ir XXVIII-Ti	751r25Pt XXVIII-13	75Ir25Rh XXVIII-15	901r10Re XXVIII-17	75Ir12.5Rh 12.5Re XXVIII-20	751r250s XXVIII-22	7515.508 12.5Pt XXVIII-24	751512, 508 12. 5Rh XXVIII-26

*Flow rate = 0.1 ft/sec. +Based on emittance = 0.30 at λ = 0.65 μ

TABLE 17 SUMMARY OF DIMENSIONAL CHANGES FOR IRIDIUM BASE ALLOYS (0.53 atm O_2 - 0.47 atm He, flow rate = 0.2 ft/sec)

Alloy Test No.	Initial Height Diam. (mils)	T ε=0.30 at λ=0.65μ ο _F	Exposure Time (min)	Final Height <u>Diameter</u> (mils)	Calculated* Rate of Oxidation (mils/hr)	Observed** Rate of Oxidation (mils/hr)
751r 25 Pt XXVM-13		3860	60	86	5.5	4.8
751r25Rh XXVIII-15	92.8 248	3860	57	79 233	3.2	6.9 7.5
90Ir10Re XXVIII-17	105.6 224	3860	19	<u>91</u> 212	5.4	<u>23</u> 19
75Ir12.51 12.5 Re XXVIII-20	107.8	3860	24	96 218	6.8	15
75Ir12.5 Os 12.5P XXVIII-24	t 95.1	3860	32	87	13.4	12.4
75Ir12.5 Os 12.5P XXVIII-26	81.8 217.5	3860	30	75	6.2	6.8

^{*}Based on oxygen pickup.

^{**}Based on initial and final dimensions.

TABLE 18

COMPARISON OF IRIDIUM OXIDATION RESULTS

<u>T</u>	P _{O₂}	Flow Rate ft/sec	Recession Rate mils/hr	Reference
3450	0.53	400.00	51.00	Cricione et. al. (23)
3970	0.53	0.20	7.20	Present Investigation
4040	0.20	0.03	0.28	Krier and Jaffee (24)
4040	0.02	0.25	1.20	Kuriakose, Kent and Margrave (25)
4040	0.20	1.71	15.00	Kuriakose, Kent and Margrave (25)
4040	0.19	200.00	22.00	Rexer (26)
4040	0.93	416.75	240.00	Rexer (26)
4050	0,53	equilibrium	510.00	Alcock and Hooper (27)
4030	0,53	0.10	6.5 <u>+</u> 0.5	Present Investigation

TABLE 19
SPECTRAL EMITTANCE OF PLATINUM GROUP METALS (22)
(BARE SURFACE)

	€ at \ :	= 0.65µ
Element	Solid	Liquid
Iridium	0.30	
Palladium	0.33	0.37
Platinum	0.30	0.38
Rhodium	0.24	0.30
90 Pt-10Rh	0.27	

Security Classification			
DOCUMENT CONT			
(Socurity classification of title, body of obstract and indexing a			
1. ORIGINATING ACTIVITY (Corporate author)	}		CURITY CLASSIFICATION
ManLabs, Inc.			LASSIFIED
21 Erie Street		M. SHOUP	
Cambridge, Massachusetts 02139	1		N/A
S. REPORT TITLE			
Stability Characterization of Refractory	Materials un	der High	Velocity '
Atmospheric Flight Conditions, Part III	Volume I: E	xperimer	ital Results
of Low Velocity Cold Gas/Hot Wall Test	B	_	•
4. DESCRIPTIVE NOTES (Type of report and inclusive doles)			والمرافق
Technical Documentary Report, April 19	966 to July 19	969	
S. AUTHOR(S) (Pire) name, middle laiffel, last name)			والمراقب والمراقب المراود المراود المناقب والمناقب والمناقب المراقب المراقب المراقب المراقب المراقب
Larry Kaufman			
Harvey Nesor			
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6. REPORT DATE	74. TOTAL NO. OF	PAREL	76, NO. OF REPS
December 1969	118		27
M. CONTRACT OR BRANT NO.	S. ORIGINATOR'S	REPORT HUM	
AF33(615)-3859	1	**/ A	
& PROJECT NO.		N/A	
7312 Task 731201	ì		
4 7350 Tasks 735001 and 735002	SA OTHER REPOR	T HO(F) (ANY of	be pushed that may be analysed
4	AFML-TR-	<u>69-84, Pa</u>	art III Volume I
This document is subject to special expo	et controle o	nd each t	renemitted to foreign
governments or foreign nationals may be			
governments or foreign nationals may be	made only	AILL PEIGE	Obt Arata
Force Materials Laboratory (MAMC), W	right-Patter	BOR AFD	Onio 45433.
II. SUPPLEMENTARY NOTES	12. SPONSORING W	LITARY ACTIV	VITŸ
N/A	Air Force l	Materials	Laboratory (MAMC)
N/A	Air Force S		
			r Force Base, Ohio
IS. ABSTRACT			
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Furnace exidation results in flowing air at 0.9 to 7.2 ft/sec for times up to four hours at temperatures between 1150° and 4200°F are presented for 30 candidate materials including the most refractory borides, carbides, boride composites, boride-graphite composites, UTA), JT composites, carbide-graphite composites, pyrolytic and bulk graphite, PT graphite, coated refractory metal/alloys, exide-metal composites, exidation-resistant refractory metal alloys and coated graphites. Temperature limits for coated materials, viscous flow of metal-exide composites and effects of cyclic heating and cooling exposures are reported. Results are presented for exposures in flowing argon between 3000° and 4200°F. These data are complemented by the results of exygen pickup and gas analysis tests on JT composites, silicide coated tungsten and a series of binary and ternary iridium-base alloys which were heated by induction in exygen-helium mixtures flowing at 0.2 ft/sec. Failure conditions were established for the silicide coating on tungsten at exygen partial pressures of 0.031 and 0.20 atmospheres.

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oxidation refractory borides graphites JT composites hypereutectic carbide-graphite composites refractory metals coated refractory metals metal-oxide composites iridium coated graphites furnace tests flowing air temperatures between 1150° and 4200°F							
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